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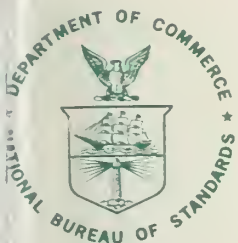
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Semiconductor Measurement Technology:

**DISTRIB I,
An Impurity Redistribution
Computer Program**

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Semiconductor Measurement Technology:

DISTRIB I, An Impurity Redistribution Computer Program

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PREFACE

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Semiconductor Measurement Technology:

DISTRIB I, An Impurity Redistribution Computer Program

by

David Gilsinn and Richard Kraft

This report provides documentation of a computer program which calculates the redistribution of impurities in silicon during a single oxidation step. The documentation provides: (1) a physical and mathematical description of the redistribution process, (2) a detailed description of the discretization of the appropriate partial differential equations, and (3) a complete description of the FORTRAN program for computing the solution.

Key Words: Diffusion; electronic technology; impurity distribution; material transport; segregation; semiconductor technology.

1. INTRODUCTION

1.1. Main Objectives of the Documentation

The principal objectives of this documentation are:

- (1) to give a detailed derivation of the algebraic equations that are used in the computer program,
- (2) to give in detail, a step-by-step description of the way the computation in each computational block of the program is carried out, and
- (3) to provide a simple example illustrating how to use the program.

The format of this documentation is modeled after the partial differential equation computer program format description in [9] in the FORTRAN IV language.

In fabrication processes redistribution of impurities takes place in multiple oxidation and diffusion steps (each step being characterized by constant process parameters). DISTRIB is aimed at simulating this complete process; however, due to the complexity of the total problem, it was decided to only document a fundamental oxidation step here. This explains the appellation DISTRIB VERSION 1.

The next section introduces the user to DISTRIB VERSION 1.

1.2. Tips on Where to Locate the Key Parts of This Documentation

Question 1: What should I do if I have a question about this program that is not answered in the documentation?

Answer 1: Call Richard Kraft, NBS, Applied Mathematics Division or Electron Devices Division, (301) 921-3621.

Question 2: Where is the physical problem explained?

Answer 2: In section 2.1.

Question 3: Where are the partial differential equations listed in summary form?

Answer 3: Equations (2.13) to (2.19).

Question 4: Where are the computational procedures outlined?

Answer 4: In section 3.1.

Question 5: Where are the discretized equations derived?

Answer 5: In chapters 5 and 6.

Question 6: What machine has the program run on?

Answer 6: UNIVAC 1108.

Question 7: Where are the flow diagrams?

Answer 7: In chapter 8.

Question 8: Where are the detailed explanations of the computational steps?

Answer 8: In chapter 7.

Question 9: Where are the input and output and a description of how to work a simple problem?

Answer 9: In chapter 9.

Question 10: Where is the listing of the computational blocks?

Answer 10: In chapter 11.

Question 11: Suppose I want to know where to go in the documentation to learn about some quantity in the listing?

Answer 11: Go to the glossary in chapter 12.

Question 12: What is the basis for the program's validity and what are its limitations?

Answer 12: See chapter 10.

Question 13: What about the "deck cards" and the statements in the listings that are not documented in VERSION 1?

Answer 13: Completely ignore them. Everything needed to understand VERSION 1 is explained in this documentation and is in the computational blocks (see listing, chapter 11).

2. DESCRIPTION OF THE PROBLEM

2.1. Physical and Mathematical Description of the Problem

The problem considered here [4] deals with the redistribution of dopant impurities found in silicon as the silicon is oxidized and converted into silicon dioxide. For the sake of specificity, we consider the impurity to be boron and have studied the following ideal situation.

Suppose the entire half space lying to the right of the x-z plane, see figure 1a, to be occupied by silicon while the region on the left-hand side of this plane is filled with oxygen at some elevated temperature. Also, suppose that the silicon is doped with boron and that the density distribution of this impurity is constant in planes parallel to the x-z plane so the distribution is essentially only a function of the y-dimension.

The time evolution of an initially uniform boron distribution (for appropriate conditions at the oxygen-oxide interface) is illustrated in figure 1b. When the oxygen contacts the silicon, it begins to react to form silicon dioxide, and a sharply defined moving boundary which separates the pure silicon from that previously converted into silicon dioxide begins to move into the pure silicon. The position of this moving boundary is known empirically, see [1] and section 4.2, and is denoted by

$$y = y_0(t), \text{ for } t \geq 0 \quad (2.1)$$

where t is time.

Inside the silicon and oxide, the transport of boron is governed by ordinary Fickian diffusion but with different diffusion coefficients D_1 and D_2 in the oxide and silicon, respectively.

The more complicated physical processes take place at the moving oxide-silicon interface. The boron has a preference to be dissolved in the oxide rather than the silicon. Hence, as the moving boundary moves into the silicon, the boron's preference to be in the oxide depletes the boron density in the vicinity of the moving boundary. The preference of the boron to be in the oxide rather than the silicon is quantitatively expressed by requiring that the moving boundary segregation condition be satisfied.

$$C_2(y_0(t), t) = m C_1(y_0(t), t) \quad (2.2)$$

where m is a given constant (the segregation coefficient) and eq (2.2) must be satisfied for all time $t > 0$. In eq (2.2) $C_1(y, t)$ and $C_2(y, t)$ represent the boron densities in the oxide and silicon, respectively.

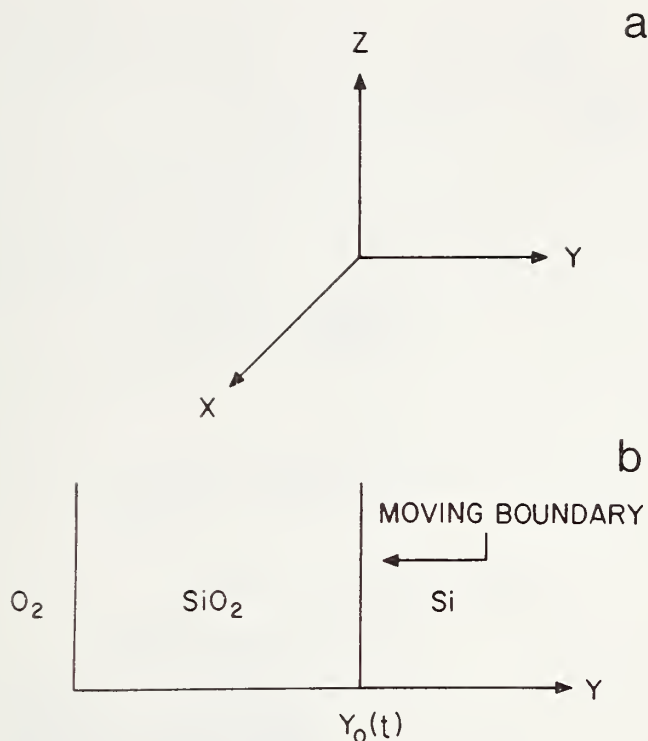


Figure 1. The problem geometry.

In addition to the condition eq (2.2) holding at the moving boundary, it is also assumed that there is conservation of boron atoms. Mathematically, this condition is expressed by the requirement that

$$D_1 \frac{\partial C_1}{\partial Y} \bigg|_{Y=Y_0(t)} + (\alpha^{-1}-1) \dot{Y}_0 C_1 \bigg|_{Y=Y_0(t)} = D_2 \frac{\partial C_2}{\partial Y} \bigg|_{Y=Y_0(t)} \quad (2.3)$$

In order to understand the origin of the convective flux $(\alpha^{-1}-1) \dot{Y}_0 C_1$, it is necessary first to understand a second complicated physical effect occurring at the moving oxide-silicon boundary. When silicon is converted into oxide, its volume expands by a factor α^{-1} , where $\alpha \approx 0.45$. In the model chosen here [4], it is assumed that all the oxidation of the silicon takes place entirely at the moving oxide-silicon interface. In this case, the expansion tends to push the previously formed oxide backwards at a certain velocity into the oxygen, creating another moving boundary between the oxygen and oxide, see figure 2. The velocity with which the oxide is being convected backwards is assumed to set up a convective drift transport in the oxide's boron atoms. The magnitude of the velocity of this convective flux of boron atoms is determined in the following manner.

BORON REDISTRIBUTION DURING OXIDATION

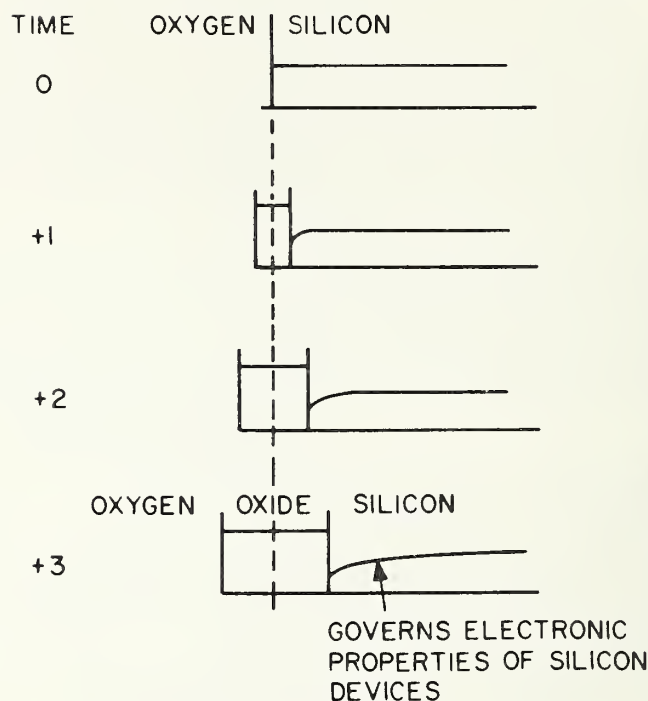


Figure 2. A hypothetical redistribution process.

Consider a thin slab with width Δy of pure silicon located exactly at the moving oxide-silicon interface at some time t_0 just before it is converted into oxide. After some time Δt , the moving boundary has traveled from one side of this thin slab to the other

$$\Delta y = y_o(t_0 + \Delta t) - y_o(t_0) , \quad (2.4)$$

converting it into a thin slab of pure oxide of width $\alpha^{-1}\Delta y$. The difference between this new larger width and the original width is assumed to be the distance that the previously formed oxide (i.e., prior to t_0) is moved backward. Therefore, this rate is

$$\lim_{\Delta t \rightarrow 0} \frac{\alpha^{-1}\Delta y - \Delta y}{\Delta t} = (\alpha^{-1} - 1) \left. \frac{dy_o}{dt} \right|_{t=t_0} \quad (2.5)$$

and the backward velocity of the oxide is $-(\alpha^{-1} - 1)\dot{y}_o$ where $\dot{y}_o = \frac{dy_o}{dt}$.

Thus, the full equation describing the transport of the boron in the oxide is

$$\partial_t C_1(y,t) = D_1 \partial_y^2 C_1 + (\alpha^{-1}-1) \dot{y}_O(t) \partial_y C_1 , \quad (2.6)$$

where the last term in eq (2.6) represents the convective boron transport.

By introducing a coordinate system (see figure 3), moving with the origin at the oxygen-oxide interface,

$$z = y + (\alpha^{-1}-1)y_O(t)$$

$$\text{or} \quad (2.7)$$

$$z = y + z_O(t) - y_O(t) ,$$

where

$$z_O(t) = \alpha^{-1} y_O(t) , \quad (2.8)$$

eq (2.6) simplifies to

$$\partial_t C_1 = D_1 \partial_z^2 C_1 \text{ for } 0 \leq z \leq z_O(t) . \quad (2.9)$$

Moreover, in the z -frame there is no longer a moving boundary at the oxygen-oxide interface to contend with.

The moving boundary conservation condition in the z - and y -frame is

$$D_1 \partial_z C_1(z_O, t) + \dot{z}_O C_1(z_O, t) = D_2 \partial_y C_2(y_O, t) + \dot{y}_O C_2(y_O, t) . \quad (2.10)$$

In this model we assume the transport of boron across the oxygen-oxide interface to be governed by

$$D_1 \partial_z C_1 = C_p (C_1(0, t) - C_{out}) , \quad (2.11)$$

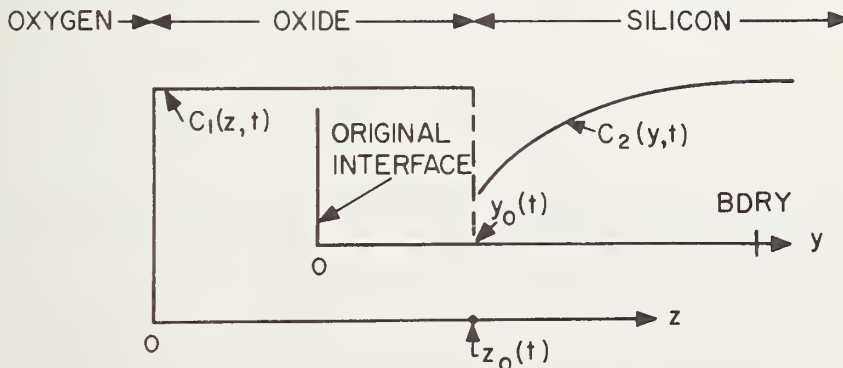


Figure 3. The moving z -coordinate frame.

where C_p and C_{out} are assumed to be known constants. Finally, at $y = \infty$ we assume the concentration to be stationary and equal to a "bulk" value C_B :

$$C_2(\infty, t) = C_B . \quad (2.11')$$

Since we intend to solve the above equations on the computer, it is mandatory to truncate the infinite y -domain by selecting some point $y = BDRY$ far from the y -origin and requiring there that

$$C_2(BDRY, t) = C_B . \quad (2.12)$$

Finally, at time $t = 0$ it is assumed that the silicon slab is completely unoxidized [$y_0(0) = 0$] and that the concentration has a step function distribution:

$$\begin{aligned} C_2(y, 0) &= C_{\max} & y &\leq NH \\ C_2(y, 0) &= C_B & NH < y \leq BDRY \end{aligned} \quad (2.13)$$

where $C_{\max}$, $NH > 0$ are parameters.

In summary, we will solve eq (2.13) and

$$\partial_t C_1 = D_1 \partial_z^2 C_1 \text{ for } 0 \leq z \leq z_0(t) , \quad (2.14)$$

$$\partial_t C_2 = D_2 \partial_y^2 C_2 \text{ for } y_0(t) \leq y \leq BDRY , \quad (2.15)$$

$$D_1 \partial_z C_1 + \dot{z}_0 C_1 \Big|_{z=z_0(t)} = D_2 \partial_y C_2 + \dot{y}_0 C_2 \Big|_{y=y_0(t)} , \quad (2.16)$$

$$C_2(y_0, t) = m C_1(z_0, t) , \quad (2.17)$$

$$D_1 \partial_z C_1 - C_p (C_1 - C_{out}) \Big|_{z=0} = 0 , \text{ and} \quad (2.18)$$

$$C_2(BDRY, t) = C_B , \quad (2.19)$$

where the moving boundary $y_0(t)$ or $z_0(t) = \alpha^{-1} y_0(t)$ is a specified monotonic curve, see section 4.2.

2.2. The Partial Differential Equations in Their Equivalent Integral Form

The usual procedure for the numerical solution of partial differential equations like eqs (2.13) to (2.19) comes through solving the system of algebraic equations that results from replacing the partial derivatives in these equations by their approximating difference quotients. When this standard procedure was tried (see [10-13] for other approaches), it did not lead to a very accurate solution. The discretization of the following system of equations equivalent to the partial differential equations and which involves integrals in place of partial derivatives does lead to a system of algebraic equations that can be solved readily to yield an accurate solution of the original system.

The system of equivalent equations is:

$$\frac{d}{dt} \int_{z_A}^{z_B} C_1(z, t) dz = -D_1 \partial_z C_1 \Big|_{z=z_A} + D_1 \partial_z C_1 \Big|_{z=z_B} \quad (2.20)$$

for every pair of points $z_A < z_B$ such that $0 \leq z_A, z_B \leq z_O(t)$,

$$\frac{d}{dt} \int_{y_A}^{y_B} C_2(y, t) dy = -D_2 \partial_y C_2 \Big|_{y=y_A} + D_2 \partial_y C_2 \Big|_{y=y_B} \quad (2.21)$$

for every pair of points $y_A < y_B$ such that $y_O(t) \leq y_A, y_B \leq \text{BDRY}$,

$$\frac{d}{dt} \int_{z_A}^{z_O(t)} C_1(z, t) dz + \int_{y_O(t)}^{y_B} C_2(y, t) dy = -D_1 \partial_z C_1 \Big|_{z=z_A} + D_2 \partial_y C_2 \Big|_{y=y_B}, \quad (2.22)$$

$$C_2(y_O, t) = m C_1(z_O, t), \quad (2.23)$$

$$D_1 \partial_z C_1 - C_p (C_1(0, t) - C_{\text{out}}) = 0, \quad (2.24)$$

$$C_2(\text{BDRY}, t) = C_B, \text{ and} \quad (2.25)$$

$$C_2(y, 0) = C_O(y), \quad (2.26)$$

where

$$C_o(y) = \begin{cases} C_{\max} & y \leq NH \\ C_B & NH < y \leq \text{BDRY} \end{cases}.$$

To see that eq (2.14) is equivalent to eq (2.20), first carry out the differentiation on the left-hand side of eq (2.20) under the integral sign and substitute for $\partial_t C_1$ by employing eq (2.14). One gets

$$\frac{d}{dt} \int_{z_A}^{z_B} C_1(z,t) dz = \int_{z_A}^{z_B} D_1 \partial_z^2 C_1 dz \quad (2.27)$$

and

$$\int_{z_A}^{z_B} D_1 \partial_z^2 C_1 dz = -D_1 \partial_z C_1 \Big|_{z=z_A} + D_1 \partial_z C_1 \Big|_{z=z_B} \quad (2.28)$$

yielding the right-hand side of eq (2.20).

By reversing these steps starting with the right-hand side of eq (2.20), one finds

$$\int_{z_A}^{z_B} (\partial_t C_1 - D_1 \partial_z^2 C_1) dz = 0 \quad (2.29)$$

for every $0 \leq z_A < z_B \leq z_o(t)$. Therefore, the integral of eq (2.29) must vanish (it is assumed to be continuous) and eq (2.14) results. By using trivial modifications of these same techniques, the remaining equations can be shown to be equivalent to eqs (2.13) to (2.19).

3. THE COMPUTATIONAL PROCEDURE

3.1. General Description of the Computational Procedure

The numerical approach to the solution of the partial differential equations in the integral form, eqs (2.20) to (2.26), replaces the problem of finding the continuous functions $C_1(z,t)$, $C_2(y,t)$ with the problem of determining the functions $C_1(z, t_{MM})$, $C_2(y, t_{MM})$ which are only defined at discrete points on a finite difference grid. The time coordinates of these grid points are specified through the definition of a sequence of discrete times t_{MM} for $MM = 1, \dots, MME$ where MME is some given positive integer and the first discrete time, t_1 , is zero. The spatial coordinates of the "fixed" grid points (see sec. 4.1 and fig. 4 for further details) are

$$\begin{aligned} z &= (J - 1)\Delta z \text{ for } J = 1, 2, \dots, \\ y &= (I - 1)\Delta y \text{ for } I = 1, \dots, N2, \end{aligned} \quad (3.1)$$

where $N2$ is some given integer index. The mesh widths Δz , Δy are also given quantities whose magnitudes like those of MME and $N2$ need not be considered now. In addition to the fixed grid points in eq (3.1), there are two grid points located at the moving boundary (see sec. 2.1). One is at the moving boundary bordering the z -region and the second is at the moving boundary bordering the y -region, see figure 4. The space and time coordinates of these two moving boundary grid points are, respectively, $(z_O(t_{MM}), t_{MM})$ and $(y_O(t_{MM}), t_{MM})$. In addition to seeking the concentrations at the fixed grid points $C_1(J, t_{MM})$, $C_2(I, t_{MM})$, we also desire to find the concentrations at the two moving boundary grid points,

$$C_1(z_O(t_{MM}), t_{MM}), C_2(y_O(t_{MM}), t_{MM}) \text{ for } MM=1, \dots, MME.$$

Because of the initial condition eq (2.26), these concentrations are known at time $t_1 = 0$.

Let us assume that we have already determined the concentrations at the fixed and moving grid points up to some arbitrary time t_{MM} ; then we will proceed to describe how these same concentrations at the next time $t_{MM} + \Delta t = t_{MM+1}$ (where $\Delta t \equiv t_{MM+1} - t_{MM}$) can be found by performing the operations in the following three steps.

Step #1: Discretize the equations.

By discretizing the equivalent description of the partial differential equations in eqs (2.20) to (2.26), we derive a system of linear algebraic tridiagonal equations that couple the concentrations at time t_{MM} with those at t_{MM+1} . Specifically, with each of the fixed grid points in the z -region, we derive and associate an equation of the form

$$Z_1 C_1(J - 1, T_{MM+1}) + Z_2 C_1(J, T_{MM+1}) + Z_3 C_1(J + 1, T_{MM+1}) = Z_4 \quad (3.2)$$

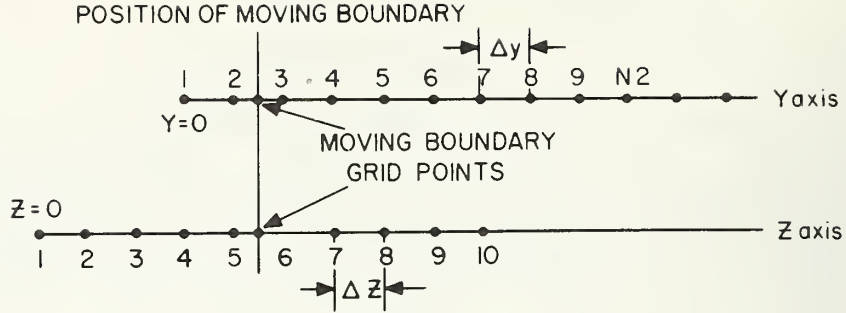


Figure 4. Finite difference grids with $\alpha = 1/3$ and $NZO = 3$.

Table 1: FORTRAN Version of Symbols in Eqs (3.2) to (3.4) in the Y- and Z-Regions.

$$C_1((P - 1)\Delta z, t_{MM+1}) \equiv C_1(P, TTMMP1)$$

$$C_2((P - 1)\Delta y, t_{MM+1}) \equiv C_2(P, TTMMP1)$$

$$t_{MM+1} \equiv TTMMP1$$

$$C_1(z_O(t_{MM+1}), t_{MM+1}) \equiv CB(1, TTMMP1)$$

$$C_2(y_O(t_{MM+1}), t_{MM+1}) \equiv CB(2, TTMMP1)$$

for $J = 1, \dots, NL$ and where the FORTRAN notation is defined in table 1. Similarly, with each of the fixed grid points in the y-region, we derive and associate an equation of the form

$$Y_1 C_2(I - 1, TTMMP1) + Y_2 C_2(I, TTMMP1) + Y_3 C_2(I + 1, TTMMP1) = Y_4 \quad (3.3)$$

where $I = NR, \dots, N2$ and table 1 contains the FORTRAN symbol definitions. The coefficients $Z_1, \dots, Z_4$, $Y_1, \dots, Y_4$ are composed of the mesh width quantities Δt , Δz , Δy and hence are known. In addition, the quantities Z_4, Y_4 contain, respectively, $C_1(z_O(t_{MM}), t_{MM})$ and $C_2(y_O(t_{MM}), t_{MM})$ and therefore these equations couple the concentrations at the two successive time steps t_{MM} and t_{MM+1} .

At the moving boundary grid point in the z-region, there is an additional equation called the preliminary equation (for reasons explained in step #3) which expresses the value of $C_1(z_O(t_{MM+1}), t_{MM+1})$ in terms of the concentrations at the neighboring grid points, at time t_{MM+1} ,

$$\begin{aligned}
DM1 \text{ CB}(1,TTMMP1) &= DM2 \text{ C1}(NL,TTMMP1) \\
&+ DM3 \text{ C2}(NR,TTMMP1) + DM4 \text{ C1}(NL - 1,TTMMP1) \\
&+ DM5 \text{ C2}(NR + 1,TTMMP1) + DM6
\end{aligned} \tag{3.4}$$

where the FORTRAN symbols are defined in table 1. In this equation DM1,...,DM6 are composed of known mesh quantities and DM6 contains concentrations, at time t_{MM} (at the grid points coincident and adjacent to the moving boundary grid points), which are of course assumed to be known.

Step #2: Put the tridiagonal equations into "P,Q" form.

By algebraically manipulating eq (3.2), it is possible to put it in the form

$$C1(J,TTMMP1) = P1(J) \text{ C1}(J + 1,TTMMP1) + Q1(J) \tag{3.5}$$

for $J = 1, \dots, NL - 1$ and

$$C1(NL,TTMMP1) = PA(1) \text{ CB}(1,TTMMP1) + QA(1) . \tag{3.6}$$

By similar manipulations, eq (3.3) can be put into the form

$$C2(I,TTMMP1) = P2(I) \text{ C2}(I - 1,TTMMP1) + Q2(I) \tag{3.7}$$

for $I = NR + 1, \dots, N2$ and

$$C2(NR,TTMMP1) = PA(2) \text{ CB}(2,TTMMP1) + QA(2) . \tag{3.8}$$

The "P, Q" coefficients in these equations, i.e., $P1(J)$, $Q1(J)$, $P2(I)$, $Q2(I)$, $PA(L)$, $QA(L)$ for $L = 1,2$ are algebraic combinations of the quantities $Y_1, \dots, Y_4$, $Z_1, \dots, Z_4$ and are hence known.

Step #3: Determination of the concentrations at time $TTMMP1 = t_{MM+1}$.

The first important use of eqs (3.5) to (3.8) is that it is possible using these equations with $J = NL - 1$ in eq (3.5) and $I = NR + 1$ in eq (3.7) to eliminate with the help of eq (2.23) all the unknown concentrations on the right-hand side of the preliminary eq (3.4). Thus, we obtain the value of the concentration at the moving boundary in the z-region in terms of known quantities,

$$CB(1,TTMMP1) = \text{"Some function of (DM1,...,DM6, } Z_1, \dots, Y_4\text{)"} . \tag{3.9}$$

Since eq (3.4) leads directly in this way to what will turn out to be the most important concentration at time $TTMMP1$ in the sense that with this value of $CB(1,TTMMP1)$ all the other concentrations are simply calculated, we call eq (3.4) the preliminary equation for distinction pur-

poses. From this result and the segregation boundary condition eq (2.23) with $SEG \equiv m$, we can find $DB(2,TTMMP1)$.

$$CB(2,TTMMP1) = SEG \cdot CB(1,TTMMP1) . \quad (3.10)$$

By using these two concentrations at the moving boundary and back substituting in eqs (3.6) and (3.8), we can find $C1(NL,TTMMP1)$ and $C2(NR,TTMMP1)$.

Finally, by using these two quantities and by back substituting in eq (3.5) starting with $J = NL - 1$ and by back substituting in eq (3.7) beginning with $I = NR + 1$, we can successively generate all the concentrations at the fixed grid points at time $t_{MM+1} = TTMMP1$.

By repeating steps one through three starting at time $t_1 = 0$ when the concentrations are known in the y-region (there is no z-region since the moving boundary starts at $z = 0$ at time $t = 0$), all the concentrations at all the grid points at the discrete times t_{MM} , $MM = 1, \dots, MME$ can be found.

3.2. Short Guide to the Following Chapters

In this documentation, the derivation of the tridiagonal linear eqs (3.2), (3.3), and (3.4) is carried out in Chapter 5. The manipulation of these equations into the form eqs (3.5) to (3.9) is carried through in Chapter 6. The computational procedure is described in detail in Chapter 7, and Chapter 8 contains flow diagrams of the listing in Chapter 11. Chapter 9 contains a worked example and a compact and precise description of the input and output for the program. Chapter 10 describes the validation and limitations of the program, and Chapters 12 and 13 contain a glossary for FORTRAN symbols and references. The appendices collect finite difference approximations used in Chapter 5 and an "in-house" plot documentation.

The next chapter collects material needed in Chapter 5 and gives a detailed description of the finite difference grid, moving boundary motion, equation dimensionalization, and plotting description.

4. DESCRIPTION OF AUXILIARY COMPUTATIONAL PROCEDURES

4.1. A Detailed Description of the Finite Difference Grid

In this section we describe more fully the finite difference grid already introduced in section 3.1, see eq (3.1). We (see fig. 4) begin by describing how the magnitudes of the mesh widths Δy , Δz , Δt and the number of grid points, $N2$, on the y -axis are determined.

The mesh width Δy is calculated in DISTRIB by dividing the program input quantity BDRY [see above eq (2.12)] by an integer input NYO, i.e.,

$$\Delta y = \frac{\text{BDRY}}{\text{NYO}} . \quad (4.1)$$

Consequently, placing the grid point index 1 at $y = 0$ and calling the index of the y -grid point at $y = \text{BDRY}$, $N2$, implies that

$$N2 = \text{NYO} + 1 . \quad (4.2)$$

In order to understand the motivation for the way we define the magnitude of the mesh width Δz , imagine the width of an interval of size Δy of silicon after it has been converted into oxide. It swells to a size [see sec. 2.1] $\alpha^{-1}\Delta y$. Since in DISTRIB α is an unrestricted input and is possibly very small, this latter quantity, $\alpha^{-1}\Delta y$, could be very large. We want to choose the magnitude of Δz in such a way that there are enough Δz intervals in this width to describe any concentration variation in it. Therefore, we introduce another program input integer NZO and use it to define

$$\Delta z = \alpha^{-1}\Delta y/\text{NZO} \quad (4.3)$$

in such a way that $\alpha^{-1}/\text{NZO} \approx 1$ so that Δz and Δy are approximately the same magnitude. Another very important advantage of this choice of Δz is that it implies that when the moving boundary sweeps through a mesh width of magnitude Δy in the y -region NZO mesh widths of magnitude Δz are swept out in the z -region.

In order to explain the reasoning behind the definition of Δt , we remark that the computer program's numerical stability seems to be affected if the moving boundary moves too rapidly between successive grid points. Therefore, Δt is defined in such a way that the moving boundary does not travel more than a fraction WFRC (real program input) of a Δz mesh width between the times $t = 0$ and $t = \Delta t$. Thus, we solve the equation

$$\text{WFRC} \cdot \Delta z = z_o(\Delta t) - z_o(0) \quad (4.4)$$

for Δt and then define Δt as this solution. This is how Δt for the first iteration (see sec. 3.1) when $t_1 = 0$ and $z_o(0) = 0$ is chosen. In computational blocks #16 and #20 (see sec. 7.1), it is explained how Δt is increased during later iterations of the main loop 78 in DISTRIB.

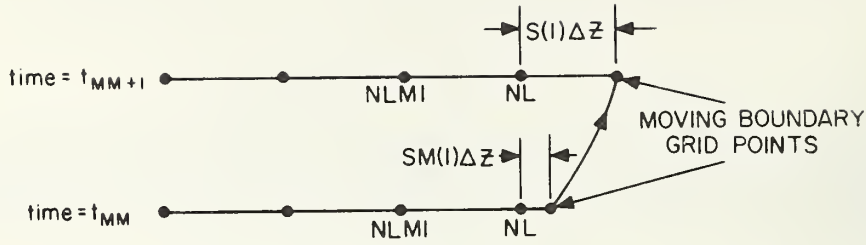


Figure 5: Motion of the moving boundary in the z-region.

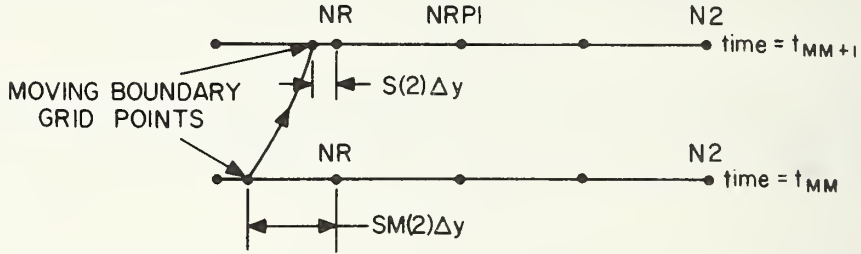


Figure 6. Motion of the moving boundary in the y-region.

Before leaving the description of the finite difference grid, it is important and convenient to introduce special names for certain indices of special grid points. Figure 5 shows the motion of the moving boundary starting at time t_{MM} and ending at time t_{MM+1} in the z-region. We denote the index of the z-grid point which is at or immediately to the left of the moving boundary at time t_{MM} by NL and the next grid point to its left by NLMI ($= NL - 1$). Similarly (see fig. 6), the index of the first grid point in the y-region greater than the position of the moving boundary at time t_{MM} is denoted by NR, and the index of the next point to its right is NRPI ($= NR + 1$). Of course, the values of NL and NR change with t_{MM} .

4.2. The Description of the Moving Boundary

In DISTRIB the user can choose between two different formulas for the moving boundary. These are the two motions related to the wet and dry oxidations in [1]. In both cases there are three parameters A, B, and τ (each with values that are temperature dependent) in the equations that describe the motion of the moving boundary.

Case I: Wet oxidation, $\tau = 0$.

The equation is [see 1, eq (13)]

$$z_O = \frac{A}{2} \left[1 + \frac{4tB}{A^2} \right]^{1/2} - 1 \text{ for } t > 0. \quad (4.5)$$

The equation expressing t in terms of z_o is

$$t = (z_o^2 + Az_o)/B . \quad (4.6)$$

Table 1 in [1] gives the values of A and B for different temperatures.

Case II: Dry oxidation, $\tau > 0$.

For times $t \geq \tau$ [1]

$$z_o = \frac{A}{2} \left[1 + \frac{4tB}{A^2} \right]^{1/2} - 1 \text{ for } t \geq \tau . \quad (4.7)$$

When $t \leq \tau$, we use [1]

$$z_o = \frac{ZCRIT}{\tau} \cdot t , \quad (4.8)$$

where

$$ZCRIT = CNSTX = \frac{A}{2} \left[1 + \frac{4tB}{A^2} \right]^{1/2} - 1 . \quad (4.9)$$

CNSTX is a duplicate name for ZCRIT. Table II in [1] gives the values of A , B , and τ for different temperatures.

The FORTRAN symbols for the constants in the previous equations are given in table 2.

Table 2: FORTRAN Version of Symbols Used in the Moving Boundary Equation and Finite Difference Grid.

$A =$	CNSTA
$B =$	CNSTB
$.5A =$	CNA
$\tau =$	CNTAU = TLIN
$ZCRIT =$	CNSTX
$\Delta z =$	DZ
$\Delta y =$	DY
$\Delta t =$	DT
$\alpha =$	ALPHA

4.3. Dimensionalization

Although the physical input in DISTRIB is required to be in units of micrometers and hours, it is computationally more efficient to solve the partial differential equations with the physical quantities expressed in other units. For the kinds of problems of interest in impurity redistribution, a convenient basic length is $BLTH = 0.02 \mu m$. Given the basic length unit, a basic time is frequently introduced in diffusion theory by defining

$$BTM = \frac{BLTH^2}{D_o} \text{ hours} \quad (4.10)$$

where D_o is some diffusion coefficient in the problem. In our program, D_o is chosen to be D_2 , the diffusion coefficient in silicon. When these new units are used to dimensionalize the diffusion equation in the silicon, one finds the new equation has a diffusion constant of unity. That is, making a change of independent variables

$$t' = \frac{t}{BTM}, \quad y' = \frac{y}{BLTH}, \quad \text{and} \quad z' = \frac{z}{BLTH}$$

transforms eq (2.14) into

$$\partial_{t'} C_2 = \partial_{y'}^2 C_2$$

and eq (2.15) into

$$\partial_{t'} C_1 = \frac{D_1}{D_2} \partial_{z'}^2 C_1.$$

The rest of the dimensionalizations carried out in block #4 of section 7.1 are standard conversions from micrometers and hours to the new units $BLTH$ and BTM .

4.4. The Description of the Way Arrays C1 and C2 Are Plotted

The plotting is really a peripheral item and not described in as much detail as substantive parts of the program. All the quantities undefined are defined or referenced in the glossary and their definition in the glossary makes their function clear. First, the way C1 is plotted is described. Let NC be the integer part of $(NL - 1)/NMOD$. When $NC > 0$, we plot the concentrations C1 and z-coordinate (in units of $ZOP1$) at every grid point $K = V \cdot NMOD + 1$ for $V = 1, \dots, NC$. When $NC = 0$, we plot the concentrations at $z = 0$ and at the moving boundary z_o . The quantities $X1S$, $Y1S$ determine the largest abscissa and ordinate on the graph of C1 versus z.

The graph of array C2 is plotted in the following way. All abscissa are in units of UN2 (which is essentially SCALE2, since y is still in units of BLTH). The first C2 concentration plotted is CB(2) at the moving boundary. The next concentration is C2(NR) with abscissa S(2)DY. Next, we plot ND - 2 concentrations with the indices KS = NR + (V - 2) NMOD1 for V = 3, ..., ND. Next, we pass these grid points through a filter which eliminates those with an abscissa greater than $X2S/2 = X2SCT$. The quantities X2S and Y2S determine the largest abscissa and ordinate that appear on the C2 versus y plot. Note: The specific scales used as the ordinates and abscissa for these plots were chosen in order to make the resultant graphs identical in size to those obtained from the equipment which experimentally determined the concentration data. This also accounts for the elimination of points beyond $X2S/2$. Both conditions may be changed to accommodate the user.

The smallest abscissa and ordinate are determined in both graphs by (0,0).

The plot subroutine is an NBS "house program" that is documented in Appendix 2.

This plotting procedure has worked well in all cases, the only adjustments needing to be made being in NMOD and NMOD1 (see table 20 in sec. 9.22).

5. DERIVATION OF THE DISCRETE ALGEBRAIC EQUATIONS

5.1. The General Prescription for Obtaining the Tridiagonal Equation Associated with a Fixed Grid Point

This section, which should be read casually, gives a rough description of the precise derivations in the following sections.

Each particular tridiagonal equation in eqs (3.2), (3.3) [and (3.4) also] associated with some particular grid point is derived by discretizing some integral form of the conservation of number eqs (2.20) to (2.22) over the "flux cell" (to be described below) that contains that particular grid point. The flux cells are intervals that arise by partitioning the z - and y -regions in a certain way. That is, both the z -region and the y -region are broken up into nonoverlapping intervals called flux cells or concentration cells in such a way that the intervals completely cover the regions $[0, z_0(t)]$ and $[y_0(t), \text{BDRY}]$ at every time t ; and each grid point is contained in at most one cell except for the grid points with indices NL and NR . Each of these grid points is contained in both the irregular sized cell with which it is associated and the "moving boundary cell"; these statements will be explained more completely later. The two boundaries of each of the concentration cells are called the flux boundaries of the cell. We interpret the concentration, $C_1(J, \text{TTMMP1}) = C_1((J - 1)\Delta z, t_{\text{MM}+1})$, at some grid point J to represent the average number density in the cell at time $t_{\text{MM}+1}$.

The flux boundaries for the cells in the y -region are shown in figure 7 by the vertical lines located halfway between successive grid points. Notice that all the cells in the y -region that contain fixed grid points (see sec. 3.1) are of width Δy except the irregular one of width $0.5 \Delta y$ that contains and leads to the tridiagonal algebraic equation associated with the grid point with index NR at $(NR - 1)\Delta y$. This cell has one flux boundary at $(NR - 1)\Delta y$ and the other is at $(NR - 1/2)\Delta y$. Similar remarks apply to figure 8.

The significance of the flux cell containing some grid point, with index I in the y -region (see fig. 7) is that it leads to a linear algebraic equation containing the concentration $C_2(I, \text{TTMMP1})$ as an unknown when the conservation eq (2.21) defined on this cell is discretized.

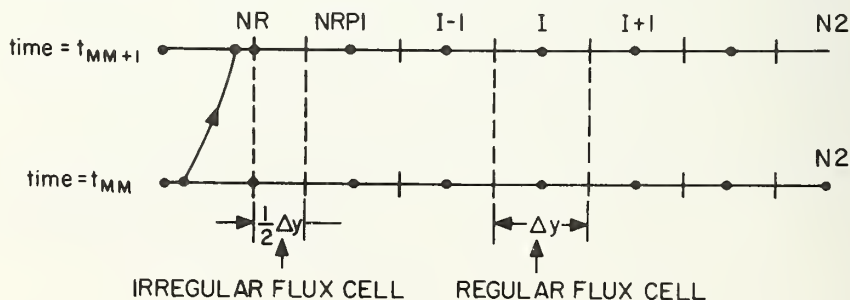


Figure 7: Flux cells and flux boundaries in the y -region for fixed grid points.

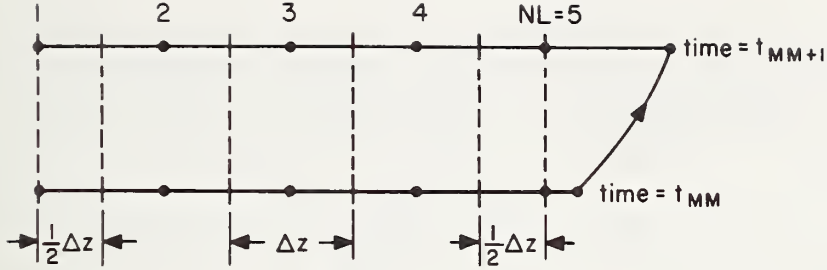


Figure 8. Flux cells for fixed grid points in the z -region when $NL > 2$.

In particular, let y_A and y_B in eq (2.21) be at $(I - 3/2)\Delta y$ and $(I - 1/2)\Delta y$, respectively. Make now the following approximations in eq (2.21) (with $t = t_{MM+1}$):

$$\frac{d}{dt} \int_{y_A}^{y_B} C_2(y, t) dy \approx \int_{y_A}^{y_B} [C_2(y, t_{MM+1}) - C_2(y, t_{MM})] dy / \Delta t ,$$

$$\int_{y_A}^{y_B} C_2(y, t_{MM+1}) dy \approx C_2((I - 1)\Delta y, t_{MM+1}) \Delta y ,$$

$$\int_{y_A}^{y_B} C_2(y, t_{MM}) dy \approx C_2((I - 1)\Delta y, t_{MM}) \Delta y ,$$

$$D_2 \frac{\partial C_2}{\partial y} \Big|_{y=y_A} \approx D_2 [C_2((I - 1)\Delta y, t_{MM+1}) - C_2((I - 2)\Delta y, t_{MM+1})] , \text{ and}$$

$$D_2 \frac{\partial C_2}{\partial y} \Big|_{y=y_B} \approx D_2 [C_2(I\Delta y, t_{MM+1}) - C_2((I - 1)\Delta y, t_{MM+1})] .$$

Then eq (2.21) becomes, up to terms of higher order, the linear tridiagonal equation in eq (3.4) associated with the grid point with index I ,

$$\begin{aligned} C_2((I - 2)\Delta y, t_{MM+1}) - \left[2 + \frac{\Delta y^2}{D_2 \Delta t} \right] C_2((I - 1)\Delta y, t_{MM+1}) \\ + C_2(I\Delta y, t_{MM+1}) = - \frac{\Delta y^2}{D_2 \Delta t} C_2((I - 1)\Delta y, t_{MM}) . \end{aligned}$$

The important fact this example illustrates is that, by evaluating the fluxes in eq (2.21) at the flux boundaries of the flux cell and evaluating the integrals by a quadrature approximation with a "node" located at the grid point in the flux cell, one ends up with a tridiagonal (i.e., an equation involving the concentrations at three consecutive grid points) equation for the unknown concentration at time t_{MM+1} at that grid point. Thus, with the help of these flux cells one can in a natural way associate with each unknown at a fixed grid point an algebraic equation.

The flux cells of the points in the z-region depend on the values of NL. There are three cases depending on whether $NL = 1$, $NL = 2$, or $NL > 2$. The cell configuration for the case $NL > 2$ can be visualized from figure 8. In the case $NL = 2$ (see fig. 9), there are just two irregular cells each of width $0.5 \Delta z$. The flux cell associated with the grid point with index NL has its right side flux boundary located coincident with the grid point. The flux cell associated with the first z-grid point with index 1 has its left-hand flux boundary coincident with the first grid point. These facts also hold when $NL > 1$, but in this case there are regular grid cells, i.e., with width Δz in between the irregular ones at the outer boundaries. The case $NL = 1$ is special because there are no grid points in the z-region between the moving and fixed boundaries.

Finally, we point out that for all values of NL the conservation formula eq (2.22) (conservation across the moving boundary) is discretized to derive the preliminary eq (3.4), and in this derivation the flux cell is as shown in figure 10 with the flux boundaries at $z_A = (NL - 1)\Delta z$ and $y_B = (NR - 1)\Delta y$. The trapezoidal rule is used to evaluate the integrals in eq (2.22) with the nodes at NL, NR and the moving boundary grid points at $S(1)\Delta z + (NL - 1)\Delta z$ and $(NR - 1)\Delta y - S(2)\Delta y$, see figures 5 and 6.

These different cases, which arise because we have flux cells with different widths and with different orientation of grid points relative to the flux boundaries for different values of NL, explain the slight variations, classified in tables 3 and 15, in the way the tridiagonal algebraic equations and their "P,Q" coefficients (see sec. 3.1) are derived in the following sections.

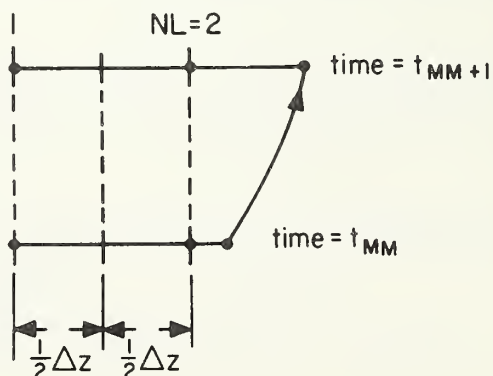


Figure 9. Flux cells for fixed grid points in the z-region when $NL = 2$.

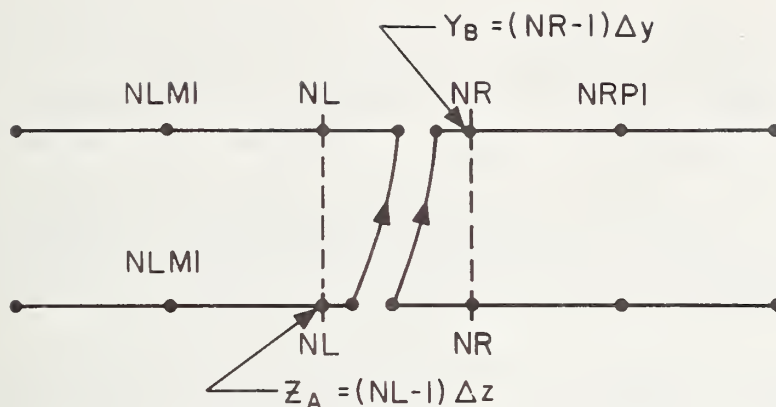


Figure 10. Schematic description of the flux cell associated with the discretization of the conservation equation across the moving boundary.

Table 3: Guide to the Sections Where the Tridiagonal Algebraic Equations Associated With the Grid Points are Described and Derived.

Case I: The moving boundary has not reached the second z-grid point or $NL < 2$.

- (a) The index of the z-grid point is 1 (see sec. 5.9)
- (b) The index of the y-grid point is greater than NR (see sec. 5.3)
- (c) The index of the y-grid point is NR (see sec. 5.5)
- (d) The grid point is at the moving boundary (see sec. 5.7)

Case II: The moving boundary has reached the second z-grid point or $NL \geq 2$.

- (a) The index of the z-grid point is 1 (see sec. 5.8)
- (b) The index of the z-grid point ranges from 2 to $NL - 1$ (see sec. 5.2)
- (c) The index of the z-grid point is NL (see sec. 5.4)
- (d) The grid points are at the moving boundary (see sec. 5.6)
- (e) The index of the y-grid point is greater than NR (see sec. 5.3)
- (f) The index of the y-grid point is NR (see sec. 5.5)

5.2. The Index of the Z-Grid Point Ranges from 2 to $NL - 1$ When $NL > 2$.

In this case we suppose the index, $J + 1$, is such that $2 < J + 1 < NL - 1$, and begin with the formula, see eq (2.20)

$$\frac{d}{dt} \int_{z_A}^{z_B} C_1(z,t) dz = - D_1 \partial_z C_1 \Big|_{z=z_A} + D_1 \partial_z C_1 \Big|_{z=z_B} . \quad (5.1)$$

For the z -grid point, $J + 1$, we assume z_A and z_B "the flux boundaries" to be at $(J - 1/2)\Delta z$, $(J + 1/2)\Delta z$, respectively. We speak of these grid points as regular grid points because the distance between the cell flux boundaries is Δz .

The left-hand side of eq (5.1) is discretized by employing the backward time difference formula (A7) in Appendix 1 between the times $t = t_{MM}$ and $t = t_{MM} + \Delta t$. Here, Δt is some small positive time increment that sometimes depends on the index MM . After the derivative has been replaced by the backward difference quotient, the integrals are approximated by the midpoint quadrature rule (A2).

Finally, after further algebraic manipulation we have

$$\begin{aligned} \frac{d}{dt} \int_{z_A}^{z_B} C_1(z,t) dz &= \frac{\Delta z}{\Delta t} [C_1(J\Delta z, t_{MM} + \Delta t) \\ &\quad - C_1(J\Delta z, t_{MM})] + O(\Delta z^2 + \Delta t^2)/\Delta t . \end{aligned} \quad (5.2)$$

Since all the expressions in eq (5.1) are assumed to be evaluated at $t = t_{MM} + \Delta t$, the approximation of the derivatives on the right-hand side of eq (5.1) gives

$$\partial_z C_1 \Big|_{z=z_A} = [C_1(J\Delta z, t_{MM} + \Delta t) - C_1((J - 1)\Delta z, t_{MM} + \Delta t)]/\Delta z + O(\Delta z) \quad (5.3)$$

and

$$\partial_z C_1 \Big|_{z=z_B} = [C_1((J + 1)\Delta z, t_{MM} + \Delta t) - C_1(J\Delta z, t_{MM} + \Delta t)]/\Delta z + O(\Delta z) . \quad (5.4)$$

By substituting eqs (5.2) to (5.4) into eq (5.1) and further rearranging, we obtain up to higher order terms the discrete version of eq (5.1) in tridiagonal form,

$$\begin{aligned} D_1 C_1((J - 1)\Delta z, t_{MM} + \Delta t) - (2 \cdot D + \Delta z^2/\Delta t) C_1(J\Delta z, t_{MM} + \Delta t) \\ + D_1 C_1((J + 1)\Delta z, t_{MM} + \Delta t) = \frac{-(\Delta z)^2}{\Delta t} C_1(J\Delta z, t_{MM}) . \end{aligned} \quad (5.5)$$

After introducing the FORTRAN quantities in table 4, eq (5.5) becomes

$$\begin{aligned} DF1 \cdot C1(J, TTMMPl) - (2 \cdot DF1 + DZ**2/DT) \cdot C1(J + 1, TTMMPl) \\ + DF1 \cdot C1(J + 2, TTMMPl) = \frac{-(DZ)**2}{DT} \cdot C1(J + 1, TTMM) \end{aligned} \quad (5.6)$$

Table 4: FORTRAN Version of Quantities in Eq (5.5).

$$\begin{aligned} D1 &= DF1 \\ C1(,) &= C1(,) \\ t_{MM} &= TTMM \\ t_{MM} + \Delta t &= TTMMPl \\ \Delta t &= DT \\ \Delta z &= DZ \\ C1(J\Delta z, t_{MM}) &= C1(J + 1, TTMM) \\ C1(J\Delta z, t_{MM} + \Delta t) &= C1(J + 1, TTMMPl) \end{aligned}$$

In the FORTRAN program, the following intermediate quantities in table 5 have been introduced for convenience and computational efficiency.

Table 5: Intermediate Quantities Used in Eq (5.7).

$$\begin{aligned} \frac{DT}{DZ^2} &= RA1 \\ DF1 &= A2L \\ -(2 \cdot DF1 + (RA1)^{-1}) &= A2M \\ DF1 &= A2R \\ -(RA1)^{-1} &= A1M \\ AF(J + 1) &= A1M \cdot C1(J + 1, TTMM) \end{aligned}$$

In terms of these intermediate quantities, eq (5.6) can be written in the compact tridiagonal FORTRAN form

$$\begin{aligned} A2L \cdot C1(J, TTMMPl) + A2M \cdot C1(J + 1, TTMMPl) + A2R \cdot C1(J + 2, TTMMPl) \\ = AF(J + 1) . \end{aligned} \quad (5.7)$$

As has been explained in more detail in section 3.1, the quantities A2L, ..., AF(J) are used in computing the values of the arrays P1, Q1, and D1. Specifically, the quantities A2L, ..., A2R, A1M are computed in

subroutine INTER. The subroutine INTER is called by subroutine TRIDNL when this latter subroutine is calculating the arrays P1, Q1. The array AF(J) is computed in block #25 of the main program, see section 7.1.

SUMMARY

Schematic summary of the derivation of the tridiagonal FORTRAN equation for z-grid points with indices between 1 and NL:

$$(5.1) \rightarrow (5.5) \rightarrow (5.6) \rightarrow (5.7) .$$

Summary notes:

- (1) Quantities in table 5 except for AF are computed in subroutine INTER.
- (2) The array AF(J) is computed in block #25 of the main program.

5.3. The Index of the Y-Grid Point is Greater than NR

The derivation of the tridiagonal FORTRAN form of the algebraic equations associated with these grid points is almost entirely analogous to the derivation of the equations in subsection 5.2 once the substitutions z for y, D_1 for D_2 , C_1 for C_2 , etc., are made. However, there is one exception; in the y-region we have divided the equivalent of eq (5.5) by D_2 so that the equivalent of that equation is

$$\begin{aligned} C_2((J-1)\Delta y, t_{MM} + \Delta t) - \left[2 + \frac{\Delta y^2}{D_2 \Delta t} \right] C_2(J\Delta y, t_{MM} + \Delta t) \\ + C_2((J+1)\Delta y, t_{MM} + \Delta t) = \frac{\Delta y^2}{D_2 \Delta t} C_2(J\Delta y, t_{MM}) . \end{aligned} \quad (5.8)$$

Table 6 is the equivalent of table 4.

Table 6: FORTRAN Version of Quantities in Eq (5.8).

$D_2 = DF2$
$\Delta y = DY$
$C_2(\cdot, \cdot) = C2(\cdot, \cdot)$
$\Delta z = DZ$
$C_2(J\Delta y, t_{MM}) = C2(J+1, TTMM)$
$C_2(J\Delta y, t_{MM} + \Delta t) = C2(J+1, TTMMPl)$

When the quantities in table 6 are introduced into eq (5.8), it becomes

$$\begin{aligned}
 C1(J,TTMMP1) - \left[2 + \frac{DY^{**2}}{DF2 \cdot DT} \right] C2(J + 1,TTMMP1) + C2(J + 2,TTMMP1) \\
 = \frac{DY^{**2}}{DF2 \cdot DT} C2(J + 1,TTMM) .
 \end{aligned}
 \tag{5.9}$$

This form of the equation is further simplified by introducing the intermediate quantities in table 7.

Table 7: Intermediate Quantities Used in Eq (5.10).

$$\begin{aligned}
 \frac{DT}{DY^2} &= RA2 \\
 1 &= B2L \\
 -(2 + RA2^{-1}/DF2) &= B2M \\
 1 &= B2R \\
 -RA2^{-1}/DF2 &= B1M \\
 BF(J + 1) &= B1M \cdot C2(J + 1,TTMMP1)
 \end{aligned}$$

In terms of the intermediate quantities in table 7, eq (5.9) assumes the form

$$\begin{aligned}
 B2L C2(J, TTMMP1) + B2M C2(J + 1, TTMMP1) + B2R C2(J + 2, TTMMP1) \\
 = BF(J + 1) .
 \end{aligned}
 \tag{5.10}$$

The quantities RA2, B2L,...,B1M are computed in subroutine INTER. This subroutine is called by subroutine TRIDNL and in this routine the quantities RA2,...,B1M are used to compute arrays P2, D2. The quantity BF(J) is computed in block #26 of the main program.

SUMMARY

Schematic summary of the derivation of the tridiagonal FORTRAN equations for y-grid points with indices greater than NR:

$$(5.8) \rightarrow (5.9) \rightarrow (5.10) .$$

Summary notes:

- (1) Quantities in table 7 except for BF are calculated in subroutine INTER.
- (2) The array BF(J) is computed in block #26 of the main program.

5.4. The Index of the Z-Grid Point is NL and NL > 1

In this subsection we derive the FORTRAN tridiagonal form of the equation associated with the z-grid point with index NL which is located at $z = (NL - 1)\Delta z$.

The derivation begins with the integral conservation equation

$$\frac{d}{dt} \int_{z_A}^{z_B} C_1(z, t) dz = -D_1 \partial_z C_1 \Big|_{z=z_A} + D_1 \partial_z C_1 \Big|_{z=z_B} \quad (5.11)$$

In this equation, $z_B = (NL - 1)\Delta z$, $z_A = (NL - 3/2)\Delta z$ are the "flux boundaries"; notice the flux boundary at z_B coincides with the location of the grid point associated with the cell (see fig. 9). Also, the cell width, the distance between the flux boundaries, is $\Delta z/2$, and therefore this grid point is called an irregular grid point, see section 5.1.

By using the backward difference quotient approximation in eq (A7) to approximate the time derivative on the left-hand side of eq (5.11) between the times t_{MM} and $t_{MM} + \Delta t$ and the right end point quadrature approximation in eq (A3) to approximate the resulting integrals, the left-hand side of eq (5.11) becomes equivalent to

$$\begin{aligned} \frac{d}{dt} \int_{(NL-3/2)\Delta z}^{(NL-1)\Delta z} C_1(z, t) dz &= \frac{\Delta z}{2\Delta t} \left\{ C_1[(NL - 1)\Delta z, t_{MM} + \Delta t] \right. \\ &\quad \left. - C_1[(NL - 1)\Delta z, t_{MM}] + O(\Delta t + \Delta z^2/\Delta t) \right\}. \end{aligned} \quad (5.12)$$

The spatial derivative on the right-hand side of eq (5.11) at $z = z_A$ is approximated by the central difference approximation

$$\begin{aligned} \partial_z C_1 \Big|_{z=z_A} &= \frac{1}{\Delta z} \left\{ C_1[(NL - 1)\Delta z, t_{MM} + \Delta t] - C_1[(NL - 2)\Delta z, t_{MM} + \Delta t] \right\} \\ &\quad + O(\Delta z). \end{aligned} \quad (5.13)$$

To approximate the derivative at $z = z_B$ on the right-hand side of eq (5.11), we use the three point derivative approximation given in eq (A9). Setting in that formula

$$\begin{aligned}
x_1 &= z_o(t_{MM} + \Delta t) \\
x &= (NL - 1)\Delta z = z_B \\
x_2 &= (NL - 2)\Delta z \\
h &= \Delta z
\end{aligned}$$

we obtain the sought-after result

$$\begin{aligned}
\partial_z C_1 \Big|_{z=z_B} &= \frac{1}{\Delta z} \left\{ - \frac{S(1)}{1 + S(1)} C_1[(NL - 2)\Delta z, t_{MM} + \Delta t] \right. \\
&+ [(S(1) - 1)/S(1)] C_1[(NL - 1)\Delta z, t_{MM} + \Delta t] \\
&\left. + \frac{1}{S(1) [1 + S(1)]} C_1[z_o(t_{MM} + \Delta t), t_{MM} + \Delta t] \right\} + O(\Delta z^2) ,
\end{aligned} \tag{5.14}$$

where

$$S(1) = [z_o(t_{MM} + \Delta t) - (NL - 1)\Delta z]/\Delta z . \tag{5.15}$$

When eqs (5.12), (5.13), and (5.14) have been substituted into eq (5.11) and the expression simplified, it becomes up to terms of higher order

$$\begin{aligned}
& - \frac{D_1 S(1)}{1 + S(1)} C_1[(NL - 2)\Delta z, t_{MM} + \Delta t] \\
& + \left[\frac{D_1 \cdot S(1)}{R(1)} + D_1 \right] C_1[(NL - 1)\Delta z, t_{MM} + \Delta t] \\
& - \frac{D_1}{(1 + S(1))} C_1[z_o(t_{MM} + \Delta t), t_{MM} + \Delta t] \\
& = \frac{S(1) C_1[(NL - 1)\Delta z, t_{MM}]}{R(1)} ,
\end{aligned} \tag{5.16}$$

where

$$R(1) = \frac{2\Delta t}{\Delta z^2} . \tag{5.16'}$$

After introducing the FORTRAN notation in table 8 into eq (5.16), it becomes

$$\begin{aligned}
& - \frac{DF1}{1 + S(1)} C1(NL - 1, TTMMPl) + \frac{DF1}{R(1)} + \frac{DF1}{S(1)} C1(NL, TTMMPl) \\
& - \frac{DF1}{S(1) (1 + S(1))} CB(1) = \frac{C1(NL, TTMM)}{R(1)} .
\end{aligned} \tag{5.17}$$

Table 8: FORTRAN Version of Quantities in Eq (5.16).

$$\begin{aligned}
D_1 &= DF1 \\
t_{MM} &= TTMM \\
t_{MM} + \Delta t &= TTMMPl \\
\Delta t &= DT \\
\Delta z &= DZ \\
R(1) &= \frac{Z \cdot DT}{DZ**2} \\
C_1((NL - 2)\Delta z, t_{MM} + \Delta t) &= C1(NL - 1, TTMMPl) \\
C_1((NL - 1)\Delta z, t_{MM} + \Delta t) &= C1(NL, TTMMPl) \\
C_1((NL - 1)\Delta z, t_{MM}) &= C1(NL, TTMM) \\
C_1(z_O(t_{MM} + \Delta t), t_{MM} + \Delta t) &= CB(1)
\end{aligned}$$

Equation (5.17) will be used to obtain the "P, Q" quantities PA(1), QA(1) for z-grid point NL, i.e., quantities such that

$$C1(NL, TTMMPl) = PA(1) \cdot CB(1) + QA(1) , \tag{5.18}$$

in section 6.6.

SUMMARY

Schematic summary of the derivation of the tridiagonal FORTRAN equation for the z-grid point with index NL when $NL \geq 2$,

$$(5.11) \rightarrow (5.16) \rightarrow (5.17) .$$

Summary note:

Equation (5.17) is used in section 6.6 to obtain quantities PA(1), QA(1).

5.5. The Index of the Y-Grid Point is NR

The derivation of the tridiagonal FORTRAN formula for this grid point is analogous to the derivation in section 5.4 for the irregular z-grid

point at NL so the user should refer to that section if more details concerning the following derivation are desired.

Again, we start with the integral conservation equation,

$$\frac{d}{dt} \int_{y_A}^{y_B} C_2(y, t) dy = -D_2 \partial_Y C_2 \Big|_{Y=y_A} + D_2 \partial_Y C_2 \Big|_{Y=y_B}, \quad (5.19)$$

where $y_A = (NR - 1)\Delta y$ and $y_B = (NR - \frac{1}{2})\Delta y$.

By using the same approximation procedure that led from eq (5.11) to eq (5.12) (except for using the left end point quadrature approximation), we find

$$\begin{aligned} \frac{d}{dt} \int_{y_A}^{y_B} C_2(y, t) dy &= \frac{\Delta y}{2\Delta t} \left\{ C_2[(NR - 1)\Delta y, t_{MM} + \Delta t] \right. \\ &\quad \left. - C_2[(NR - 1)\Delta y, t_{MM}] \right\} + O\left(\frac{\Delta t^2 + \Delta y^2}{\Delta t}\right). \end{aligned} \quad (5.20)$$

The spatial derivative on the right-hand side of eq (5.19) at $y = y_B$ is approximated by the central difference approximation (see eq (A8), with $h = \Delta y/2$)

$$\partial_Y C_2 \Big|_{Y=y_B} = \frac{1}{\Delta y} \left\{ C_2(NR\Delta y, t_{MM} + \Delta t) - C_2[(NR - 1)\Delta y, t_{MM} + \Delta t] \right\} + O(\Delta y). \quad (5.21)$$

The spatial derivative at $y = y_A$ on the right-hand side of eq (5.19) is approximated by using the three point formula eq (A9) with:

$$\begin{aligned} X_1 &= NR\Delta y \\ X &= (NR - 1)\Delta y \\ X_2 &= y_O(t_{MM} + \Delta t). \end{aligned}$$

We find

$$\begin{aligned} \partial_Y C_2 \Big|_{Y=y_A} &= \frac{1}{\Delta y} \left\{ \frac{S(2)}{1 + S(2)} C_2((NR)\Delta y, t_{MM} + \Delta t) \right. \\ &\quad + \frac{(1 - S(2))}{S(2)} C_2((NR - 1)\Delta y, t_{MM} + \Delta t) \\ &\quad \left. - \frac{1}{S(2)(1 + S(2))} C_2(y_O(t_{MM} + \Delta t), t_{MM} + \Delta t) \right\} + O(\Delta y^3), \end{aligned} \quad (5.22)$$

where

$$S(2) = -[y_O(t_{MM} + \Delta t) - (NR - 1)\Delta y]/\Delta y . \quad (5.23)$$

When eqs (5.20), (5.21), and (5.22) have been substituted into eq (5.19) and the resulting expression is simplified, it becomes

$$\begin{aligned} & - \frac{1}{1 + S(2)} C_2[y_O(t_{MM} + \Delta t), t_{MM} + \Delta t] \\ & + \left(\frac{S(2)}{R(2)} + 1 \right) C_2[(NR - 1)\Delta y, t_{MM} + \Delta t] \end{aligned} \quad (5.24)$$

$$- \frac{S(2)}{1 + S(2)} C_2(NR\Delta y, t_{MM} + \Delta t) = \frac{S(2)}{R(2)} C_2[(NR - 1)\Delta y, t_{MM} + \Delta t] ,$$

where

$$R(2) = \frac{2 D_2 \Delta t}{\Delta y^2} . \quad (5.25)$$

After introducing the FORTRAN notation in table 9 into eq (5.24), it becomes

$$\begin{aligned} & - \frac{1}{1 + S(2)} CB(2, TTMMPl) + \left(\frac{S(2)}{R(2)} + 1 \right) C2(NR, TTMMPl) \\ & - \frac{S(2)}{1 + S(2)} C2(NR + 1, TTMMPl) = \frac{S(2)}{R(2)} C2(NR, TTMM) . \end{aligned} \quad (5.26)$$

Table 9: FORTRAN Version of Quantities in Eq (5.24).

D_2	$= DF2$
t_{MM}	$= TTMM$
$t_{MM} + \Delta t$	$= TTMMPl$
Δt	$= DT$
Δy	$= DY$
$R(2)$	$= \frac{2 \cdot DF2 \cdot DT}{DY**2}$
$C_2(y_O(t_{MM} + \Delta t), t_{MM} + \Delta t)$	$= CB(2)$
$C_2((NR - 1)\Delta y, t_{MM} + \Delta t)$	$= C2(NR, TTMMPl)$
$C_2((NR - 1)\Delta y, t_{MM})$	$= C2(NR, TTMM)$

Equation (5.26) will be utilized later in section 6.9 to find the quantities PA(2), QA(2) such that

$$C2(NR, TTMMPl) = PA(2) CB(2) + QA(2) \quad (5.26')$$

Schematic summary of the derivation of the tridiagonal FORTRAN equation for the y-grid point NR,

$$(5.19) \rightarrow (5.24) \rightarrow (5.26)$$

Summary note:

Equation (5.26) is used in section 6.9 to determine the quantities PA(2), QA(2) associated with grid point NR.

5.6. The Grid Points Lie at the Moving Boundary and $NL > 1$ (The Preliminary Equation)

The main equation associated with the two unknowns $C_1[z_O(t_{MM} + \Delta t), t_{MM} + \Delta t]$, $C_2[y_O(t_{MM} + \Delta t), t_{MM} + \Delta t]$ located at the grid points which form the interior boundary of the z- and y-regions, respectively, is derived from the integral form of the conservation of number boundary condition eq (2.22), namely

$$\begin{aligned} \frac{d}{dt} \int_{z_A}^{z_O(t_{MM} + \Delta t)} C_1(z, t) dz + \int_{y_O(t_{MM} + \Delta t)}^{y_B} C_2(y, t) dy \\ = - D_1 \partial_z C_1 \Big|_{z=z_A} + D_2 \partial_y C_2 \Big|_{y=y_B} \end{aligned} \quad (5.27)$$

where $z_A = (NL - 1)\Delta z$ and $y_B = (NR - 1)\Delta y$.

Furthermore, it is assumed that the moving boundary $z_O(t)$ is such that $(NL - 1)\Delta z \leq z_O(t) \leq NL\Delta z$, for all times t between t_{MM} and $t_{MM} + \Delta t$. Similarly, for times in this same interval the moving boundary $y_O(t)$ is assumed to satisfy

$$(NR - 2)\Delta y \leq y_O(t) \leq (NR - 1)\Delta y .$$

With these restrictions, eq (5.27) is equivalent to the differential boundary condition eq (2.16).

Before proceeding with the discretization of eq (5.27), it is convenient to introduce immediately the FORTRAN notation in table 10.

Table 10: FORTRAN Symbols Used in Eq (5.28).

$$\begin{aligned}
 C_1((NL - 1)\Delta z, t_{MM} + \Delta t) &= C1(NL, TTMMPl) \\
 C_1((NL - 1)\Delta z, t_{MM}) &= C1(NL, TTMM) \\
 C_2((NR - 1)\Delta y, t_{MM} + \Delta t) &= C2(NR, TTMMPl) \\
 C_2((NR - 1)\Delta y, t_{MM}) &= C2(NR, TTMM) \\
 C_1(z_o(t_{MM} + \Delta t), t_{MM} + \Delta t) &= CB(1, TTMMPl) \\
 C_2(y_o(t_{MM} + \Delta t), t_{MM} + \Delta t) &= CB(2, TTMMPl) \\
 C_1(z_o(t_{MM}), t_{MM}) &= CB(1, TTMM) \\
 C_2(y_o(t_{MM}), t_{MM}) &= CB(2, TTMM)
 \end{aligned}$$

By using the backward difference quotient approximation in eq (A7) to approximate the time derivatives on the left-hand side of eq (5.27) and using the trapezoidal rule to approximate the integrals in the resulting expression, we find (using the notation introduced in table 10) that the left-hand side of eq (5.27) is equivalent to

$$\begin{aligned}
 &\frac{S(1)\Delta z}{2\Delta t} C1(NL, TTMMPl) + CB(1, TTMMPl) + \frac{S(2)\Delta y}{2\Delta t} CB(2, TTMMPl) \\
 &\quad + C2(NR, TTMMPl) - \frac{SM(1)\Delta z}{2\Delta t} C1(NL, TTMM) \\
 &\quad + CB(1, TTMM) - \frac{SM(2)\Delta y}{2\Delta t} CB(2, TTMM) + C2(NR, TTMM) \\
 &\quad + \text{higher order terms in } \Delta y, \Delta z, \Delta t,
 \end{aligned} \tag{5.28}$$

where

$$\begin{aligned}
 S(1) &= [z_o(t_{MM} + \Delta t) - (NL - 1)\Delta z]/\Delta z \\
 SM(1) &= [z_o(t_{MM}) - (NL - 1)\Delta z]/\Delta z \\
 S(2) &= [(NR - 1)\Delta y - y_o(t_{MM} + \Delta t)]/y \\
 SM(2) &= [(NR - 1)\Delta y - y_o(t_{MM})]/\Delta y.
 \end{aligned} \tag{5.29}$$

These are consistent with previous definitions of $S(1)$ and $S(2)$.

When eqs (5.14) and (5.22) (re-expressed in the FORTRAN notation of table 10) are employed to approximate the spatial derivatives on the right-hand side of eq (5.27) and these approximations along with eq (5.28) are substituted into eq (5.27), there results after simplification and up to terms of higher order

$$\begin{aligned}
& \frac{S(1)}{R(1)} C1(NL, TTMP1) + CB(1, TTMP1) + \frac{R \cdot S(2)}{R(2)} CB(2, TTMP1) \\
& + C2(NR, TTMP1) - \frac{SM(1)}{R(1)} C1(NL, TTMM) + CB(1, TTMM) \\
& - \frac{R \cdot SM(2)}{R(2)} CB(2, TTMM) + C2(NR, TTMM) \\
& = -D_1 \left\{ - \frac{S(1)}{1 + S(1)} C1(NL - 1, TTMP1) \right. \\
& + (S(1) - 1) C1(NL, TTMP1) \\
& + \frac{1}{S(1)(1 + S(1))} CB(1, TTMP1) \left. \right\} \\
& + R \left\{ - \frac{1}{S(2)(1 + S(2))} CB(2, TTMP1) \right. \\
& + \frac{1 - S(2)}{S(2)} C2(NR, TTMP1) \\
& + \frac{S(2)}{1 + S(2)} C2(NR + 1, TTMP1) \left. \right\} ,
\end{aligned} \tag{5.30}$$

where

$$\begin{aligned}
R &= \frac{RM}{DR} \\
RM &= \frac{\Delta z}{\Delta y} \\
DR &= \frac{1}{D_2} .
\end{aligned} \tag{5.31}$$

In order to eliminate the division by $S(2)$ (which could have the value zero) in the last term on the right-hand side of eq (5.30), we eliminate that term by substituting from the relation

$$\begin{aligned}
& - \frac{1}{S(2)(1 + S(2))} CB(2, TTMP1) + \frac{1 - S(2)}{S(2)} C2(NR, TTMP1) \\
& + \frac{S(2)}{1 + S(2)} C2(NR, TTMP1) \\
& = C2(NR + 1, TTMP1) - C2(NR, TTMP1) \\
& + \frac{1}{R(2)} [-C2(NR, TTMP1) + C2(NR, TTMM)] .
\end{aligned} \tag{5.32}$$

This latter equation is just the formula [equivalent before simplification to eq (5.24)] that results when eqs (5.20), (5.21), and (5.22) are substituted into eq (5.19) and the FORTRAN notation of table 9 introduced.

If the terms in the brackets on the right-hand side of eq (5.30) are eliminated by substitution from eq (5.32) and if the resulting equation is multiplied through by S(1) (to prevent possible division by zero), then we obtain [after CB(2, TTMMPl) has been replaced by (m = SEG) · CB(1, TTMMPl) using boundary condition eq (2.23)]:

$$\begin{aligned}
& \left[\frac{S(1)^2}{R(1)} + \frac{D_1}{1 + S(1)} + \frac{SEG \cdot S(1) \cdot S(2)}{R(2)} \right] CB(1, TTMMPl) \\
&= \left[-\frac{S(1)^2}{R(1)} + (1 - S(1)) \cdot D_1 \right] C1(NL, TTMMPl) \\
&+ \left[-\frac{R \cdot S(1) \cdot S(2)}{R(2)} - R \cdot S(1) \left(1 + \frac{1}{R(2)} \right) \right] C2(NR, TTMMPl) \\
&+ \frac{S(1)^2 \cdot D_1}{1 + S(1)} C1(NL - 1, TTMMPl) + R \cdot S(1) C2(NR + 1, TTMMPl) \\
&+ \frac{S(1) \cdot SM(1)}{R(1)} \left[C1(NL, TTMM) + CB(1, TTMM) \right] \\
&+ \frac{R \cdot SM(2) \cdot SM(1)}{R(2)} CB(2, TTMM) \\
&+ S(1) \cdot \left(\frac{R \cdot SM(2)}{R(2)} + \frac{R}{R(2)} \right) C2(NR, TTMM) .
\end{aligned} \tag{5.33}$$

Further FORTRAN notation in table 11 can be introduced into eq (5.33) and by using intermediate variables, it can be more compactly rewritten:

$$\begin{aligned}
DM1 \cdot CB(1, TTMMPl) &= DM2 \cdot C1(NL, TTMMPl) + DM3 \cdot C2(NR, TTMMPl) \\
&+ DM4 \cdot C1(NL - 1, TTMMPl) + DM5 \cdot C2(NR + 1, TTMMPl) + DM6 ,
\end{aligned} \tag{5.34}$$

where

$$\begin{aligned}
DM1 &= \frac{S(1)**2}{R(1)} + \frac{DF1}{1 + S(1)} + \frac{SEG \cdot RT \cdot S(1) \cdot S(2)}{R(2)} , \\
DM2 &= -\frac{S(1)**2}{R(1)} + DF1 \cdot (1 - S(1)) , \\
DM3 &= -\frac{RT \cdot S(1) \cdot S(2)}{R(2)} - RT \cdot S(1) \cdot \left(1 + \frac{1}{R(2)} \right) , \\
DM4 &= \frac{DF1 \cdot S(1)**2}{1 + S(1)} ,
\end{aligned} \tag{5.34'}$$

$$DM5 = RT \cdot S(1) , \text{ and}$$

$$\begin{aligned} DM6 &= \frac{S(1) \cdot SM(1)}{R(1)} C1(NL, TTMM) + CB(1, TTMM) \\ &+ \frac{RT \cdot SM(2) \cdot S(1)}{R(2)} CB(2, TTMM) \\ &+ S(1) \cdot \frac{RT \cdot SM(2) - RT}{R(2)} \cdot C2(NR, TTMM) , \end{aligned}$$

and where

$$\begin{aligned} R &= RT = \frac{DF2 \cdot DZ}{DY} , \\ R(1) &= \frac{2 \cdot DT}{DZ^{**2}} , \\ R(2) &= \frac{2 \cdot DF2 \cdot DT}{DY^{**2}} , \\ S(1) &= (ZOP1 - (NL - 1) \cdot DZ)/DZ , \\ S(2) &= ((NR - 1)DY - YOP1)/DY , \\ SM(2) &= ((NR - 1)DY - Y_O(t_{MM}))/DY , \text{ and} \\ SM(1) &= (z_O(t_{MM}) - (NL - 1)DZ)/DZ . \end{aligned} \tag{5.35}$$

Table 11: FORTRAN Version of Symbols in Eq (5.33).

$$\begin{aligned} \Delta t &= DT \\ \Delta y &= DY \\ \Delta z &= DZ \\ z_O(t_{MM} + \Delta t) &= ZOP1 \\ y_O(t_{MM} + \Delta t) &= YOP1 \\ D_1 &= DF1 \\ D_2 &= DF2 \end{aligned}$$

SUMMARY

Schematic summary of the derivation of the FORTRAN equation for the z-grid point at the moving boundary, i.e., at $(z_O(t_{MM} + \Delta t))$, when $NL > 1$:

$$(5.27) \rightarrow (5.33) \rightarrow (5.34) \text{ and } (5.34') .$$

Summary notes:

- (1) All the concentrations on the right-hand side of eq (5.34), i.e., $C1(NL, TTMMPl), \dots, C2(NR + 1, TTMMPl)$ will be eliminated in terms of known quantities and thereby $CB(1, TTMMPl)$ will be found. This is carried through in section 6.10.
- (2) The concentrations in DM6 are known because they are evaluated at time TTMM.

5.7. The Grid Point Is at the Moving Boundary and $NL = 1$

The derivation of the preliminary equations for $C1(z_O(t_{MM} + \Delta t), t_{MM} + \Delta t)$ is very similar to the derivation of the preliminary equation for the same quantity in the previous section, so if the user desires more details than are given below, he should refer to that section.

We again begin with the conservation eq (5.27). However, instead of approximating the spatial derivative at $z = z_A$ by eq (5.14), we use boundary condition eq (2.24). Because of this change, we find in place of eq (5.30)

$$\begin{aligned}
 & \frac{S(1)}{R(1)} [C1(NL, TTMMPl) + CB(1, TTMMPl)] \\
 & + \frac{R \cdot S(2)}{R(2)} [CB(2, TTMMPl) + C2(NR, TTMMPl)] \\
 & - \frac{SM(1)}{R(1)} [C1(NL, TTMM) + CB(1, NR, TTMM)] \\
 & - \frac{R \cdot SM(2)}{R(2)} [CB(2, TTMM) + C2(NR, TTMM)] \quad (5.36) \\
 & = - [+ C_p \Delta z (C1(1, TTMMPl) - C_{out})] \\
 & + R \left[- \frac{1}{S(2)(1 + S(2))} CB(2, TTMMPl) + \frac{1 - S(2)}{S(2)} C2(NR, TTMMPl) \right. \\
 & \left. + \frac{S(2)}{1 + S(2)} C2(NR + 1, TTMMPl) \right].
 \end{aligned}$$

When the term in the second parenthesis on the right-hand side of eq (5.36) is eliminated by using eq (5.32), there results

$$\begin{aligned}
 & \frac{S(1)}{R(1)} [C1(NL, TTMMPl) + CB(1, TTMMPl)] \\
 & + \frac{R \cdot S(2)}{R(2)} [CB(2, TTMMPl) + C2(NR, TTMMPl)]
 \end{aligned}$$

$$\begin{aligned}
& - \frac{SM(1)}{R(1)} [C1(NL, TTMM) + CB(1, TTMM)] \\
& - \frac{R \cdot SM(2)}{R(2)} [CB(2, TTMM) + C2(NR, TTMM)] \quad (5.37) \\
& = -[C_p \Delta z (C1(1, TTMP1) - C_{out})] \\
& + R [C2(NR + 1, TTMP1) - C2(NR, TTMP1)] \\
& + \frac{R}{R(2)} [-C2(NR, TTMP1) + C2(NR, TTMM)] .
\end{aligned}$$

By rearranging terms and introducing the FORTRAN symbols in eq (5.35) into eq (5.37), we get

$$\begin{aligned}
DM1 \cdot CB(1, TTMP1) &= DM2 \cdot C1(NL, TTMP1) + DM3 \cdot C2(NR, TTMP1) \\
&+ DM4 \cdot C1(NL - 1, TTMP1) \quad (5.38) \\
&+ DM5 \cdot C2(NR + 1, TTMP1) + DM6 ,
\end{aligned}$$

where

$$\begin{aligned}
DM1 &= \frac{S(1)}{R(1)} + \frac{RT \cdot S(2) \cdot SEG}{R(2)} , \\
DM2 &= - \frac{S(1)}{R(1)} + CONPRO \cdot DZ , \\
DM3 &= - \frac{RS(2)}{R(2)} - R \left(1 + \frac{1}{R(2)} \right) , \quad (5.38') \\
DM4 &= 0 , \\
DM5 &= RT , \text{ and} \\
DM6 &= \frac{SM(1)}{R(1)} [C1(NL, TTMM) + CB(1, TTMM)] \\
&+ \frac{RT \cdot SM(2)}{R(2)} [CB(2, TTMM)] \\
&+ \frac{RT \cdot SM(2) - RT}{R(2)} [C2(NR, TTMM)] \\
&+ DZ \cdot CONPRO \cdot CONOUT ,
\end{aligned}$$

and where the FORTRAN symbols above are the same as in eq (5.35) with the addition of the ones in table 12.

Table 12: Additional FORTRAN Symbols for Eq (5.38).

$$\begin{aligned} C_p &= \text{CONPRO} \\ C_{\text{out}} &= \text{CONOUT} \end{aligned}$$

Notice that the quantities DM3, DM5, and DM6 [with DZ = CONPRO * CONOUT added to it in eq (5.34')] are equal to their counterparts in eq (5.38') when S(1) = 1. Hence, by setting S(1) to 1 when we are computing these quantities, i.e., in the case NL = 1, we can use the same FORTRAN expression as is used to compute these quantities in eq (5.34') when NL > 1.

Of course in computing in this way we must leave the S(1) in DM1 and DM2 of eq (5.38') unchanged. This can be done, when NL = 1, by introducing the quantity SAVE which is equal to S(1) and replacing S(1) where it appears in DM1 and DM2 by the symbol SAVE.

SUMMARY

Schematic summary for obtaining the preliminary equation for the z-grid point at the moving boundary when NL = 1.

$$(5.27) \rightarrow (5.37) \rightarrow (5.38) \text{ and } (5.38')$$

Summary notes:

- (1) Since the coefficients of the concentrations on the right-hand side of eq (5.38) are the same as those on the right-hand side of eq (5.34), the concentrations from both of these preliminary equations can be eliminated by the same procedure which will be described in section 6.10.
- (2) The actual computation of the quantities in eq (5.38') are carried through as described above in computing block #4 of subroutine CENTER, see section 7.2.

5.8. The Index of the Z-Grid Point is 1 and NL > 1

The derivation of the tridiagonal algebraic equation that is associated with the z-grid point 1 (when the moving boundary has reached the second z-grid point) begins with the conservation of number eq (2.20)

$$\frac{d}{dt} \int_{z_A}^{z_B} C_1(z,t) dz = -D_1 \partial_z C_1 \Big|_{z=z_A} + D_1 \partial_z C_1 \Big|_{z=z_B} \quad (5.39)$$

where $z_A = 0$ and $z_B = \Delta z/2$ denote the positions of the flux boundaries.

After approximating the time derivative on the left-hand side of eq (5.38) by the back difference quotient approximation eq (A7) and the integrals by quadrature formulas with a node at the left-hand end point, we find

$$\frac{d}{dt} \int_0^{z_0(t_{MM} + \Delta t)} C_1(z, t) dz = \frac{1}{\frac{2\Delta t}{\Delta z}} [C_1(0 \cdot \Delta z, t_{MM} + \Delta t) - C_1(0 \cdot \Delta z, t_{MM})] + O(\Delta z^2 + \Delta t^2/\Delta t) . \quad (5.40)$$

By substituting from eq (2.24),

$$C_p (C_1(0 \cdot \Delta z, t_{MM} + \Delta t) - C_{out})$$

for $D_1 \partial_z C_1 \Big|_{z=z_A}$ on the right-hand side of eq (5.39) and then

$$D_1 (C_1(\Delta z, t_{MM} + \Delta t) - C_1(0 \cdot \Delta z, t_{MM} + \Delta t))$$

for $D_1 \partial_z C_1 \Big|_{z=z_B}$ on the right-hand side of eq (5.39), that equation

yields together with eq (5.40) after simplification

$$\left[\left(\frac{2\Delta t}{\Delta z^2} \right)^{-1} + \Delta z \cdot C_p + D_1 \right] C_1(0 \cdot \Delta z, t_{MM} + \Delta t) = D_1 C_1(\Delta z, t_{MM} + \Delta t) + \frac{C_1(\Delta z, t_{MM})}{\frac{2 \cdot \Delta t}{\Delta z^2}} + \Delta z \cdot C_p \cdot C_{out} . \quad (5.41)$$

After introducing into eq (5.41) the FORTRAN notation in table 13, that equation becomes

$$\left[\left(\frac{2DT}{DZ^2} \right)^{-1} + DZ \cdot CONPRO + DF1 \right] Cl(y, TTMMPl) = DF1 \cdot Cl(2, TTMMPl) + \frac{Dl(1, TTMM)}{\frac{2DT}{DZ^{**2}}} + DZ \cdot CONPRO \cdot CONOUT . \quad (5.42)$$

Table 13: FORTRAN Version of Quantities in Eq (5.41).

```

Δt = DT
Δz = DZ
CP = CONPRO
Cout = CONOUT
D1 = DF1
C1(0 · Δz, tMM + Δt) = C1(1, TTMMPl)
C1(0 · Δz, tMM) = C1(1, TTMM)
C2(Δz, tMM + Δt) = C2(2, TTMMPl)

```

Equation (5.42) is the FORTRAN tridiagonal equation which will give rise to the "P, Q" quantities associated with the z-grid point 1 and unknown C1(1, TTMMPl). This is carried through in section 6.4.

SUMMARY

Schematic summary of the derivation of the FORTRAN tridiagonal equation for the z-grid point 1 when the moving boundary is beyond z-grid point 2.

$$(5.39) \rightarrow (5.41) \rightarrow (5.42).$$

Summary note:

The FORTRAN eq (5.42) leads to values of P1(1), Q1(1) that are computed in computational block #24 of the main program. See section 6.4 for the derivation of these "P, Q" quantities.

5.9. The Index of the Z-Grid Point is 1 and NL = 1

This equation is different from all the others in that it is not developed from an integral conservation equation. It is basically derived from combining eq (2.14) with a Taylor series expansion.

From a spatial Taylor's formula expansion of $C_1(z, t_{MM} + \Delta t)$, we have

$$\begin{aligned}
 C_1(z_O(t_{MM} + \Delta t)) &= C_1(0, t_{MM} + \Delta t) + \left. \partial_z C_1 \right|_{z=0} z_O(t_{MM} + \Delta t) \\
 &+ 1/2 \left. \partial_z^2 C_1 \right|_{z=0} (z_O(t_{MM} + \Delta t))^2 + O(\Delta z^3).
 \end{aligned}
 \tag{5.43}$$

By defining

$$S(1) = z_o (t_{MM} + \Delta t) / \Delta z$$

and substituting this together with (from eq (2.14))

$$\partial_z^2 C_1 = \partial_t C_1 / D_1$$

into eq (5.43), it becomes after rearranging and up to higher order terms

$$\begin{aligned} D_1 C_1(z_o(t_{MM} + \Delta t), t_{MM} + \Delta t) &= D_1 C_1(0, t_{MM} + \Delta t) + D_1 \partial_z C_1 \Big|_{z=0} (S(1) \Delta z) \\ &+ 1/2 \partial_t^2 C_1 \Big|_{z=0} (S(1) \cdot \Delta z)^2 . \end{aligned} \quad (5.44)$$

When the backward difference approximation,

$$\partial_t C_1 = (C_1(0, t_{MM} + \Delta t) - C_1(0, t_{MM})) / \Delta t + O(\Delta t) ,$$

and the expression from eq (2.24),

$$D_1 \partial_z C_1 \Big|_{z=0} = C_p (C_1(0, t_{MM} + \Delta t) - C_{out}) , \quad (5.45)$$

are substituted into eq (5.44), it becomes, after rearrangement (ignoring higher order terms),

$$\begin{aligned} &\left[D_1 + \frac{(S(1) \Delta z)^2}{\Delta t \cdot 2} + S(1) \cdot \Delta z \cdot C_p \right] C_1(0, t_{MM} + \Delta t) \\ &= D_1 C_1(z_o(t_{MM} + \Delta t), t_{MM} + \Delta t) \\ &+ C_1(0, t_{MM}) \cdot \frac{(S(1) \cdot \Delta z)^2}{2 \Delta t} + S(1) \cdot \Delta z \cdot C_p \cdot C_{out} . \end{aligned} \quad (5.46)$$

By transferring the symbols in eq (5.46) through the correspondences in table 14, that equation becomes

$$\begin{aligned} DF1 + \frac{(S(1) \cdot DZ)^{**2}}{2 \cdot DT} + S(1) \cdot DZ \cdot CONPRO \cdot Cl(1, TTMMPl) \\ = DF1 CB(1, TTMMPl) + Cl(1, TTMM) \frac{(S(1) \cdot DZ)^{**2}}{2DT} \\ + S(1) \cdot DZ \cdot CONPRO \cdot CONOUT . \end{aligned} \quad (5.47)$$

Table 14: FORTRAN Version of Quantities in Eq (5.46).

$$\begin{aligned}
 D_1 &= DF1 \\
 \Delta z &= DZ \\
 \Delta t &= DT \\
 C_1(0, t_{MM} + \Delta t) &= C1(1, TTMMPl) \\
 C_1(0, t_{MM}) &= C1(1, TTMM) \\
 C_1(z_O(t_{MM} + \Delta t), t_{MM} + \Delta t) &= CB(1, TTMMPl) \\
 C_p &= CONPRO \\
 C_{out} &= CONOUT
 \end{aligned}$$

FORTRAN tridiagonal eq (5.47) will lead to the quantities $P1(1)$, $Q1(1)$ in section 6.3. These are the "P, Q" associated with z-grid point 1 when the moving boundary has not yet reached the second z-grid point.

Notice that when $t_{MM} = 0$ the quantity $C1(1,0)$ is unknown, i.e., it is not given as data in the problem. Thus, the equation we use in place of eq (5.46) for the first iteration $MM = 1$ when $t_{MM} = 0$ is

$$\begin{aligned}
 (DF1 + S(1) \cdot DZ \cdot CONPRO) \cdot C1(1, TTMMPl) &= DF1 \cdot CB(1, TTMMPl) \\
 + S(1) \cdot DZ \cdot CONPRO \cdot CONOUT &.
 \end{aligned} \tag{5.48}$$

This is the equation we would have arrived at if we had truncated the Taylor's formula in eq (5.43) to first order terms and proceeded just as above, and eq (5.48) is consistent with, i.e., the same as, the formula we would get by approximating eq (5.45) directly.

SUMMARY

Schematic summary of the derivation of the FORTRAN tridiagonal equation associated with the z-grid point 1 when $NL = 1$,

$$(5.43) \rightarrow (5.45) \rightarrow (5.47) \text{ or } (5.48) \text{ (use (5.48) when } t_{MM} = 0 \text{)}.$$

Summary note:

The "P, Q" terms that result from eq (5.47) or eq (5.48) are derived in sections 6.2 and 6.3.

6. METHOD OF SOLVING THE ALGEBRAIC EQUATIONS

6.1. The Derivation of the "Double Sweep" "P, Q" Coefficients Associated with the Grid Points

In this section we put each of the tridiagonal FORTRAN equations associated with the fixed grid points in "double sweep" form. Specifically, we manipulate these tridiagonal FORTRAN eqs (3.2) and (3.3) into the forms

$$C1(J, TTMMPl) = P1(J) C1(J + 1, TTMMPl) + Q1(J) \quad (6.1)$$

for $J = 1, \dots, NL - 1$, and

$$C1(NL, TTMMPl) = PA(1) CB(1, TTMMPl) + QA(1) . \quad (6.2)$$

Also, at the fixed grid points in the y-region,

$$C2(J, TTMMPl) = P2(J) C1(J + 1, TTMMPl) + Q2(J) \quad (6.3)$$

for $J = NR + 1, \dots, N2$, and

$$C2(NR, TTMMPl) = PA(2) CB(2, TTMMPl) + QA(2) . \quad (6.4)$$

Once again the specific composition of the double sweep "P, Q" factors associated with a grid point depends on the location of the grid point and the position of the moving boundary at time TTMMPl. The following table 15 completely classifies all the cases that arise. Of course, because the "P, Q" coefficients for a grid point are obtained from the tridiagonal equation associated with that grid point, this table is the same as table 3 except for Case I(e) and Case II(g) which were not included in table 3 (since they are so trivial).

Table 15: Guide to the Subsections Where the "P, Q" Coefficients Associated With Each of the Fixed Grid Points Are Derived and Described.

Case I: The index NL equals 1:

- (a) The first z-grid point, see sections 6.2 and 6.3.
- (b) The index of the y-grid point is greater than NR, see section 6.8.
- (c) The index of the y-grid point is NR, see section 6.9.
- (d) The grid point lies at the moving boundary, see section 6.10.
- (e) The largest y-grid point, which has index N2 and is located at $y = BDRY = NYO \cdot DY$, see section 6.7.

Case II: The index NL is greater than 1.

- (a) The index of the z-grid point is 1, see section 6.4.
 - (b) The index of the z-grid points ranges from 2 to NL - 1, see section 6.8.
 - (c) The index of the z-grid point is NL, see section 6.6.
 - (d) The grid point is at the moving boundary, see section 6.10.
 - (e) The index of the y-grid point is greater than NR, see section 6.8.
 - (f) The index of the y-grid point is NR, see section 6.9.
 - (g) The index of the y-grid point is N2 and is at $y = \text{BDRY}$, see section 6.7.
-

6.2. The First Z-Grid Point When $NL = 1$ and $t_{MM} = \text{TTMM} = 0$

After dividing both sides of eq (5.48) by $(\text{DF1} + S(1) \cdot \text{DZ} \cdot \text{CONRPO})$, we get

$$\text{C1}(1, \text{TTMMP1}) = \text{P1}(1) \cdot \text{CB}(1, \text{TTMMP1}) + \text{Q1}(1) \quad (6.5)$$

where

$$\begin{aligned} \text{P1}(1) &= \text{DM} \cdot \text{DF1} \\ \text{Q1}(1) &= \text{DM} \cdot (\text{C1}(1) \cdot \text{DM3} + \text{DM1} \cdot \text{CONPRO} \cdot \text{CONOUT}) \\ \text{DM1} &= S(1) \cdot \text{DZ} \\ \text{DM2} &= 0 \\ \text{DM3} &= \text{DM2} \\ \text{DM} &= (\text{DF1} + \text{DM2} + \text{DM1} \cdot \text{CONPRO})^{-1} \end{aligned} \quad (6.5')$$

The introduction of the zero quantities DM2, DM3 into the above equations enables us to use below in section 6.3 the same expression DM but with $\text{DM2}, \text{DM3} \neq 0$.

SUMMARY

Equations (6.5') are calculated in computational block #23 of the main program (see sec. 7.1).

6.3. The First Z-Grid Point When $NL = 1$ and $t_{MM} = \text{TTMM} > 0$

When eq (5.47) is divided through by $\text{DF1} + \frac{(S(1) \cdot \text{DZ})^{**2}}{2 \text{DT}} + S(1) \cdot \text{DZ} \cdot \text{CONPRO}$, there results

$$\text{C1}(1, \text{TTMMP1}) = \text{P1}(1) \text{CB}(1, \text{TTMMP1}) + \text{Q1}(1) \quad (6.6)$$

with

$$\begin{aligned}
P1(1) &= DM \cdot DF1 \\
Q1(1) &= DM \cdot (C1(1, TTMM) \cdot DM3 + DM1 \cdot CONPRO \cdot CONOUT) \\
DM &= (DF1 + DM2 + DM1 \cdot CONPRO)^{-1} \\
DM1 &= S(1) \cdot DZ \\
DM2 &= (DM1)^2 / 2 \cdot DT \\
DM3 &= DM2 .
\end{aligned} \tag{6.6'}$$

SUMMARY

Note that all quantities in eq (6.6') are the same as in eq (6.5') except for DM2 and DM3. The calculation of the quantities in eq (6.6') takes place in computational block #23 of the main program (see sec. 7.1).

6.4. The Index of the Z-Grid Point is 1 and $NL > 1$

After dividing eq (5.42) by $\frac{(DZ)^{**2}}{2 \cdot DT} + DZ \cdot CONPRO + DF1$, it becomes

$$C1(1, TTMM1) = P1(1) \cdot C1(2, TTMM1) + Q1(1) \tag{6.7}$$

where

$$\begin{aligned}
P1(1) &= DF1 \cdot DM \\
Q1(1) &= DM \cdot C1(1, TTMM) \cdot \frac{DZ^{**2}}{2 \cdot DT} + DZ \cdot CONPRO \cdot CONOUT \\
DM &= \frac{DZ^{**2}}{2 \cdot DT} + DZ \cdot CONPRO + DF1 .
\end{aligned} \tag{6.7'}$$

SUMMARY

The quantities in eq (6.7') are computed in computational block #24 of the main program (see sec. 7.1).

6.5. The Index of the Z-Grid Point is Between 1 and $NL - 1$ and $NL > 2$

We begin with eq (5.7) which holds for the indices $J = 2, \dots, NL - 1$. Assume that for one of the indices in this range

$$C1(J - 1, TTMM1) = P1(J - 1) \cdot C1(J, TTMM1) + Q1(J - 1) . \tag{6.8}$$

After substituting this value of $C1(J - 1, TTMM1)$ into the left-hand side of eq (5.7) and rearranging the terms, there results

$$C1(J, TTMM1) = P1(J) \cdot C1(J + 1, TTMM1) + Q1(J) \tag{6.9}$$

where

$$P1(J) = -A2R/D1(J)$$

$$Q1(J) = (AF(J) - Q1(J - 1)A2L)/D1(J) \quad (6.9')$$

$$D1(J) = A2M = P1(J - 1) \cdot A2L .$$

Notice that eq (6.8) with $J = 2$ holds because of eq (6.7). Hence, by induction we get eqs (6.9) and (6.9') for $J = 2, \dots, NL - 1$.

SUMMARY

Summary notes:

- (1) The arrays $P1(J)$, $D1(J)$ are computed in computational block #3 of subroutine TRIDNL.
- (2) The quantities $A2L, \dots, A1M$ (see table 5) are computed in subroutine INTER which is called by subroutine TRIDNL when $P1(J)$, $D1(J)$ are being computed.
- (3) The arrays $AF(J)$, $Q1(J)$ are calculated in computational block #25 of the main program.

6.6 The Index of the Z-Grid Point is NL and $NL > 1$

When eq (5.17) is multiplied through by $S(1)$ (since $S(1)$ may be zero, this prevents possible division by zero) and the terms are transposed, there results

$$\begin{aligned} DM1 \ C1(NL, TTMMPl) &= DM2 \ CB(1, TTMMPl) \\ &+ DM3 \ C1(NL - 1, TTMMPl) + DM4 , \end{aligned} \quad (6.10)$$

with

$$\begin{aligned} DM &= 1 + S(1) \\ DM &= DF1 + \frac{S(1)}{R(1)} \\ DM2 &= DF1/(1 + S(1)) = DF1/DM \\ DM3 &= DF1 \cdot S(1)/(1 + S(1)) = DF1 \cdot DM2 \\ DM4 &= \frac{S(1)}{R(1)} \ C1(NL, TTMM) . \end{aligned} \quad (6.10')$$

We also have from eq (6.9) with $J = NL - 1$,

$$C1(NL - 1, TTMMPl) = P(1) \ C1(NL, TTMMPl) + Q(1) \quad (6.11)$$

where we have used the abbreviations

$$\begin{aligned} P(1) &= P1(NL - 1) \\ Q(1) &= Q1(NL - 1) . \end{aligned} \quad 6.11'$$

When eq (6.11) is substituted into the right-hand side of eq (6.10) and the result is simplified, we find

$$C1(NL, TTMMPl) = PA(1) CB(1, TTMMPl) + QA(1) \quad (6.12)$$

where

$$\begin{aligned} PA(1) &= DM2/(DM1 - DM3 \cdot P(1)) \\ QA(1) &= (DM4 + Q(1) \cdot DM3)/(DM1 - DM3 \cdot P(1)) \end{aligned} \quad (6.12')$$

SUMMARY

The quantities in eqs (6.10') and (6.12') are evaluated in computational block #3 of subroutine CENTER.

6.7. The Index of the Y-Grid Point is $N2 = NYO + 1$ and is located at $y = BDRY$

The boundary condition for $C2(,)$ at the boundary point $y = BDRY$ is (see eq (2.12))

$$C2(N2, TTMMPl) = CBULK. \quad (6.13)$$

We rewrite this simple equation for use later on in the more convenient form

$$C2(N2, TTMMPl) = P2(N2) C2(N2 - 1, TTMMPl) = Q2(N2), \quad (6.14)$$

if we assume (and we do)

$$\begin{aligned} P2(N2) &= 0 \\ Q2(N2) &= CBULK. \end{aligned} \quad (6.14')$$

SUMMARY

The quantities in eq (6.14') are calculated in computational block #13 of the main program. These quantities are used in block #26 of the main program (see sec. 7.1) and block #4 of subroutine INTER (see sec. 7.3).

6.8. The Index of the Y-Grid Point is Between NR and N2

We start with tridiagonal eq (5.10) which holds for $J = NR + 1, \dots, N2 - 1$.

Assume for one of the indices in this range that

$$C2(J + 1, TTMMPl) = P2(J + 1) C2(J, TTMMPl) + Q2(J + 1). \quad (6.15)$$

After substituting this value of $C2(J + 1, TTMMPl)$ into the left-hand side of eq (5.10), with J in place of $J - 1$, and rearranging terms, it becomes for $J = NR + 1, \dots, N2 - 1$

$$C2(J, TTMMPl) = P2(J) C2(J - 1, TTMMPl) + Q2(J) \quad (6.16)$$

where

$$\begin{aligned} P2(J) &= - \frac{1}{D2(J)} \\ Q2(J) &= (BF(J) - Q2(J + 1) B2R)/D2(J) \\ D2(J) &= B2M + P2(J + 1) B2R \end{aligned} \quad (6.16')$$

or, since $B2R = 1$ from table 7,

$$D2(J) = B2M + P2(J + 1) .$$

Notice that eq (6.15) with $J = N2 - 1$ holds because of eq (6.14). Hence, by induction we get eq (6.16) and eq (6.16') for $J = NR + 1, \dots, N2 - 1$.

SUMMARY

Summary notes:

- (1) The arrays $P2(J)$, $D2(J)$ are calculated in computational block #4 of subroutine TRIDNL.
- (2) The quantities $B2M$, $B1M$ (the other B's equal 1) are computed in subroutine INTER which is called by subroutine TRIDNL when $P2(J)$, $D2(J)$ are computed.
- (3) The arrays $Q2(J)$, $BF(J)$ are calculated in computational block #26 of the main program.

6.9. The Y-Grid Point has Index NR

After transposing terms in the tridiagonal FORTRAN eq (5.26), it takes the form

$$\begin{aligned} DM1 C2(NR, TTMMPl) &= DM2 CB(2, TTMMPl) \\ &+ DM3 C2(NR + 1, TTMMPl) + DM4 \end{aligned} \quad (6.17)$$

where

$$\begin{aligned} DM1 &= 1 + \frac{S(2)}{R(2)} \\ DM2 &= \frac{1}{1 + S(2)} \\ DM3 &= S(2)/(1 + S(2)) \\ DM4 &= \frac{S(2)}{R(2)} C2(NR, TTMM) . \end{aligned} \quad (6.17')$$

We also have from eq (6.16) with $J = NR + 1$

$$C2(NR + 1, TTMMPl) = P(2) \cdot C2(NR, TTMMPl) + Q(2) \quad (6.18)$$

where we have used the abbreviations

$$\begin{aligned} P(2) &= P2(NR + 1) \\ Q(2) &= Q2(NR + 1) . \end{aligned} \quad (6.18')$$

When eq (6.18) is substituted into the right-hand side of eq (6.17) and the result is simplified, we find

$$C2(NR, TTMMPl) = PA(2) CB(2, TTMMPl) + QA(2) \quad (6.19)$$

where

$$\begin{aligned} PA(2) &= DM2 / (DM1 - DM3 \cdot P(2)) \\ QA(2) &= (DM4 + Q(2) \cdot DM3) / (DM1 - DM3 \cdot P(2)) . \end{aligned} \quad (6.19')$$

SUMMARY

The quantities eqs (6.17') and (6.19') are evaluated in computational block #3 of subroutine CENTER.

6.10. The Determination of $CB(1, TTMMPl)$ in Terms of Known Quantities

The values of the "P, Q" coefficients in the eqs (6.1) through (6.4) are determined by the coefficients in the tridiagonal eqs (3.2) and (3.3) and these in turn are composed of known mesh parameters, material parameters and concentrations evaluated at time TTMM. Hence, by using eqs (6.1) through (6.4), we can eliminate the concentrations evaluated at time TTMMPl that occur on the right-hand side of the "preliminary" eq (5.34) and thereby determine the value of $CB(1, TTMMPl)$ entirely in known quantities.

More precisely, substituting eqs (6.11) and (6.18) into the right-hand side of the "preliminary equation," i.e., eq (5.34) for $NL > 1$ (and eq (5.38) for $NL = 1$), we get

$$\begin{aligned} DM1 \cdot CB(1, TTMMPl) &= DM8 \cdot C1(NL, TTMMPl) \\ &+ DM9 \cdot C2(NR, TTMMPl) + DM10 \end{aligned} \quad (6.20)$$

where

$$\begin{aligned} DM8 &= DM2 + DM4 \cdot P(1) \\ DM9 &= DM3 + DM5 \cdot P(2) \\ DM10 &= DM6 + Q(1) \cdot DM4 + Q(2) \cdot DM5 . \end{aligned} \quad (6.20')$$

Finally eliminating the concentrations at the grid point NL and NR on the right-hand side of eq (6.20) by use of eqs (6.12) and (6.19) leads to the

expression for $CB(1, TTMP1)$ in terms of known quantities

$$CB(1, TTMP1) = \frac{DM11}{DM12}, \quad (6.21)$$

with

$$DM12 = DM1 - DM8 \cdot PA(1) - SEG \cdot DM9 \cdot PA(2) \quad (6.21')$$

$$DM11 = DM10 + QA(1) \cdot DM8 + QA(2) \cdot DM9,$$

and where

DM1

DM2

DM3

are given in eq (5.39) if $NL = 1$

DM4 eq (5.34) if $NL > 1$

DM5

DM6

and furthermore,

PA(2)
QA(2) are given in eq (6.19')

P(2)
Q(2) are given in eq (6.18')

PA(1)
QA(1) are given in eq (6.12')

P(1)
Q(1) are given in eq (6.11')

R(1) is given in eq (5.16')

R(2) is given in eq (5.35)

RT = R is given in eq (5.31)

(6.22)

SUMMARY

The quantities in eqs (6.21), (6.21') and all the quantities listed below eq (6.21') are computed in computational block #4 of subroutine CENTER to find the value of $CB(1, TTMP1)$.

7. DETAILED DESCRIPTION OF THE PROGRAM

7.1. Block-by-Block Detailed Description of the Computational Procedure in the Main Program

As is shown in the program listing (Chapter 11), the overall calculations in DISTRIB: VERSION 1 are broken down into a set of consecutive blocks. The computations in each of these blocks have a unified purpose which is described with pertinent comments for each of these blocks #1 through #36 in this chapter. In Chapter 8, the logic in these blocks is flow charted. The precise calculations carried through in each of these blocks are shown in the program listing in Chapter 11, and the material in the following blocks is intended to illuminate the contents by organizing and elaborating on the material in the listing rather than to re-describe the contents in a different language.

IMPORTANT: Quantities with names which appear in the program listing but do not appear in the glossary are not needed or used in DISTRIB: VERSION 1 and therefore should be ignored, i.e., all material in the listing that is not in a block or glossary.

Block #1: Input Declaration, Type Statements, Dimensionalize Arrays and Common Blocks

The arrays SRL() and YRL() are declared real because of certain constraints in the plotting routines where these arrays are employed. The fact that they are dimensionalized by 200 means that only 200 data points can be plotted in a single call of the plot routine.

Arrays that have an element associated with each grid point, e.g., C2(J) (see glossary) are dimensionalized by 2000. This means the maximum number of grid points is 2000 and the maximum number of mesh widths in either region must be less than 2000.

Since the number of cells of the array C1() actually used is, at time TTMMPL, equal to $NR \cdot NZO$, the input quantities NZO and TFINAL (which together with the equation of the moving boundary determine the largest possible value NR takes) must be constrained so that the product $NR \cdot NZO$ is always less than the dimension of C1().

Many of the arrays are dimensionalized in common blocks because they are also used in subroutines.

Block #2: Input the Proper Problem and Material Parameters with Accompanying Format Declarations

The definition of each of the input quantities is to be found in the glossary, where references are given to places in the main body of this documentation which contain more elaborate descriptions of these quantities. The list of input and output is given in section 9.2 in a systematic fashion and in classified form.

Real input is read under format 4 and real output printed under format 5. Integer input and output are under format 1.

A table listing the input data is found in section 9.2 along with ranges of values for the input parameters that have worked well in trial runs. The units for the input data are micrometers, hours. The problem with CONOUT = 0 is homogeneous in the concentrations, and therefore the input concentrations are normalized to CBULK = 1. By homogeneous is meant the value of $C_i(x,t)$ for CBULK = A is equal to $C_i(x,t)$ [for CBULK = 12 times A.

Block #3: Store Input in Terms of Their Original Dimension Units

In the next block certain input parameters are dimensionalized (rescaled). Consequently, these input quantities are stored in their original units in the array PARAM so they can be printed out later in block #34 in their original units. Also, before its defining quantities are changed, the quantity SCALE2 (in micrometers which is used to scale the distance along the y-coordinate system, i.e., in the silicon, in the plots that are printed in block #34 is calculated and stored for later output. The reason SCALE2 does not appear in the plot routine is that its role there is played by UN2 which represents the same physical quantity as SCALE2 but is in units of BLTH rather than micrometers. The fact that DY, YOP1, etc., when they appear in the plot routines are in BLTH units requires the use of UN2 instead of SCALE2. A detailed description of the dimensionalization procedure is given in section 4.3.

Block #4: Redimension the Input Data by Introducing Computationally Efficient Units

The dimensionalization carried out here is described in section 4.3 in detail. Note that, in Version 1, DFC is set equal to 1 in a declare card. Thus, during the calculations, DF2 will have the value 1 and DF1 will be the ratio DF1/DF2. The computational formula for BTM is given in eq (4.10).

Block #5: Compute the Values of the Grid Mesh Widths

This is the step described in section 4.1 where DY and DZ, the mesh widths in the y- and z-regions, respectively, are calculated. The computational formula for DY is eq (4.1) and eq (4.3) for DZ.

Block #6: Compute the Value of ZCRIT = CNSTX.

In this step CNSTX, which is another name for ZCRIT, is calculated, see section 4.2. The quantities CNA and CNB are just two intermediate variables used in computing DNSTX and ZOP1, ZOP2 later on.

Block #7: Compute the Time Increment DT for the First Iteration of the Main Loop 78

In this block the main purpose is to compute the initial value of Δt ($= DT$). Recall, from section 4.2, that in the "wet oxidation" Case I the time $TLIN = CNTAU = \tau = 0$, so the motion of the moving boundary is always parabolic. In this case DT is defined as the time it takes the moving boundary to move the distance $DM = WFRC \cdot DZ$, having started at $Z = 0$. The number $WFRC$ must be positive, real, and less than 1, for the program to be stable. In the case of a "dry oxidation," Case II in section 4.2 which starts at $Z = 0$ (in VERSION 1) $TLIN = CNTAU = \tau > 0$, the boundary moves linearly for the time period $CNTAU$ with a speed $SLOPE = ZCRIT/CNTAU$. Hence, the time DT the moving boundary needs to transverse the distance DM (where DM is as above) is $DM/SLOPE$. Values of $WFRC$ that have been successfully tested range between 0.01 and 0.33.

We have required $TLIN$ to be less than or equal to 10^{-9} rather than zero in order to distinguish between the wet and dry oxidation cases. This does not seem now to be necessary, but we have left this as it is because in all practical cases $TLIN$ is always much greater than 10^{-9} whenever it is greater than zero, so no harm is done.

The quantity DTS is used to store the quantity DT for recall at a later step, see computational block #17.

When $CNTAU = \tau = 0$, the quantities $ZCRIT = CNSTX$ and $SLOPE$ which are not used but still appear in later formulas are assigned the values 0 and 1, respectively, which do not foul up these formulas, for example by causing division by zero.

In case $\tau > 0$ (i.e., dry oxidation), $WFRC$ must certainly be chosen so that $DM < ZCRIT$ for the above prescription for DT to make sense. In all the cases we have run, this has been naturally satisfied when data in the literature are satisfied.

Block #8: Computation and Storage of Initial Value DT in Hours

The quantity DT just calculated in the previous block is multiplied by BTM (the unit in which time has been rescaled) to determine its magnitude in units of hours. It is stored in the array $PARAM$ for printout in block #34.

Block #9: Calculation of Initial Values of NL , NR and Value of $N2$ for the First Iteration of the Main Loop 78

The quantity $N1$ is another name for the index, NL , of the first grid point with a z -coordinate less than or equal to the z -coordinate of the moving boundary at the beginning time of the main iteration loop 78. Because $Y01$, $Z01$ are zero in Version 1, $N1$ has the value 1, as it should since at this point in the program the moving boundary is at $z = 0$ (recall we are computing here NL for the first iteration of loop 78) NR

(which is the index of the first grid point that has a y-coordinate greater than the y-coordinate of the moving boundary at the start of the iterations in loop 78) has the value 2.

The quantity N2 is the index of the last grid point on the y-axis and since NYO is the number of grid mesh widths in the interval (0, BDRY) (see below eq (2.11) for the definition of BDRY) $N2 = NYO + 1$ (see computational formula eq (4.2)).

Block #10: Calculation of Initial Values of C2()

The initial values of array C2() at all the grid points are determined from the prescription in eq (2.13) of C2(y,0). Because of this prescription, the grid points from NR through NR + NH (NH is an input integer) are assigned the value CMAX (input value) while all the following grid points are assigned the value CBULK (input value).

Since in VERSION 1 no oxide is initially present, there is no necessity to assign array C1().

Notice that C2(1) is essentially assigned through the assignment of CB(2). This is because CB(2) denotes by definition the concentration in the silicon at the position of the moving boundary and initially the moving boundary is located at the position of the first y-grid point.

Block #11: Calculation of the Value of TTMM for MM = 1

This is the step in which TTMM, the time at the beginning of the MMth iteration of loop 78, for the first iteration is calculated. Since Z01 in VERSION 1 has been assigned the value zero, in a declaration card, this quantity obviously has the correct value which is zero.

Block #12: Calculation of the Initial Values of SM()

The quantities SM(1), SM(2) are, respectively, the distance between grid point NL and ZOP1 (the position of the moving boundary in the z-coordinate system at time TTMMPl) and the grid point NR (for more details see figs. 5 and 6).

The quantity FNL represents the number of mesh widths between z-grid point 1 and z-grid point NL, and FNR is the number of mesh widths between y-grid point NR and y-grid point N2 (the last grid point on the y-axis in the domain of the silicon).

Since Z01 and Y01 are declared zero in VERSION 1, $SM(1) = 0$ and $SM(2) = 1$ as they should be when we are calculating these quantities for the initial iteration of loop 78.

Block #13: Calculation of the "P, Q" Coefficients for Grid Point N2

As has been explained in section 6.7, the satisfaction of the boundary condition $C2(N2) = CBULK$ (see eq (2.12)) at $y = BDRY$ is equivalent (in the way this problem is being solved) to assuming $P2(N2)$, $Q2(N2)$ are assigned in such a way that $C2(N2) = P2(N2) C2(N2 - 1) + Q2(N2)$ [see eqs (6.14) and (6.14')].

The values of $P2(N2)$, $Q2(N2)$ are used in subroutine TRIDNL.

Block #14: Beginning of the Main Loop which Calculates Concentrations at Time = TTMMPl

At the beginning of this loop, 78, the quantities in the arrays $C1()$, $C2()$ representing the concentrations in the z- and y-regions at each grid point have their values at time TTMM. At the end of the MMth iteration, these same quantities will have their proper values at time TTMMPl.

Before the main loop begins, certain starting values for quantities used in the loop are set. The definitions and use of these quantities ZOPS, TJ, etc., are explained in later steps.

The overall manner in which the new concentrations are calculated is explained in section 3.

Block #15: Setting the Print-out Control Parameter

The integer KW controls print-out in block #30. This data will be printed out after the first iteration, then skip KPRINT - 1 iterations of loop and print out the data again, and so on.

Block #16: Increasing the Distance that the Moving Boundary Travels in an Iteration of Loop 78

During the MMth iteration of loop 78, the quantity ZOACEL measures that fraction of the mesh width DZ that the moving boundary transversed during the previous iteration of loop 78. (If $MM = 1$, $ZOACEL = 0$ since $ZOP1 = 0$. and $ZOPS = 0$. In this case, see block #14.) If ZOACEL is less than 0.2 and KPOW (defined below) is greater than 100, then the magnitude to DT is increased by 0.05 in order to accelerate the distance the boundary moves during the MMth iteration of loop 78. This acceleration is put into the algorithm in order to decrease the number of iterations that are required in order to compute the solution to a problem in which the moving boundary moves a certain specified distance.

Of course, subroutine TRIDNL, which computes and stores quantities that depend on DT, has to be recomputed and the new value of DT is placed in DTS. When leaving the loop in which DT has been increased, the value of the control parameter KPOW is increased by 100 so that DT will not be increased again for at least another 100 iterations of loop 78.

The quantities 0.2 and 100 mentioned above are, of course, somewhat arbitrary, but the above values have worked satisfactorily in a great number of trial runs.

Block #17: Adjustments Required When Moving Boundary Reached New Z-Grid Point on Previous Iteration of Loop 78.

The quantity TJ will be computed in a later step, block #20, in such a way that when and only when the moving boundary reached a new z-grid point during the previous step will TJ have a value greater than or equal to 1. Hence, assuming $TJ \geq 1$, NL, which is the first grid point less than or equal to the position of the moving boundary at the time when MMth iteration of loop 78 starts, has to be increased in value by one. The quantity FNL (the number of mesh widths to the left of NL) also must be increased by 1 and $NLM1 = NL - 1$, $NLM2 = NL - 2$, increased accordingly.

Also, C1 at the new grid point, NL, must be defined.

Furthermore, since DT has been adjusted (see block #20) during the previous iteration of loop 78, this quantity is reset to the value it had during the (MM - 2)th iteration, specifically DTS. Also, TRIDNL, the subroutine computing the arrays P1, Q1, etc., depends on DT (besides a new P1, D1 being added in the y-region) and hence needs to be recomputed.

The value SM(1) (see secs. 5.6 and 5.7 for its meaning) must be set equal to zero because during the (MM - 1)th iteration the moving boundary reached a new grid point in the z-region.

All these changes are effected when $TJ > 1$. Of course, in the contrary case the implication is that the moving boundary had not yet reached a new z-grid point and the above changes are not required.

Block #18: Computing the Time and Position of the Moving Boundaries at the End of the MMth Iteration of Loop 78

In this step we are simply computing what the value of the time will be at the end of the MMth iteration of loop 78. Since at the beginning of the loop, t has the value TTMM by definition and since time is made to increase by DT during the loop, the time at the end of the loop $TTMMP1$ is given by $TTMM + DT$. After this value of $TTMMP1$ is computed, the location of the moving boundary in the z- and y-regions, respectively, $ZOP1$, $YOP1$ can be computed through the use of formulas in section 4.2 and eq (2.8). Remember, ZW and TW equal zero in VERSION 1.

Block #19: Adjustments Required When Moving Boundary Reached New Y-Grid Point on Previous Iteration of Loop 78

The quantity SES is the fraction which the signed distance between NR and $YOP1$ is of the mesh width $DY = \Delta Y$. If $YOP1$ is beyond the y-grid point NR (during the MMth iteration of loop 78), then SES is negative

and NR, FNR, and NRPl = NR + 1 have to be increased by 1. When SES is negative at the beginning of the MMth loop, it means (see the next block) the moving boundary is located at time TTMM on a grid point, and hence SM(2) should be set equal to 1.

Block #20: If the Moving Boundary Moves for a Time 2DT, Will It Reach a New Z-Grid Point?

During the MMth iteration of loop 78, we look at where $z_0()$ is at time $TTMMP2 = TTMMP1 + DT$. This position is denoted as ZOP2. Then we compute TJ which is that fraction the signed distance between grid point NL and ZOP1 is of the mesh width $\Delta Z = DZ$. If this fraction is less than one, it means that during the (MM + 1)th iteration of loop 78 the moving boundary will not reach a new z-grid point, and we proceed with the MMth iteration. On the other hand, if TJ is greater than or equal to 1, we know that the moving boundary will reach or cross grid point NL + 1 on the next iteration (MM + 1). Therefore, we decide to change the value of DT so that while still in the MMth iteration of loop 78, z_0 travels all the way to the next grid point. At the time TTMMP1 when this happens, i.e., $z_0(TTMMP1) = (FNL + 1)$, DZ is calculated (as shown in the listing) for the two cases CNTAU = 0 or CNTAU > 0. (Remember that ZW = TW = 0 in VERSION 1.) Finally, we calculate the new value of DT that will take the moving boundary $z_0()$, starting at time TTMM, to its new position. Lastly, we recompute TRIDNL because the arrays P1, P2, etc., computed there depend on the value of DT.

Block #21: Calculation of the Parameters S(1), S(2) Needed for Subroutine CENTER

The quantities FNL, FNR, etc., have now been reset (if it was necessary). These quantities S(1) and S(2) (see secs. 5.4 to 5.7 for details) are used in computing the coefficients of the unknowns in the algebraic equations that will be solved later in subroutine CENTER.

Block #22: For the First Iteration of Loop 78, Call TRIDNL

In the first iteration of loop 78, the arrays P2, D2 that are needed later and which are calculated in subroutine TRIDNL have not been calculated before in the program.

Notice that whenever a new NL occurs, and hence the quantities in TRIDNL need to be updated, this is done in step #20.

Block #23: Calculating of P1(1), Q1(1) When the Moving Boundary z_0 Has not Yet Reached Grid Point Two

In the case NL = 1, the moving boundary at time TTMMP1 has still not reached the second z-grid point. Therefore, P1(1), Q1(1) must be calculated using formulas in sections 6.2 and 6.3, specifically eqs (6.5') when TTMM = 0 and (6.6') when TTMM > 0.

Of course, DM, DML, etc., are just intermediate variables.

For the computational significance of $P1(1)$, $Q1(1)$, see again sections 6.2 and 6.3. $P1(1)$ is not calculated in subroutine TRIDNL like the rest of its elements, and $Q1(1)$ is calculated here rather than with the other elements of $Q1$ in block #25.

Block #24: Computation of $P1(1)$, $Q1(1)$ When z_0 Has Moved Beyond the First Grid Mesh Widths

In this case ($NL > 1$), the moving boundary has traveled through the first z -mesh width and $P1(1)$, $Q1(1)$ are to be calculated by the formulas in section 6.4, specifically eq (6.7'). $P1(1)$ is not calculated in subroutine TRIDNL like the rest of its elements, and $Q1(1)$ is calculated here rather than with the other elements of $Q1$ in block #25.

Block #25: Calculation of Arrays $AF()$, $Q1()$ When There are Regular Points in the Z -Region

When $NL > 2$, there are grid points with cell widths (see sec. 5.1) of magnitude DZ in the z -region, and the arrays AF and $Q1$ associated with these points are therefore computed. [This amounts to saying that the arrays $AF()$, $Q1()$ that are associated with these points are calculated by using the formulas in table 5.2 and eq (6.9').]

For the significance of the array $Q1$ in the computational procedure, see chapter 3. The array AF plays the role of the quantity Z_4 in eq (3.2); see also eq (5.7). Array AF is used to compute array $D1$ in subroutine TRIDNL. The array $Q1$, which is composed of AF and $D1$, is used in block #29.

Block #26: Calculation of Arrays BF and $Q2$ Associated with the Grid Points in the Y -Region

The array BF is used to compute $Q2$ later in this block.

For further elucidation of the computational significance of these arrays, see the references to BF in section 5.3, table 7, and eq (5.10). See section 6.8 and eqs (6.16) and (6.16') for the significance and definition of $Q2(J)$. Notice $P2(N2)$, $Q2(N2)$ are calculated in block #13. Arrays $P2$, $Q2$ are used in block #28.

Block #27: Calculation of $CB(1)$, $CB(2)$, $C1(NL)$, $C2(NR)$ at Time $TTMMP1$

The quantities above at the end of the MM th iteration of loop 78 (i.e., at time $TTMMP1$) are computed in subroutine CENTER which is documented in detailed block form in section 7.2.

Block #28: Computation of $C2()$ at Time $TTMMP1$

By making use of $C2(NR)$ that was computed in subroutine CENTER in block #27, we can carry out the backward sweep; see steps #2 and #3 in chapter 3 that generate $C2(J)$ for $J = NR + 1$ to $N2 - 1$.

Block #29: Computation of Array C1() at Time TTMMPl

In this case $NL = 1$, the value of $C1(1)$, which is the only grid point besides $CB(1)$ in the y-region, is already known, since it has been computed in subroutine CENTER as $C1(NL)$. However, when NL is greater than one, the calculation of $C1(J)$ for $J = 1, NL - 1$ must be completed by a backward sweep, as described in section 3.1, steps #2 and #3.

Block #30: Print-out Concentrations When $KW = 0$

The integer KW is zero when $(MM - 1)$ is divisible by $KPRINT$.

The concentrations are printed under a time TTMMPl which is in units of BTM (see sec. 4.3). The user is advised not to print out every concentration in each region because there are so many, especially in the y-region (i.e., the silicon).

Also printed out are the values of the concentrations at the boundary and $C1(NL)$. (Note that $C2(NR)$ will always be printed with the other concentrations in the y-region.)

Block #31: Reset Quantities in Preparation for Next Iteration of Loop 78

Unless a new grid point is reached by the moving boundary in the next iteration, the new values of $SM(1)$, $SM(2)$, $TTMM$ are as given (see figs. 5 and 6). If in the next iteration of loop 78 a new grid point is reached, the values are corrected appropriately at that time, in blocks #17 and #19.

Block #32: Test to Determine Whether TTMMPl Has Reached TFINAL

The quantity TFINAL (INPUT) is the time we want to stop the problem and TIMEND is the value of TFINAL in units of BTM which is the unit of TTMMPl. Hence, as long as TIMEND is greater than TTMMPl, we proceed to the next iteration of loop 78. If MME is not large enough to reach TFINAL, a diagnostic to this effect is printed before control shifts to statement 79 and then the end card.

Block #33: Shift Program to Statement 800 in VERSION 1

The time is greater than or equal to TFINAL and in VERSION 1 the value of JSTOP is set equal to 1 in a data card. Hence, control sends the program to statement 800 where printing and plotting occur prior to the end of the program.

Block #34: Print-out of Data and Plot of Concentrations at the Final Value of TTMMPl

The detailed description of the plotting subroutine is given in Appendix 2 and section 4.4.

Block #35: Redimensionalize Parameters to Original Units

Parameters such as ZOPl and TTMMPl (at the last iteration of loop 78 that occurs) are changed into micrometer and hour units and printed out with other pertinent parameters.

Block #36: Control in VERSION 1 Sends Program to Its End

The integers JSTOP and JSAVE have the values one and zero (see below data cards) in VERSION 1; consequently, in this case the program is sent to the end.

If TIMEND has not been reached by TTMMPl before the number of iterations MME of loop 78 is completed, a diagnostic message to this effect is printed out.

Block #37: This Block Contains Statement 79 and Ends Program.

7.2. Block-by-Block Description of Subroutine CENTER

This subroutine, which is called in computational block #27 of the main program, is where the quantities CB(1), C1(NL), CB(2), C2(NR) are evaluated at time TTMMPl.

Block #0. Insert Input Through COMMON

The following input for the subroutine passes in through COMMON: S(), SM(), N2M1, N2, NLM1, NL, NR, C1(), C2(), CB(), DF1, DF2, CONPRO, CONOUT, DT, DZ, DY, P1, P2, Q1, Q2.

The output is fed to the main program through COMMON.

Block #1: Computation of the Quantities P(2), Q(2)

These quantities defined in eqs (6.18) and (6.18') are used to determine PA(2), QA(2) in computational block #3.

Block #2: Compute P(1), Q(1)

These quantities [see eqs (6.11) and (6.11')] are used when NL > 1 to determine PA(1), QA(1). When NL = 1, the role played by PA(1), QA(1) in linking the value of CB(1) to the value of C1(1) is played by P1(1), Q1(1), which are computed in block #23 of the main program. Therefore, at the end of block #3, we set PA(1) = P1(1), QA(1) = Q1(1) when NL = 1.

Block #3: Computation of PA(L), QA(L) for L = 1,2

The computation formula for these quantities when L = 1 is described in eqs (6.10'), (6.11'), and (6.12'). [See eqs (5.16') and (5.25) for the definition of R(1) and R(2); also see tables 7 and 8.] The computation formulas of the above quantities in the case L = 2 are described

in eqs (6.17'), (6.18'), and (6.19'). The significance of $PA(L)$, $QA(L)$ is seen from eqs (5.26') and (5.18) or eqs (6.12) and (6.19).

Block #4: Computation of $CB(1)$, $CB(2)$ at Time $TTMMP1$ in Terms of Known Quantities

The concentration at the moving boundary in the z -region $CB(1, TTMMP1) = CB(1)$ is computed by using formula eqs (6.21) and (6.21') and the auxiliary eq (6.22). To find $CB(2) = CB(2, TTMMP1)$, we just use the boundary condition in eq (2.23). For the significance and explanation of how SAVE is used, see the end of section 5.7, before SUMMARY.

Block #5: Calculation of $C1(NL)$, $C2(NR)$ at Time $TTMMP1$

We introduce the abbreviations

$$C(1) = C1(NL, TTMMP1) = C1(NL)$$

$$C(2) = C2(NR, TTMMP1) = C2(NR)$$

and compute these desired quantities from $CB(1)$, $CB(2)$, $PA(L)$, $QA(L)$ known from blocks #1 to #4 by employing eqs (6.12) and (6.19).

7.3. Block-by-Block Description of Subroutine TRIDNL

The input for this subroutine is the output of subroutine INTER, DT, DZ, DY, DF1, DF2, and CONPRO. The arrays P1, D1, P2, D2 in contrast to the Q1, Q2 arrays do not depend on concentrations. The output of this subroutine is used both in the main program blocks #25, #26, #28, and #29 and subroutine CENTER (see blocks #1 and #2). The output of the subroutine is $P1(J)$, $D1(J)$ for $J = 2, NL - 1$ and $P2(J)$, $D2(J)$ for $J = NR + 1, \dots, N2 - 1$.

Block #1: Call Subroutine INTER

By calling this subroutine, we input $A2L, \dots, AlM, B2L, \dots, BlM$ through COMMON. These quantities are used in blocks #3 and #4 here.

Block #2: Calculation of $P1(1)$ when $NL > 1$

When $NL > 2$, this value of $P1(1)$ is used in the next block. Calculation formulas of the above quantities are found in eqs (6.7) and (6.7'). (This is a duplication of $P1(1)$ calculated in block #24 of the main program and is not necessary in VERSION 1.)

Block #3: Calculation of Arrays $P1(J)$, $Q1(J)$

The calculation formulas for these quantities when $J = 2, NL - 1$ is eq (6.9'). These quantities are used in blocks #25 and #29 of the main program.

Block #4: Calculation of Arrays P2(J), D2(J)

The calculation formulas for these arrays when $J = NR + 1, \dots, N2 - 1$ are given in eq (6.16'). Notice that P2(N2) is calculated in block #13 of the main program and used here.

7.4. Description of Subroutine INTER

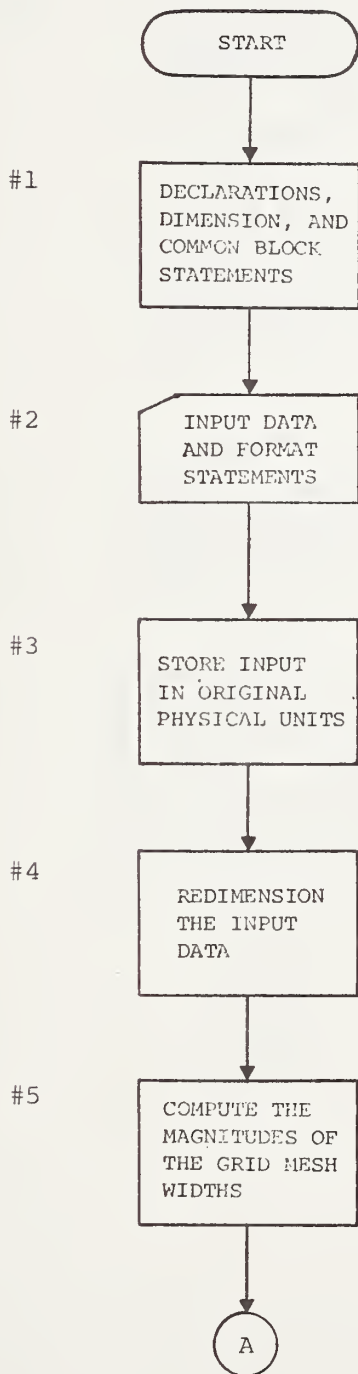
This subroutine is so trivial we only describe it briefly.

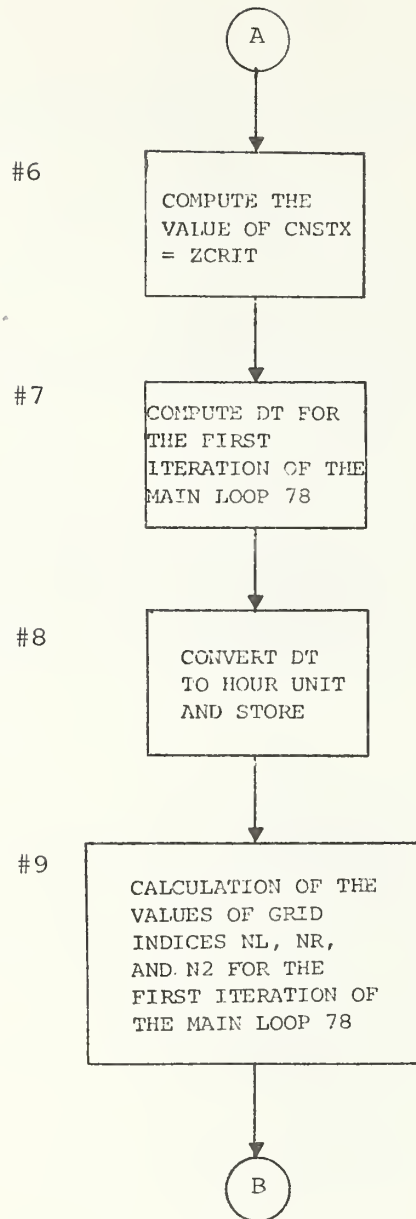
The routine uses the value of DT, DZ, DY, DF1, DF2 to compute the value of A2L, A2M, A2R, B2L, B2M, B2R, A1M, B1M for use in subroutine TRIDNL (see blocks #3 and #4).

Since the values of A2L, ..., B1M depend on DT, every time this quantity changes these quantities need to be recomputed. This explains why subroutine TRIDNL is called whenever DT changes in the main program, i.e., because TRIDNL calls INTER (see block #1 in TRIDNL) and thereby corrects the values of A2L, ..., B1M for the new DT and, consequently, simultaneously corrects the values of the arrays P1, D1, P2, D2 for the values of the new DT.

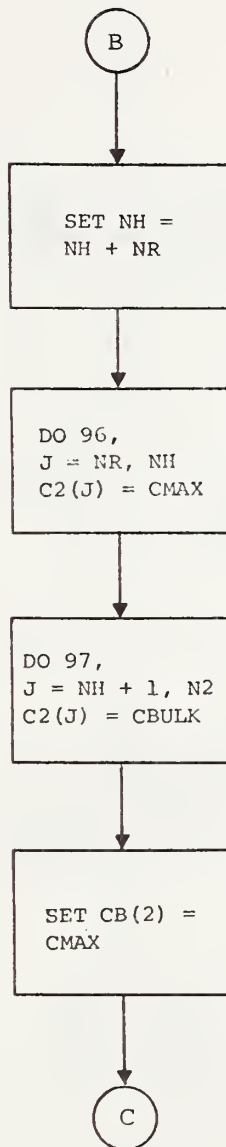
8. FLOW DIAGRAMS

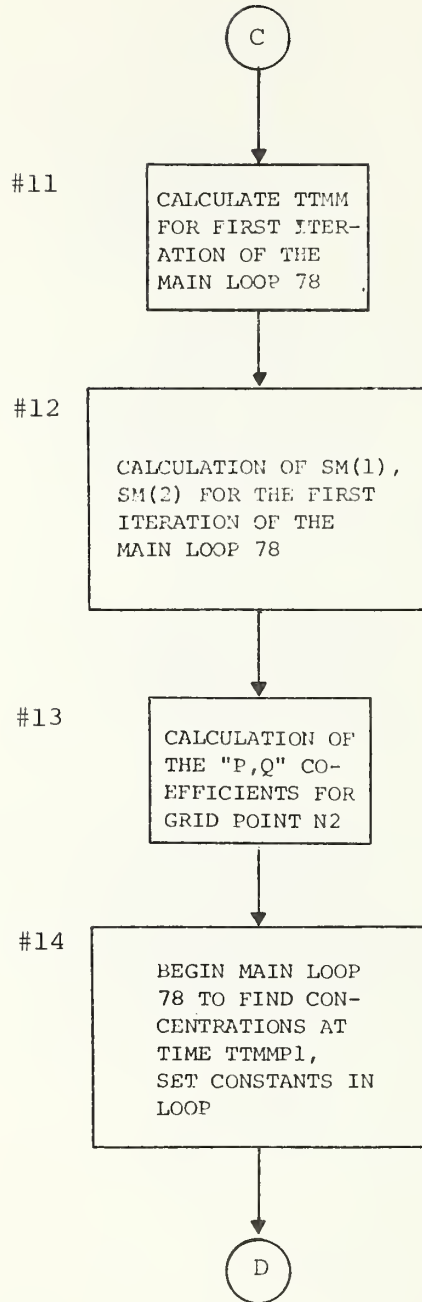
8.1. Flow Diagram of Main Program in DISTRIB

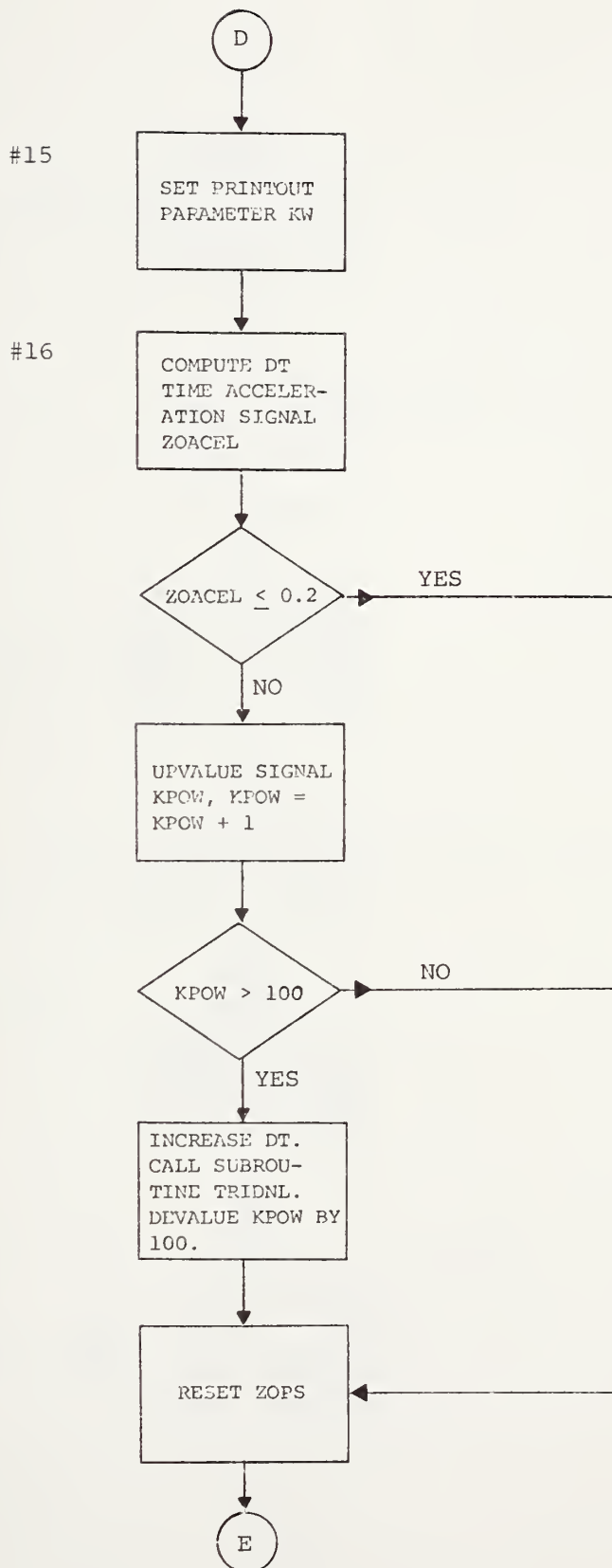


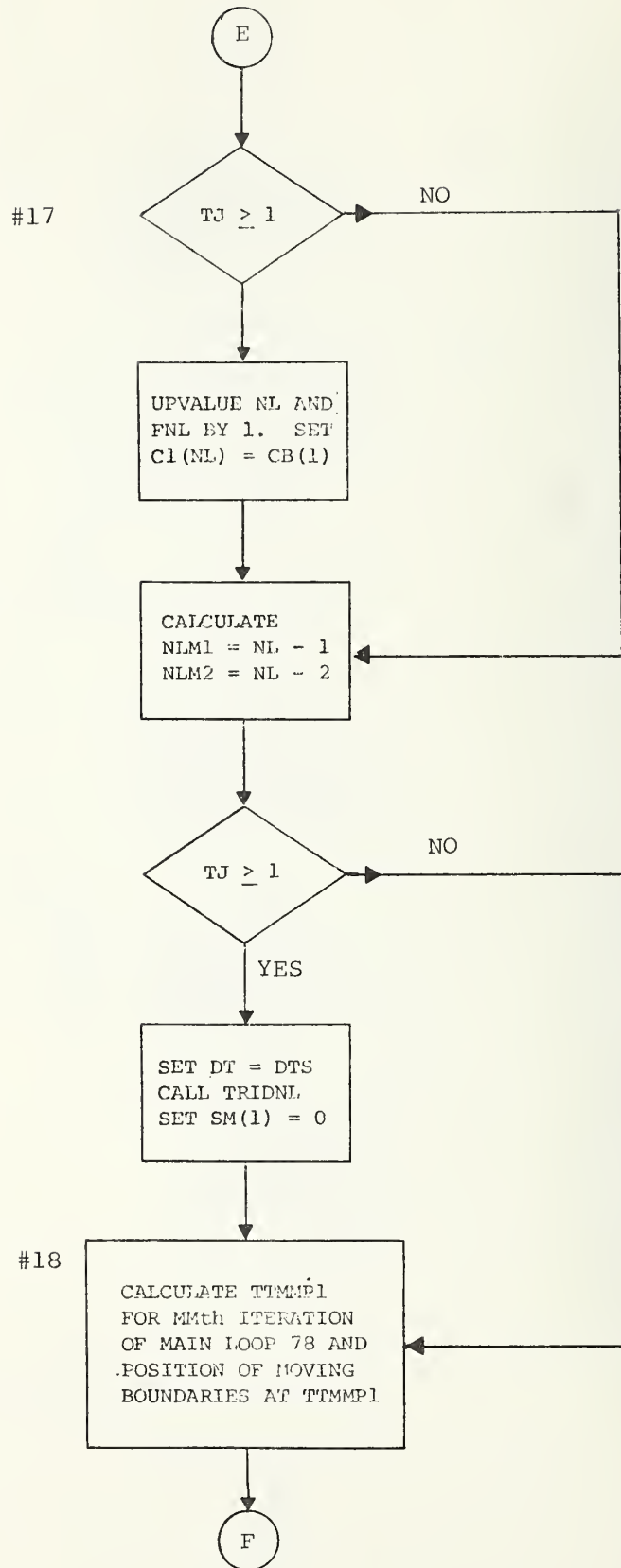


#10

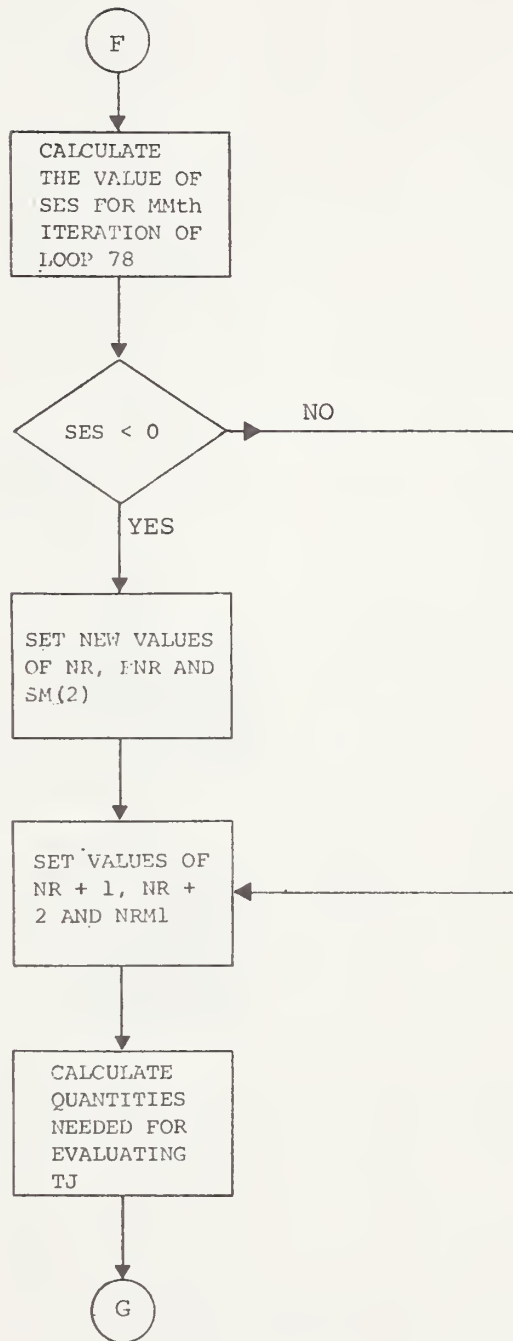




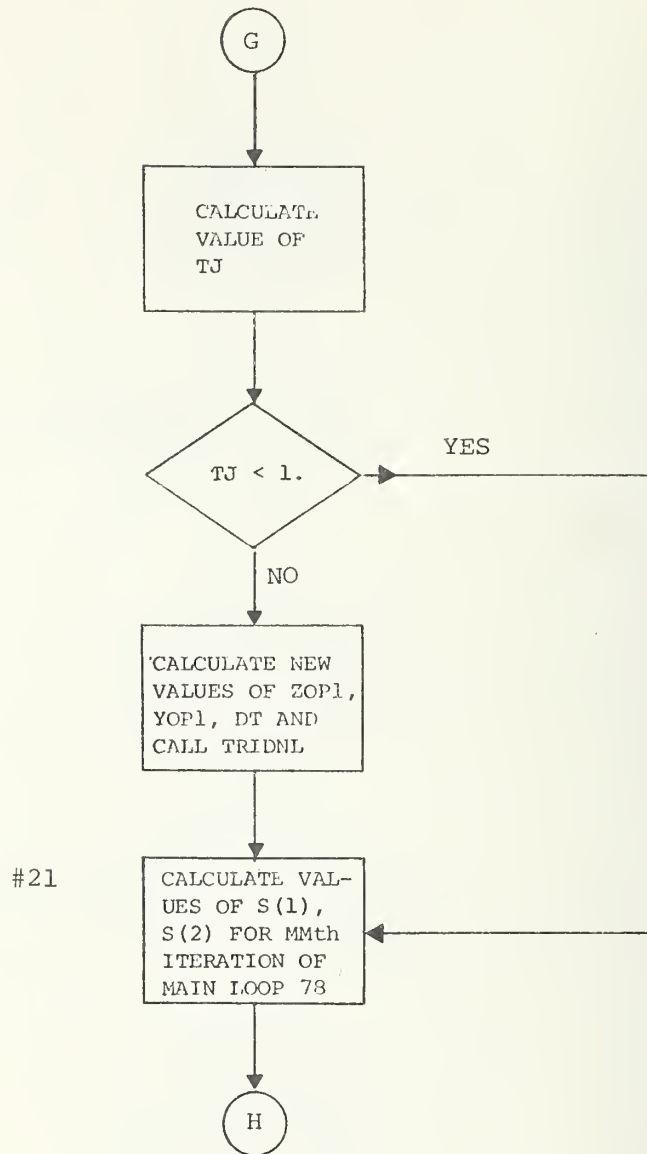


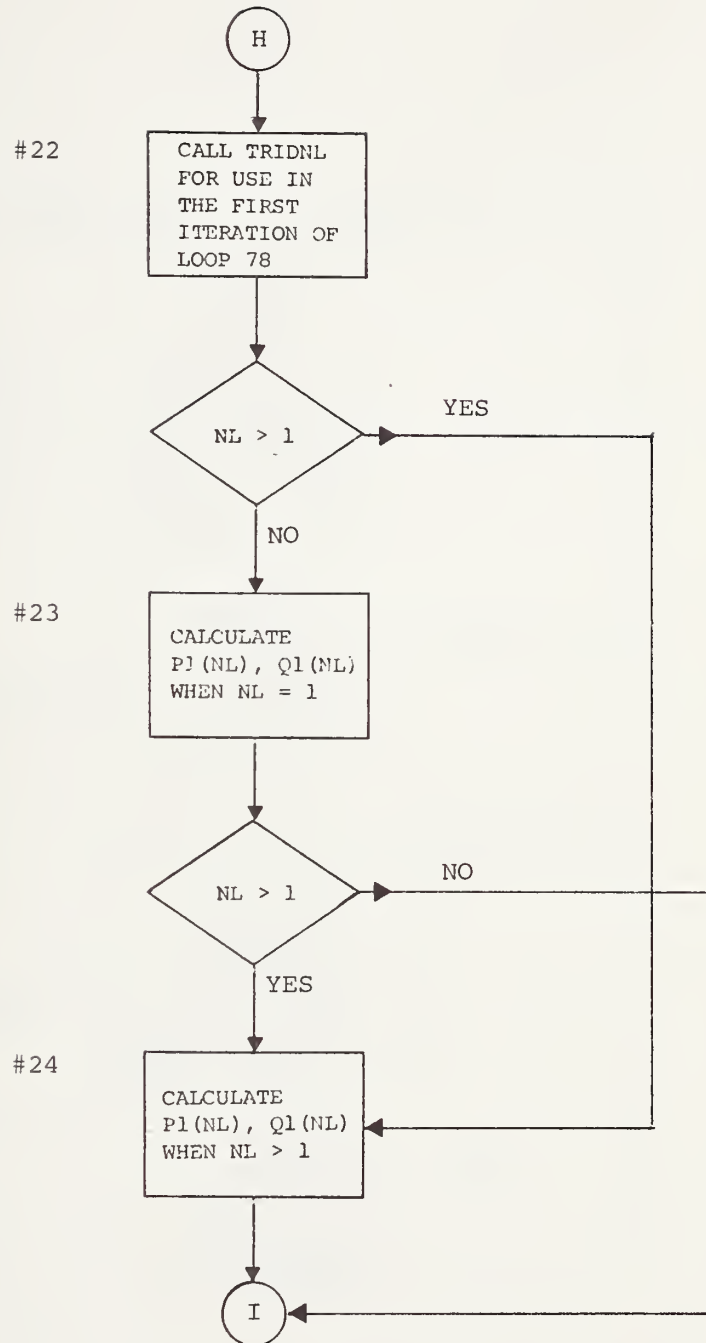


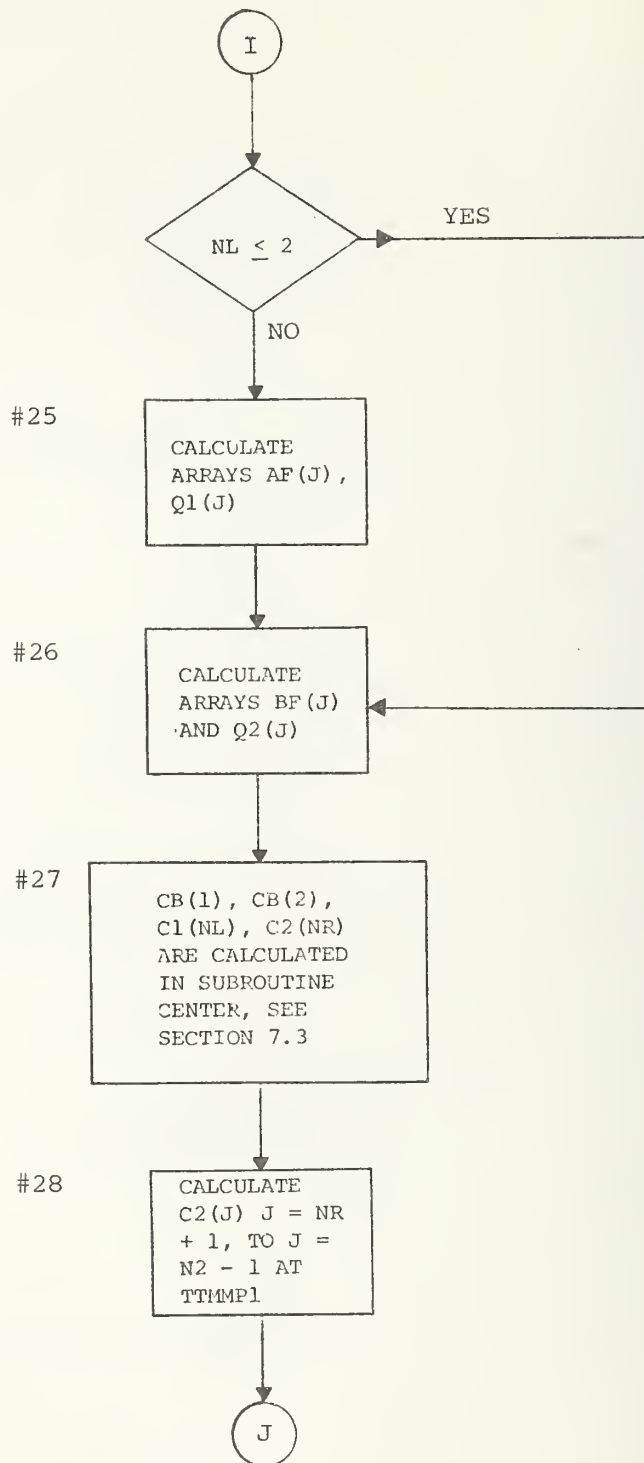
#19

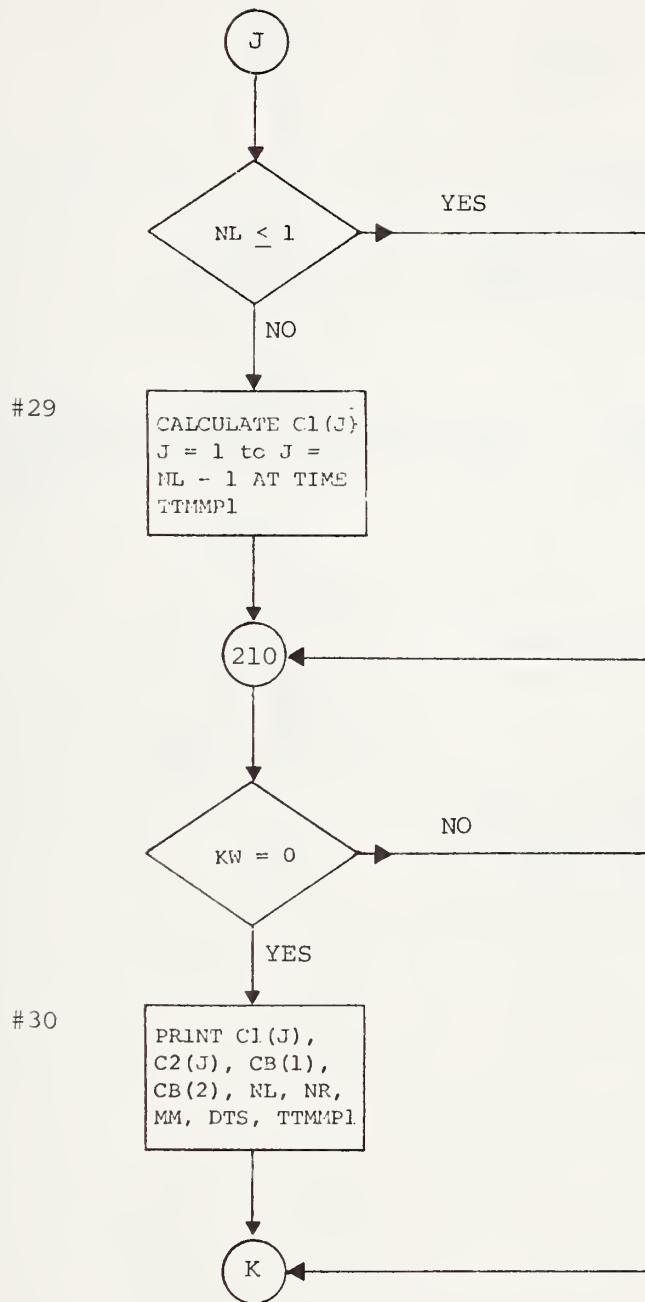


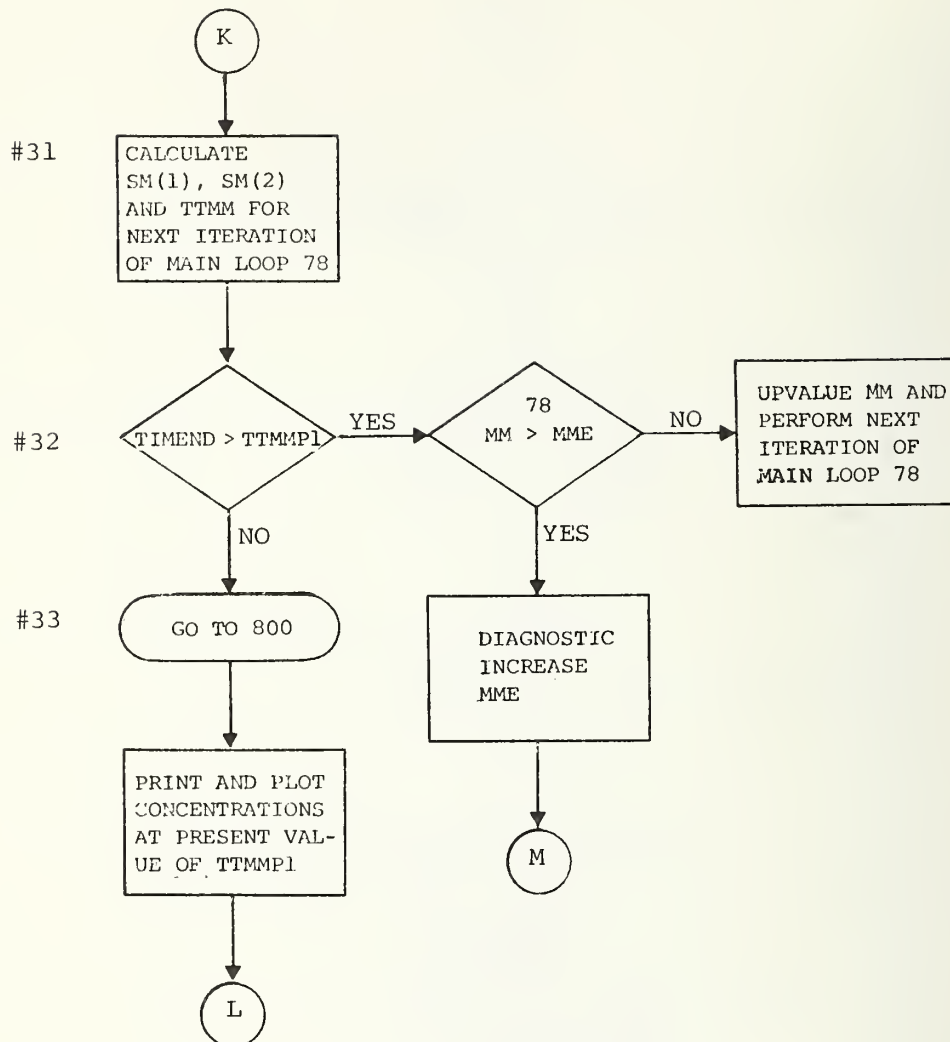
#20

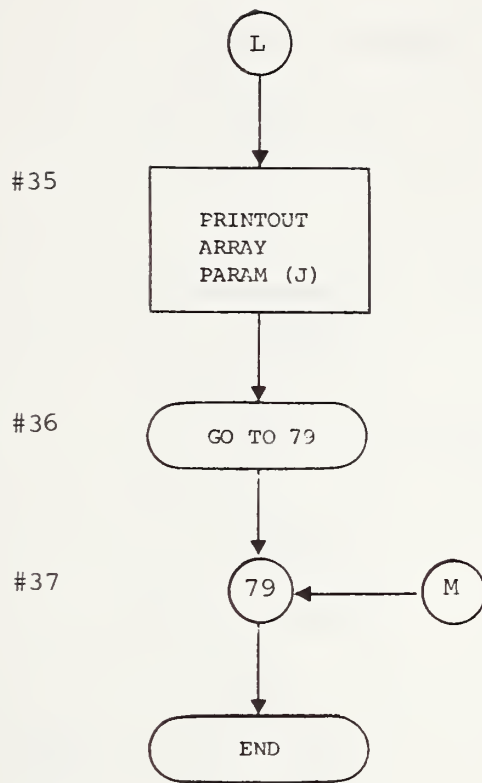




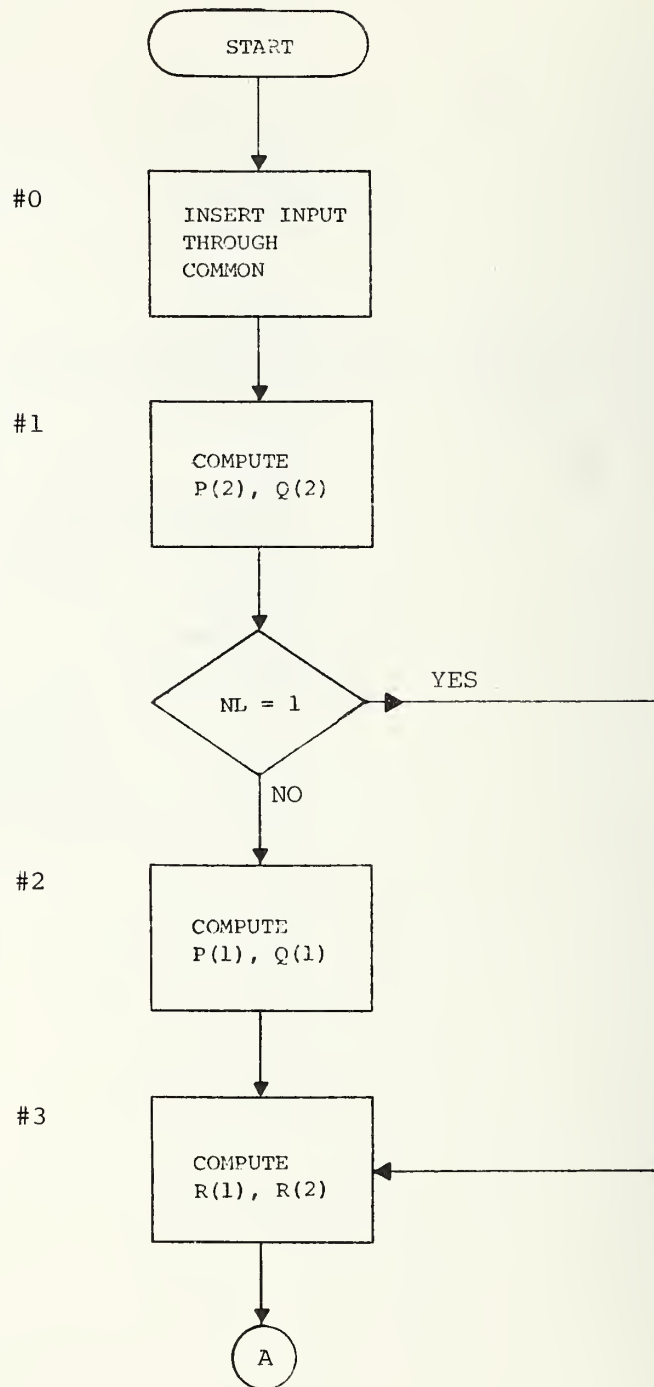


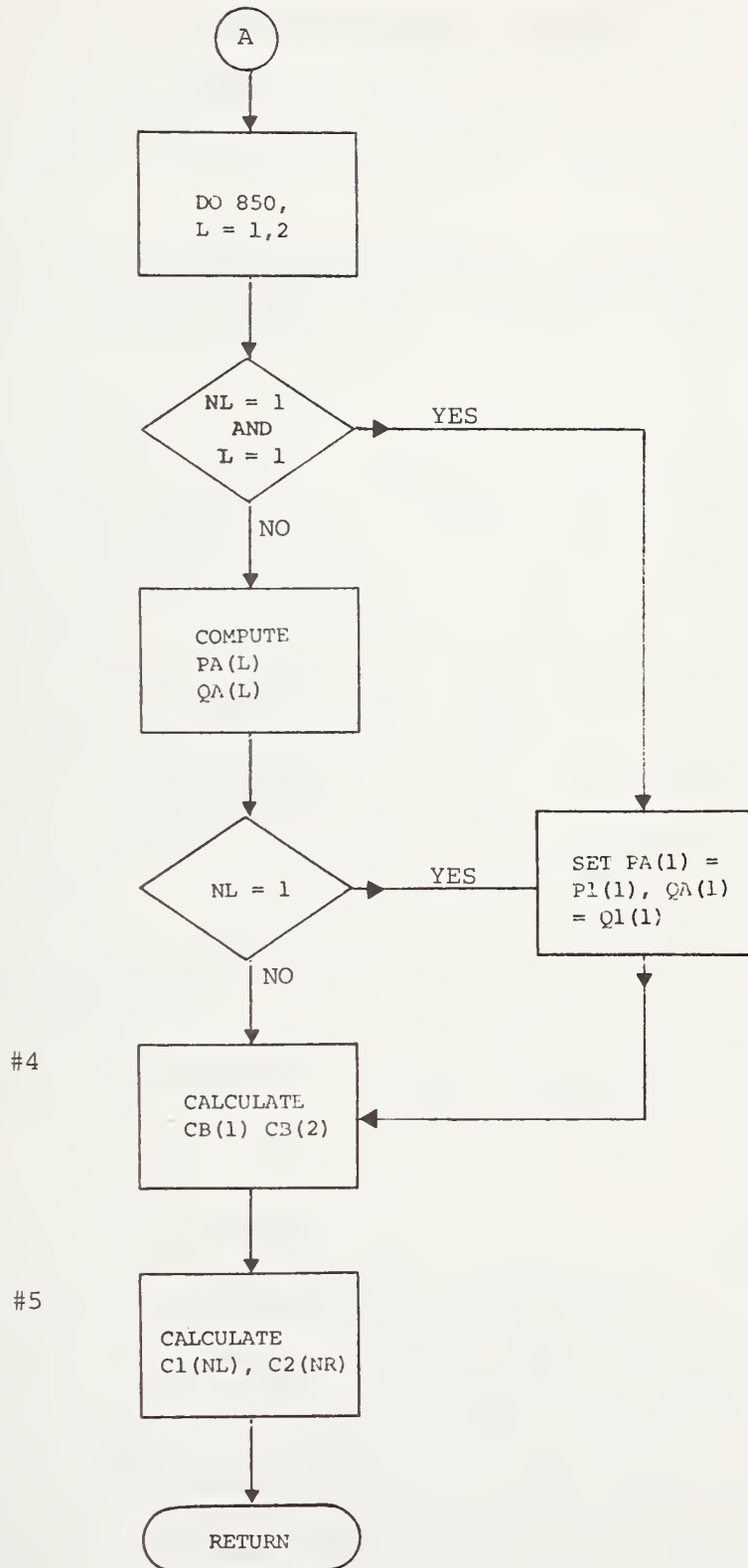




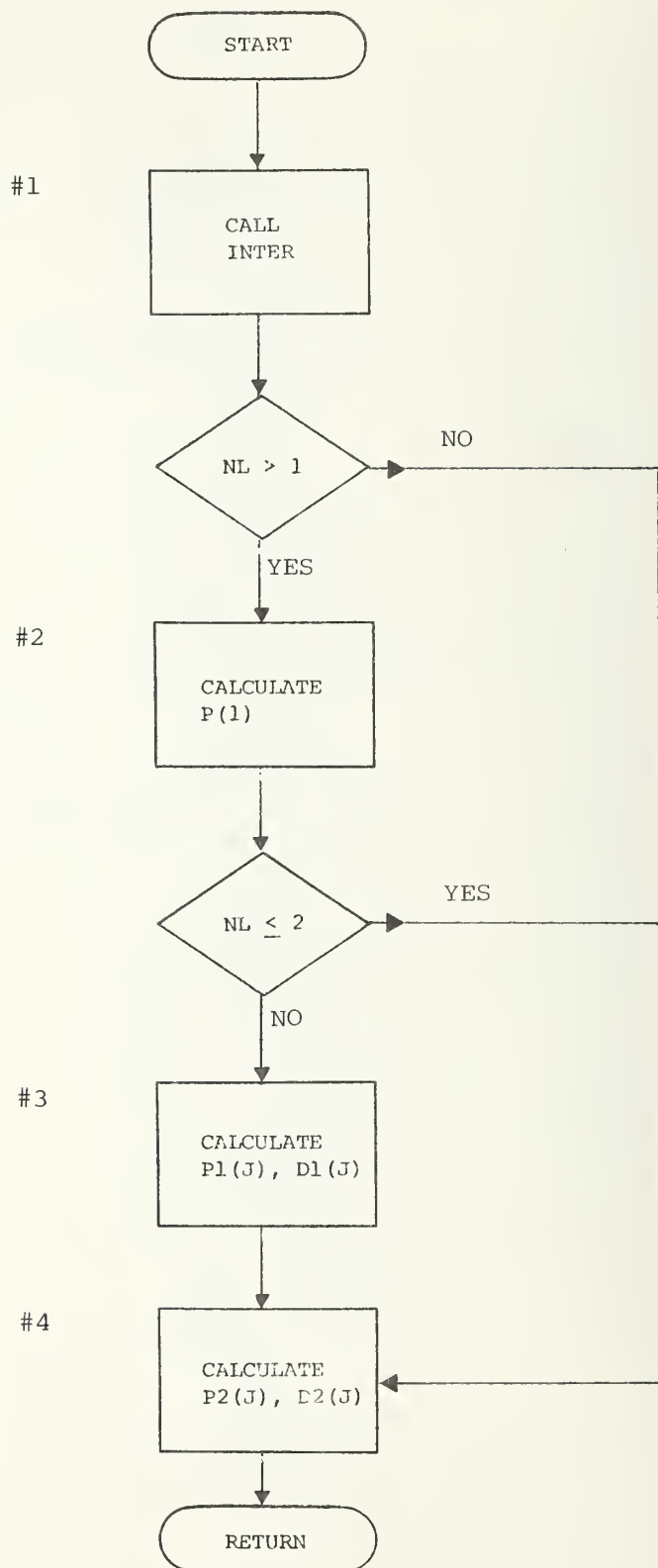


8.2. Flow Diagram for Subroutine CENTER





8.3. Flow Diagram for Subroutine TRIDNL.



9. HOW TO USE DISTRIB

9.1. A Brief Description of DISTRIB: VERSION 1

The intent of this section is to give a quick general introduction to DISTRIB: VERSION 1.

The meaning of the undefined terms in this chapter is explained in the glossary, chapter 12. A more detailed description of the physical aspects of the redistribution problem is given in chapter 2. Chapter 3 contains a more detailed description of the overall computational procedure.

DISTRIB: VERSION 1 calculates a redistributed initial impurity profile in a crystal wafer that has undergone an oxidation at a constant temperature for an input time $t = T_{\text{FINAL}}$. The impurity concentration in the oxide $C_1(z, t)$ is calculated at time $t = T_{\text{FINAL}}$. Here, z denotes (fig. 3) the distance measured into the oxide from the interface between the ambient oxygen and the oxide at time $t = T_{\text{FINAL}}$. (The z -coordinate system changes with time.) Also calculated at time $t = T_{\text{FINAL}}$ are the impurity concentrations in the silicon $C_2(y, t)$ where y represents (fig. 3) distance into the oxide-silicon composite measured from the position of the oxygen-silicon interface at time $t = 0$. At this initial time, the silicon is completely unoxidized. The principal output quantities are the concentrations $C_1(L) = C_1((L - 1)DZ, T_{\text{FINAL}})$ for $L = 1, \dots, NL$ where NL represents the index of the first grid point to the left of the position of the moving oxide-silicon interfacial boundary, $Z_0(t)$, at $t = T_{\text{FINAL}}$ (fig. 3). Also computed are $C_2(K) = C_2((K - 1)DY, T_{\text{FINAL}})$ for $K = NR + 1, \dots, N2$ where NR is the index of the first grid point to the right of the moving boundary, $y_0(t)$, at time $t = T_{\text{FINAL}}$ (fig. 3) and $N2$ represents the number of grid points in the original silicon wafer. The quantities DZ and DY above are uniform grid widths in the z - and y -coordinate systems. Besides the concentrations $C_1(\)$ and $C_2(\)$, DISTRIB computes $CB(1) = C_1(Z_0(T_{\text{FINAL}}))$ and $CB(2) = C_2(y_0(T_{\text{FINAL}}))$, the impurity concentrations in the oxide and silicon at the moving oxide-silicon interface at time T_{FINAL} . All of these concentrations are also plotted.

9.2. Definitions and Other Information Related to Input and Output

In section 9.21 the real input quantities are briefly defined. A table follows the definitions giving further information about the previously defined input, such as: the computational block number in the listing that contains the read and format cards, format information, data sources, and numerical ranges for which the parameters have been successfully tested, etc. This same procedure is used to describe the integer input in section 9.22. The same procedure is also used to describe the real and integer output in sections 9.23 and 9.24. Consult the glossary for information concerning undefined quantities and places in the documentation where more thorough definitions are given. All physical quantities must be entered in units of hours and micrometers.

9.2.1. Real Input

The real input is defined in table 16 in the same order they are read (see computational block #2 in the listing, chapter 11, for the read and format card).

Table 16: Brief Definitions of the Real Input

Card 1	
CBULK	The program handles automatically piece-wise constant initial concentrations in the silicon. The grid points in the silicon beyond the input grid point NR are assigned the value CBULK representing the concentration in the bulk of the silicon.
CMAX	The grid points 1 through NH are assigned initial concentrations of magnitude CMAX.
ALPHA	A given volume of silicon swells to a volume $(\text{ALPHA})^{-1}$ times (the original amount of silicon at the oxide-oxygen interface).
TFINAL	The total time that the wafer is to undergo redistribution.
SEG	The redistribution coefficient.
Card 2	
DF1	The diffusion coefficient of boron in the oxide.
DF2	The diffusion coefficient of boron in the silicon.
WFRC	The fraction of a mesh width distance, DZ, that the moving boundary moves in the first iteration of loop 78, i.e., in the first time step.
BDRY	A positive number representing the width of the wafer.
CONPRO	A proportionality constant representing the evaporation rate of boron from the oxide into the oxygen ambient.
Card 3	
CONOUT	A constant representing the concentration of boron in the oxygen at the oxygen-oxide interface. (In our testing CONOUT was always set equal to zero.)
CNSTA } CNSTB } CNTAU }	Constants appearing in the defining equation of the moving boundary, section 4.2.
Y1S	Same definition as Y2S, etc., below.
Card 4	
Y2S } X2S } X1S }	Quantities that are used to scale the concentrations that are outputted in the plotting routines, section 4.4, and computational block #34.

Runs of DISTRIB have been successfully completed using data in the ranges shown in table 17. Sources for the data and formal information are also given.

Table 17: Real Input (4 FORMAT (5 F 10.5)) (see block #2 in listing, chapter 11). Physical quantities are assumed to be in units of micrometers.

VARIABLE	RANGE (Note 4)
(1) CBULK	1. (Note 4)
(2) CMAX	1. (Not tested with other values)
(3) ALPHA	0.44
(4) TFINAL	0.1 to 4.
(5) SEG	0.01 to 10.
(6) DF1	See [4], [6], [7], [8]
(7) DF2	$0.00029 \cdot DF1$ (See [7] and Note 2)
(8) WERC	0.01 to 0.33 (Note 3)
(9) BDRY	3. to 8.
(10) CONPRO	0.1 to 1000.
(11) CONOUT	All runs have been with zero because of our experimental conditions.
(12) CNSTA	See tables in [1]
(13) CNSTB	"
(14) CNTAU	"
(15) Y1S	5.
(16) Y2S	2.
(17) X2S	4.
(18) X1S	2.

- Notes:
- (1) The ranges in the subsections are values from successful runs and are not to be interpreted as precise limitations.
 - (2) This relationship is cited in [4].
 - (3) WERC must be chosen small enough so that $DM = WERC \cdot DZ < ZCRIT$. For an explanation of this restriction, see the comment at the end of block #7 of the main program in chapter 7.
 - (4) The problem with $CONOUT = 0$. is homogeneous in the concentrations and therefore all runs have been made with CBULK1.

9.2.2. Integer Input

Table 18 contains brief definitions of DISTRIB's integer input.

Table 18: Brief Definition of Integer Input

Card 5	
NZO	A parameter used to determine the magnitude of DZ , eq (4.3).
MME	The concentrations are calculated at times $t_1, \dots, t_{MME}$. MME must be large enough for $t_{MME} > TFINAL$ or the program will stop before calculating the concentrations at $TFINAL$. (See table and sec. 9.3 for guidance in choice of MME.)
ND	This integer determines how many grid points in the silicon adjacent to the moving boundary will be plotted.
NYO	The number of mesh widths of length DY that equal $BDRY$.
NH	The grid point on the y -axis at which the initial boron concentration changes from C_{MAX} to C_{BULK} , eq (2.10) and section 7.2, block #10.
KPRINT	The concentrations and a few other integer parameters such as MM , NL , NR will be printed out, whenever $MM = 0$ modulo (KPRINT).

The range of values of integer data successfully calculated in DISTRIB is given in table 19.

Table 19: Integer Input Information
Integer Input (1 FORMAT (6I6)) (see block #2 of listing)

VARIABLE	RANGE
(1) NZO	2. to 8.
(2) MME	up to 4000
(3) ND	20. to 30.
(4) NYO	100 to 800
(5) NH	10. to 20.

Certain constants that can be used to control various aspects of how DISTRIB runs but do not have to be changed from run to run (and consequently, are not entered formally) are listed in the next table.

Table 20: Constants Used in Program But Not Made Part of Input.

-
- (1) 0.2 and 100 used in block #16 in the listing of the main program (see sec. 7.1., block #16).
 - (2) NMOD and NMOD1 (sec. 4.4.) and block #34 of listing of the main program. These quantities need to be changed frequently to get plotted points nicely spaced. We recommend starting with $NMOD = 8$, $NMOD1 = 4$.
 - (3) BLTH (sec. 4.3). The value 0.02 micrometers has worked all the time.
 - (4) In printing out C1, C2 in blocks #30 and #34, certain indices are skipped. Of course, this is something one changes from run to run routinely, in order to find the values at the grid points that interests one.
-

9.2.3. The Real Output of DISTRIB

Table 21: Brief Definitions of the Real Output. See Tables 24 and 25.

TTMMP1	DISTRIB calculates concentrations in the oxide and silicon for a sequence of iterations of loop 78 with indices $MM = 1, \dots, MME$. The time at the end of the MM th iteration of this loop is TTMMP1 (in units of BTM).
CB(1), CB(2)	The concentrations of boron in the oxide and silicon at the moving boundary.
C1(J) C2(J)	These are the concentrations in the oxide and silicon at the Jth grid point (for the specific values of J see below) at time TTMMP1.
C1(1)	The concentration at the oxide-oxygen interface.
See table 26.	
PARAM SEG ALPHA TFINAL ZOCR SCALE2	PARAM is an array that contains material constants (diffusion constants, etc.) in the original units of micrometers and hours. SEG is the redistribution ($\equiv$ segregation) coefficient. The swelling constant ALPHA represents the reciprocal of the factor that a given volume of silicon swells when converted to oxide at the moving boundary. TFINAL is the length of time of oxidation. ZOCR is the position of the moving boundary in the z-coordinate frame in micrometers. SCALE2 is a scale factor used in the plots.

Further specific information about the previously defined output is given in table 22.

Table 22: Real Output (5 FORMAT (7F14.8)) (see blocks #30 and #34).

Whenever $MM = 1$ modulo (KPRINT), we print out

- (1) $C1(J)$ for $J = 1, NL, 15$.
- (2) $C2(J)$ for $J = NR, N2, 20$.
- (3) $TTMMP1$ (in units of BTM).
- (4) $C1(1)$, $CB(1)$, $CB(2)$, and DTS (in BTM units).

In addition, when $TIMEND < TTMMP1$, we print out

- (5) Array $PARAM$, SEG , $ALPHA$, $TFINAL$, $ZOCR$, and $SCALE2$ (all in micrometers and hours).
-

9.2.4. The Integer Output

Table 23: Definitions of Integer Output. See tables 24 and 25.

NL, NR	NL is the index of the grid point in the oxide that is nearest the moving boundary grid point. NR is the grid point in the silicon that is nearest the grid point at the moving boundary.
MM	The index of loop 78 that calculates the solution at time $t = TTMMP1$ from the known solution at time $t = TTMM$.
See table 26.	
NZO MME ND NYO NH KPRINT	These quantities were defined in table 18.

9.3. A Simple Example

In this section we illustrate how DISTRIB: VERSION 1 is used to compute the redistribution of an initially uniform distribution of boron under wet oxidation conditions. The material constants used in this sample calculation were chosen to obtain the best fit to the experimental data shown in figure 13. For further comments about the proper values for these material constants, see the end of this section.

The first card in computational block #2 reads the real input under format four. (This format card is also in computational block #2.) Since the initial boron distribution is uniform, the value of C_{MAX} which is the concentration at the first NH grid points in the silicon (y-region) is equal to $CBULK$ which represents the initial concentration in the

bulk of the silicon and is the value assigned in the program to the grid points $NH + 1$, $NH + 2$, ..., $N2$. Because the partial differential equations are homogeneous in the concentrations when CONOUT (sec. 2.1) is zero, as in this example, we normalize the input quantities CMAX, CBULK by the value of CBULK (atoms per cubic micrometer); therefore, these two input quantities have the value 1 and the output concentrations of these quantities should be multiplied through by CBULK to obtain the true concentrations. Once again, the glossary is for answering these questions. The next parameter read is the swelling ratio ALPHA (sec. 2.1) and it is assigned the value 0.44 [4].

We desire to find the concentration of the redistributed profile after $TFINAL = 0.3$ h. When $TTMMP1$ (T_{MMP1}) is greater than $TFINAL$, the program's control is shifted to the output printing blocks #34 and #35. The segregation coefficient SEG (dimensionless) is chosen to be 0.2, in order to obtain the fit shown in figure 13. The diffusion coefficients $DF1$, $DF2$ for the boron in the oxide and silicon, respectively, were specifically assigned the values 0.001 and 0.133 in order to obtain the fit shown in figure 13, and these values are within the range of the reported values for these quantities (see the end of this section). (Note that the ratios of the diffusion constants used in the program, see [7], were relaxed in order to obtain the fit in this example.) The meaning of the real grid input parameter $WFRC = 0.5$ is explained in section 7.1 in the material concerned with block #7.

The meaning of the next parameters read, CONPRO (micrometers per hour) and CONOUT (atoms per cubic micrometer), are related to the flux of boron between the ambient and oxide (sec. 2.1, eq (2.11)). As mentioned already, $CONOUT = 0$ in this example and CONPRO is chosen to have the value 1; other calculations show that results are not sensitive to the choice of CONPRO including the value zero. The next three parameters read, CNSTA (micrometers), CNSTB (square micrometers), CNTAU (hours), relate to the moving boundary motion (sec. 4.2, eq (4.5)). The wet oxidation is assumed to take place at $1100^{\circ}C$ and therefore from table 1 in [1] $CNTAU(\tau) = 0.0$, $CNSTA(A) = 0.11$, and $CNSTB(B) = 0.51$. The real input read next, $Y1S$, $Y2S$, $X2S$, and $X1S$ (sec. 4.4.), are parameters that assign maximum abscissa and ordinates that are plotted in regions one and two, i.e., the oxide and silicon regions, respectively, in the graphical output in computational block #34. The values $Y1S = 5$, $Y2S = 2$, $X2S = 4$, and $X1S = 2$ have always yielded good graphical output, and we recommend their use.

The integer input for DISTRIB is read following the real input in computational block #2 under format number 1 (also in computational block #2). The integer $NZO = 3$, whose significance is explained in section 4.1 below, eq (4.2), is read first. The quantity $MME = 1500$ represents the number of iterations we *a priori* assign to the loop 78 (computational block #14). In this example, only 595 iterations of loop 78 occur before $TTMMP1 > TFINAL = 0.3$ h and the program stops after printing the output in computational blocks #34 and #35. Integer ND represents the number of grid points in silicon to the right of the moving boundary point in

the silicon that are plotted in computational block #34 (see DO LOOP 234). The integer NYO = 350 is read next and its function in defining DY(Δy) is explained by eq (4.1). The integer NH = 12 (sec. 2.1, eq (2.13)) signifies that the initial concentration value CMAX is assigned to the first twelve grid points in the silicon region at time zero. Since in this example CMAX = CBULK, it makes no difference what the value of NH is except NH should be less than NYO in order for the problem to make sense. The print-out parameter KPRINT = 1000 signals (in block #30) the program to print out C1(), C2(), the concentrations in the oxide and the silicon, respectively, at the end of the iterations (1 + L*KPRINT) of loop 78 where L = 0, 1, ..., etc. Since the largest value of MM is, for this example, 595, the only values of arrays C1(), C2() printed out are those at the end of the first iteration of loop 78.

These are certain constant parameters that are not read into the program. These are described in section 9.2 (table 20).

For various literature references for material constants, we recommend [1,3,4,5,6,7,9,12,13] in the supplemental bibliography in chapter 13.

The output of DISTRIB is listed and described in section 9.2. The print-out in block #30 is effected after every MM = (1 + L*KPRINT)th iteration (for L = 0, 1, 2, ...) of loop 78, which is the loop computing the concentrations at the successive times t_{MM} . Since KPRINT = 1000 for this example and only 595 iterations of loop 78 are required to compute the concentrations at time $t_{MM} = T_{FINAL} = 0.3$ h in this example, the only concentrations printed, under block #30, are those after the first iteration and are shown in table 24. From this table and computational block #30, we see printed out the values of

C1(J), J = 1, NL, 15
C2(J), J = NR, N2, 20.

Since, at time $t_1 = 0.0389$ (BTM units), there is only one fixed grid point in the oxide, the only value in the oxide that is printed is the grid point at the oxide-oxygen interface. However, between the values of C1() and C2() that we have printed out in table 24, there appear the values of boron concentration at the moving boundary grid points in the oxide and silicon CB(1), CB(2). Also printed in the same row with these quantities are DTS (in BTM units) and the mesh width lengths in the oxide and silicon, respectively, DZ and DY in units of BLTH = 0.02 μ m. In the final print-out (table 26), BTM = 0.0030 h is printed. Also, table 24 shows the last index MM of loop 78 and index NL of the first fixed grid point to the left of the moving boundary in the oxide. Finally, in the same line appears the index NR of the first grid point to the right of the moving boundary in the silicon.

The printout from block #34 is shown in table 25. The main output are the concentrations

C1(J), J = 1, NL, 15
C2(J), J = NR, N2, 20.

These are the concentrations at the first time that $TTMMP1 (= 99.756)$ is greater than $TFINAL$ (in BTM units). It is seen from table 25 that this occurs at the end of the $MMth = 595$ iteration. The meaning of the other output in table 25 is similar to the corresponding output in table 24 that has already been described (see also sec. 9.23).

The concentrations at time $TTMMP1 = 99.756$ (in BTM units) or $TTMMP1 \approx TFINAL = 0.3$ h in the oxide are plotted in figure 11. The distances from the oxide-oxygen interface (scaled in $ZOP1$ units which is the length of the oxide region at time $TTMMP1 \approx TFINAL$) are plotted on the x-axis. The concentrations at the positions of the first and $(1 + L \cdot NMOD)$ th grid points (for $L = 1, 2, \dots$) are plotted on the y-axis, in this example, $NMOD = 8$. The value of $ZOP1$ (in micrometers) is computed in the last table (26). At the same time that the concentrations in the oxide are plotted in figure 11, the concentrations in the silicon are plotted in figure 12. The x-axis in this figure represents distance in the unit $UN2 = 2 \cdot \text{SQRT}(DF2 \cdot TTMMP1)$ (where $TTMMP1$ is very nearly equal to $TFINAL$) from the oxide-silicon moving boundary. The concentrations at the moving boundary (in the silicon) and at the location of the grid point with index NR are plotted. After this, the concentrations at the grid points with the successive locations $(NR - 1) \cdot DZ + (J - 2) \cdot NMOD1 \cdot DZ$, for $J = 3, \dots, ND$ (with $NMOD1 = 4$ in this particular example) are plotted. The unit length of the abscissa, $UN2$ (micrometers), is computed in table 26 from computational block #35. In addition, in table 26 are shown all the input quantities in units of micrometers and hours as printed out in computational block #35. Besides the input data that are printed out, the quantities $ZO(TFINAL)$ (this is the same as $ZOP1$, when $TFINAL = TTMMP1$) and $2 \cdot \text{SQRT}(DF2 \cdot TFINAL)$ in micrometers which, as we have already explained, are used as quantities to scale the x-axis in the oxide and silicon concentration plots in figures 11 and 12. Also printed is the value of BTM in hours; hence, the times in tables 24 and 25 which are in units of BTM, can be converted to hours, if so desired.

Table 24. Example of output of concentration in oxide and silicon at end of iteration MM = (1 + L*KPRINT) in loop 78 for L = 0.

C1(.) AT TIME		.038598095					
2.52280046							
MM	NL	NR					
1	1	2					
C1(1)	CB(1)	CB(2)	DTS	DZ	DY		
2.52280046	3.88795223	.77759045	.03899809	.54112554	.71428571		
C2(.) AT TIME		.038598095					
.98484473	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000
1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000
1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000

Table 25. Example concentrations in oxide and silicon when TTMMP1 $\approx$ TFINAL.

C1(.) AT TIME		99.756364064					
.03302989		.87542717					
MM	NL	NR					
595	32	12					
C1(1)	CB(1)	CB(2)	DTS	DZ	DY		
.03302989	.81307112	.16261422	.28899809	.54112554	.71428571		
C2(.) AT TIME		99.756364064					
.18953686	.84437386	.98733067	.99958049	.99999438	.99999997	1.00000000	1.00000000
1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000
1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000	1.00000000

Table 26. Listing of input physical data (micrometers, hours) and important computational data.

DATA FOR STEP NO		1					
DF1	DF2	CONPRO	CONOUT	CNSTA	CNSTB	CNTAU	
.00100000	.13300000	1.00000000	.00000000	.11000000	.51000000	.00000000	
SEG	ALPHA	WFRC	TFINAL	Z0(TFINAL)	2*SQRT(DF2*TFINAL)		
.20000000	.44000000	.05000000	.30000000	.34001236	.39949969		
CB(1)	CB(2)	FIRST+DT	REAL TIME	BDRY			
.81307112	.16261422	.00086917	.30001914	5.00000000			
CMAK	CBULK	Y1S	Y2S	X2S	X1S	BTM	
1.00000000	1.00000000	5.00000000	2.00000000	4.00000000	2.00000000	.00300752	
NZC	NWE	ND	NYO	NH	KPRINT		
3	1500	30	350	12	1000		



Figure 11. Plot of example concentrations in oxide when $TTMPL \approx TFINAL$.

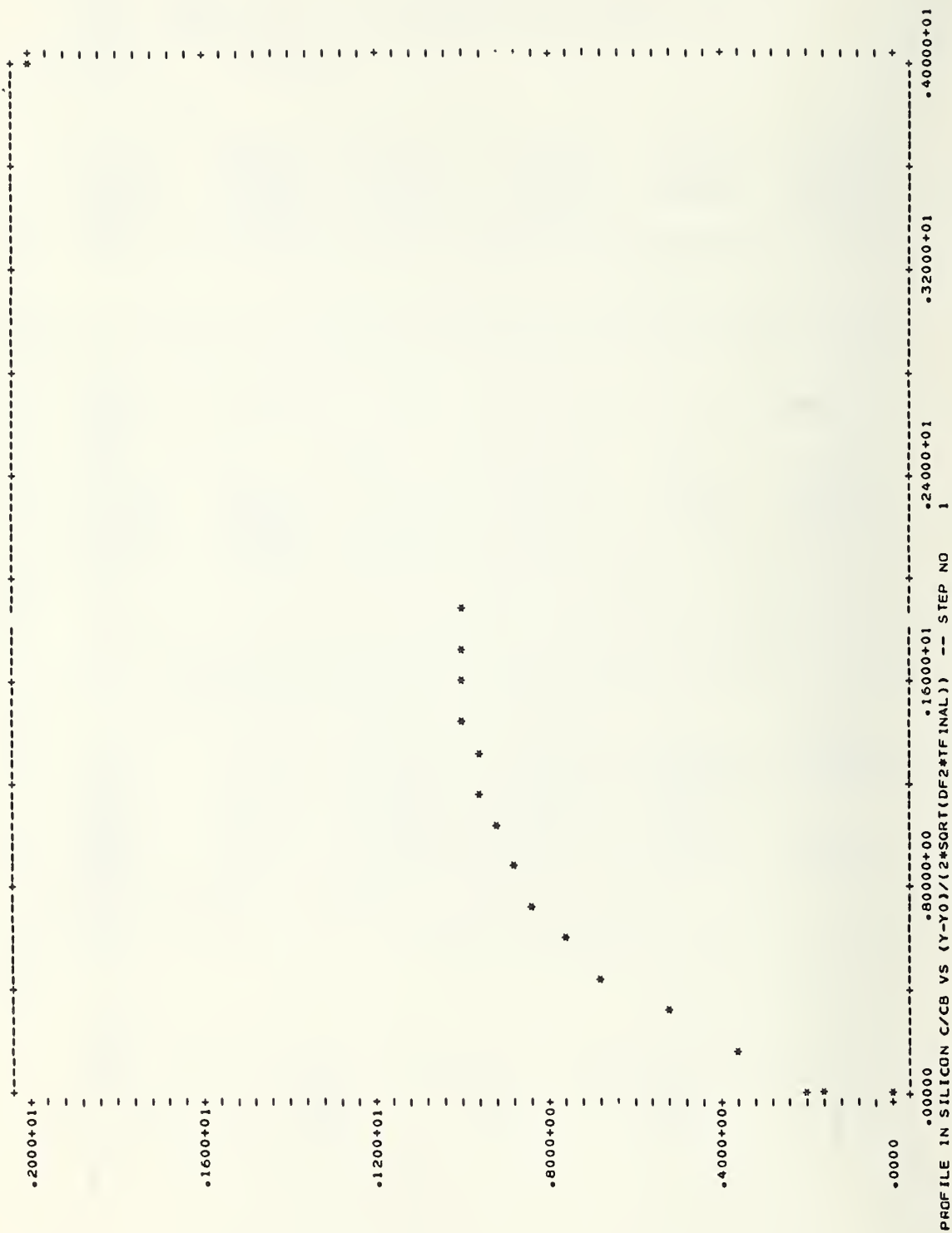


Figure 12. Plot of example concentrations in silicon when $\text{TTMPL} \approx \text{TFINAL}$.

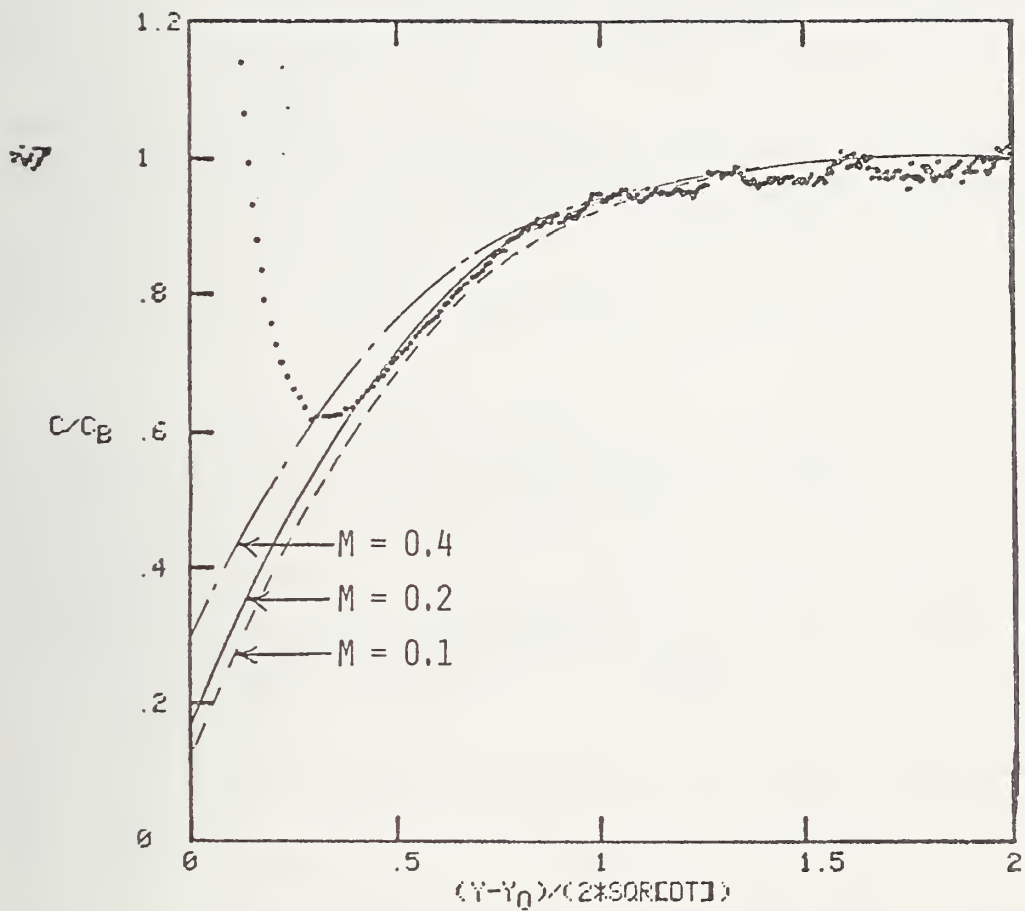


Figure 13. Comparison of three calculated impurity concentration distributions in silicon with experimentally determined concentration data.

10. VERIFICATION OF PROGRAM

10.1. Validation of the Program

A solution calculated by DISTRIB for a problem with the specified concentration $C_1(0,t) = C_0$ at the oxygen-oxide interface has been compared with an analytic similarity solution given in [4]. The calculated boundary concentrations $C_1(z_0(t), t)$ agree with the similarity solution [5] to within a few percent for a variety of problems with differing segregation constants. The calculated solutions also have qualitative properties possessed by the similarity solution such as moving boundary concentrations that are constant with time. There is also an analytic solution to special problems with zero flux at the oxygen-oxide interface. In this problem, the concentration in the oxide or z-region is constant and DISTRIB's calculated solution is constant also for these conditions.

10.2. Limitations of the Program

The previous remarks must all be qualified for very short times, up to $5\Delta t$ [5]. The difficulties in obtaining the solutions for the first few iterations are similar to those described in [2] for analogous problems. The problem with the inaccuracy of the first few iterations can be somewhat mollified, however, by choosing smaller and smaller values of WFCR. Our recommendation for obtaining a solution at small times is to calculate solutions using a series of decreasing values of WFCR and then use those solutions to extrapolate the solutions to time zero.

11. PROGRAM LISTINGS

11.1. DISTRIB: VERSION 1 MAIN PROGRAM

```

C      START COMPUTATION BLOCK NUMBER 1
      IMPLICIT DOUBLE PRECISION (A-H,O-Z)
      REAL XPL(200) ,YPL(200)
      DIMENSION TT(2000),ZO(2000),AF(2000),RF(2000),PARAM(21)
      DIMENSION BT(20), DFA(20),DFB(20),CONPR(20),CNST1(20),CNST2(20),
1  CNTA(20),TFINN(20),ZONNEW(20),TNEW(20)
      COMMON/BL20/DT,DY,DZ,THETA
      COMMON/BL21/DF1,DF2
      COMMON/BL22/DZP,DYP
      COMMON/BL23/ B2M,B2R,B2L,A2L,A2M,A2R,A1L,A1M,A1P,B1L,B1M,B1P
      COMMON/BL24/C2L,C2M,C2R,C1L,C1M,C1P
      COMMON/BL25/P(2),Q(2),PA(2),QA(2),C(2),CB(2),R(2),S(2),SM(2)
      COMMON/BL26/P1(2000),P2(2000),Q1(2000),Q2(2000),D1(2000),D2(2000)
      COMMON/BL28/N2M1,NLM1,N2 , NRP1,NL,NR
      COMMON/BL29/C1(2000),C2(2000)
      COMMON /BL30 / CO,CK,TZERO,JEE,ALPHA,CAPA,SEG,CMVY
      COMMON /BL31 / DIST(100), SOL(100)
      COMMON/BL32/CONPRO,CONOUT
C      END COMPUTATION BLOCK NUMBER 1
C      =====
C      START COMPUTATION BLOCK NUMBER 2
      READ(5,4)CBULK,CMAX,ALPHA,TFINAL,SEG,DF1,DF2,WERC,BDRY,CONPRO,
1  CONOUT,CNSTA,CNSTB,CNTAU,Y1S,Y2S,X2S,X1S
      READ(5,1)NZO,MME,ND,NYO,NH,KPRINT
1  FORMAT (6I6)
4  FORMAT (5F10.5)
5  FORMAT (7F14.8)
41  FORMAT ( 40H MM NL NR )
43  FORMAT (40H MME MUST BE INCREASED )
8  FORMAT (16H C1(.) AT TIME ,1F14.9)
9  FORMAT (16H C2(.) AT TIME ,1F14.9)
26  FORMAT( 1H1 )
27  FORMAT(40H TLIN CNTAU TTMM SLOPEZCRIT CNSTX )
36  FORMAT ( 45H PROFILE IN OXIDE ---C/CB VS Z/70-- STEP NO ,1I5 )
32  FORMAT (1H1 )
39  FORMAT ( 40H TIMEND TNEW(J) BTM CNTAU TLIN BT(J) )
45  FORMAT (101H C1(1) CB(1) CR(2) DTS
1  DZ DY )
C      END COMPUTATION BLOCK NUMBER 2
40  FORMAT ( 52H ZOP1,DF2,UN2,DY,DZ,FNC,(NL-1),TTMMP1,SCALE2,X2SCUT )
38  FORMAT ( 19H DATA FOR STEP NO ,1I5)
28  FORMAT( 33H NZO MME ND NYO NH JSTOP )
29  FORMAT( 43H S(1) ST STM E1 E2 E3 ERROR )
30  FORMAT( 33H LIST OF ZO(.) )
31  FORMAT( 33H LIST OF TT(.) )
33  FORMAT (100H DF1 DF2 CONPRO CONOUT
1  CNSTA CNSTB CNTAU )
35  FORMAT( 67H PROFILE IN SILICON C/CB VS (Y-Y0)/(2*SQRT(DF2*TFINAL)
1  ) -- STEP NO ,1I5 )
20  FORMAT (21H LIST AF(.) )
21  FORMAT (21H LIST RF(.) )
22  FORMAT ( 30H COXIDE CBULKZ01 ALPHA TFINAL )
23  FORMAT (103H SEG PRINT DF1 DF2 WERC BDRY CMAX CONPRO CONOUT
1  CNSTA CNSTB CNTAU Y1S Y2S X2S )
24  FORMAT( 33H LIST N2 NH N1 NR NL )
25  FORMAT( 33H LIST DZ DY DT TT(1) SM(1) SM2 )
19  FORMAT (21H LIST P1(.) Q2(.) )
16  FORMAT ( 33H LIST B2L B2P B2M B1L B1R B1M )

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17  FORMAT ( 33H LIST A2L A2R A2M A1L A1R A1M          )
15  FORMAT( 20H LIST OF P1(.),Q1(.))
14  FORMAT (60H VALUES OF RM RZ  RY B C F CMV1 CMV2 P1S P2S AT MM=
1      ,1I9 )
13  FORMAT (61H VALUES OF FNL DZP DYP TES ZOP1 FNR  TT(MMP1) SES AT
1      MM=      ,1I8)
12  FORMAT (28H DIVIDE FAULT AT MOV. BDRY.          )
11  FORMAT (28H DIVIDE FAULT AT LOOP 107            )
10  FORMAT (28H DIVIDE FAULT AT LOOP 105            )
34  FORMAT (101H      SEG      ALPHA      WFERC      TFINAL
1      ZO(TFINAL)  2*SORT(DF2*TFINAL)              )
6   FORMAT ( 7F10.5 )
37  FORMAT( 80H      CB(1)      CB(2)      FIRST+DT      REAL TIME
1      BDRY                                          )
44  FORMAT (101H      CMAX      CBULK      Y1S      Y2S
1      X2S      X1S      BTM                      )
42  FORMAT ( 50H  NZO  MME  ND  NYO  NH  KPRINT      )
C   DATA FIXED IN VERSION 1
    DATA  DFA(1),DFB(1), CONPR(1),CNST1(1),CNST2(1), CNTA(1),TFINN(1)
1    / .0001D0, .0001D0, .01D0, .027D0, .1D0, .1D0, .01D0/
    TW=0.
    ZW=0.
    JSAVE=0
    JSTOP =1
    Z01=0.
    COXIDE=1.
C   JSTOP TELLS NUMBER OF DRIVE IN STEPS
    JSTM1=JSTOP-1
C   =====
C   START COMPUTATION BLOCK NUMBER  3
    SCALE2 = 2.* SQRT(DF2*TFINAL)
C   THESE MATERIAL PARAMETERS ARE RESCALED THUS WE HAVE TO STORE
C   THESE GIVEN PARAMETERS IN UNITS OF MICPONS AND HOURS
    PARAM(1)=DF1
    PARAM(2)=DF2
    PARAM(3)= CONPRO
    PARAM(4)=CONOUT
    PARAM(5)=CNSTA
    PARAM(6)=CNSTB
    PARAM(7)=CNTAU
C   END  COMPUTATION BLOCK NUMBER  3
C   =====
C   START COMPUTATION BLOCK NUMBER  4
    BLTH= .02
C   DFC MODIFIES PROGRAM TO DIMENTIONALISE ABOUT DFC*DF2
    DFC= 1.
    DF2=DF2*DFC
    BTM=(BLTH**2)/DF2
    CONPRO=CONPRO*(BTM/BLTH)
    CNSTA=CNSTA/BLTH
    CNSTB=CNSTB/DF2
    CNTAU=CNTAU/BTM
    BDRY=BDRY*(1./BLTH)
    Z01=Z01*(1./BLTH)
    DF1=DF1/DF2
    DF2=1./DFC
    TIMEND=TFINAL*(1./BTM)
C   END  COMPUTATION BLOCK NUMBER  4
C   Z01 IS POSITION ON Z-AXIS WHERE THE NON DEGENERATE (ZO(ZERO)
C   NOT EQUAL TO ZERO ) MOVING BOUNDARY BEGINS
C   ZCRIT IS THE POSITION ON THE Z-AXIS WHERE THE MOVING BOUNDARY
C   CHANGES FROM LINEAR TO PARABOLIC
C   CALCULATE DY,DZ,DT AND AUXILLARY QUANTITIES
    Y01=ALPHA*Z01

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C =====
C START COMPUTATION BLOCK NUMBER 5
  DY=BDRY/NYO
  FNZO=FLOAT(NZO)
  DZ=DY*(1./(ALPHA*FNZO))
C END COMPUTATION BLOCK NUMBER 5
C =====
C START COMPUTATION BLOCK NUMBER 6
  CNA=.5*CNSTA
  CNB=CNSTB
  TAKE OUT FOLLOWING CARD IF CNSTX IS KNOWN
  CNSTX=SQRT(CNA**2+CNB*CNDAU) -CNA
C END COMPUTATION BLOCK NUMBER 6
  CNDAU=CNSTX*(CNSTX+CNSTA) /CNSTB
C =====
C START COMPUTATION BLOCK NUMBER 7
  DM=DZ*WFRG
C INSERT IF MOVING BDRY IS LINEAR AND THEN PARABOLIC
  TLIN=CNDAU
C IF MOVING BOUNDARY STARTS AT Y'0. THESE CARDS TAKE CARE OF SITUATIO
C N THAT LINEAR PART OF MOVING BOUNDARY IS NOT PRESENT
  IF( TLIN .LE. .00000001 )DT=(DM*(DM+CNSTA))/CNSTB
  IF( TLIN .LE. .00000001 )DTS=DT
  IF( TLIN .LE. .00000001 )ZCRIT=0.
  IF( TLIN .LE. .00000001 )SLOPE=1.
  IF(TLIN .LE. .00000001 )GO TO 216
  ZCRIT=CNSTX
  SLOPE=ZCRIT/CNDAU
  DT=DM/SLOPE
  DTS=DT
216 CONTINUE
C END COMPUTATION BLOCK NUMBER 7
C =====
C START COMPUTATION BLOCK NUMBER 8
  PARAM(10)=DT*BTM
C END COMPUTATION BLOCK NUMBER 8
C =====
C START COMPUTATION BLOCK NUMBER 9
C CALCULATE INITIAL INITIAL DISTRIBUTIONS
  DUM=Y01/DY
  NR=INT(DUM)+2
  N1=INT(Z01/DZ)+1
  NL=N1
  N2=NY0+1
  N2M1=N2-1
C END COMPUTATION BLOCK NUMBER 9
  DO 98 J=1,N1
  C1(J)=COXIDE
98 CONTINUE
  CB(1)=COXIDE
C =====
C START COMPUTATION BLOCK NUMBER 10
  N1P1=N1+1
  NH=NH +NR
  NHP1=NH+1
  DO 96 J=NR ,NH
  C2(J)=CMAX
96 CONTINUE
  DO 97 J=NHP1,N2
  C2(J)=CBULK
97 CONTINUE
  CB(2)=CMAX
C END COMPUTATION BLOCK NUMBER 10

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C      START COMPUTATION BLOCK NUMBER 11
      IF(Z01 .LE. ZCRIT) TTMM = Z01/SLOPE
      IF(Z01 .GT. ZCRIT) TTMM= (Z01*(Z01+CNSTA))/CNSTR
C      END COMPUTATION BLOCK NUMBER 11
C      =====
C      START COMPUTATION BLOCK NUMBER 12
      FNL=FLOAT(NL)-1.
      FNR=FLOAT(NR)-1.
      SM(1)=(Z01-FNL*NZ)/DZ
      SM(2)=(FNR*DY-Y01)/DY
C      END COMPUTATION BLOCK NUMBER 12
C      =====
C      START COMPUTATION BLOCK NUMBER 13
      MAIN LOOP
      P2(N2)=0.
      Q2(N2)=C2(N2)
C      END COMPUTATION BLOCK NUMBER 13
C      =====
C      START COMPUTATION BLOCK NUMBER 14
      ZOPS=0.
      ZOP1=0.
      TJ=0.
      NORUN=1
      KPOW=0
      JSAVE=0
      DO 78 MM=1,MME
C      END COMPUTATION BLOCK NUMBER 14
C      =====
C      START COMPUTATION BLOCK NUMBER 15
      KW=MOD(MM,KPRINT)
C      END COMPUTATION BLOCK NUMBER 15
C      =====
C      START COMPUTATION BLOCK NUMBER 16
      SPEEDS UP MOVING BOUNDARY
      ZOACEL=(ZOP1-ZOPS)/DZ
      IF(ZOACEL .GE. .2 ) GO TO 88
      KPOW=KPOW+1
      IF(KPOW .GT. 100 )DTS=DTS+.05
      IF(KPOW .GT. 100 )DT=DTS
      IF(KPOW .GT. 100 )CALL TRIDNL
      IF(KPOW .GT. 100 )KPOW=KPOW-100
88  CONTINUE
C      ZOPS IS ZO(TTMM)
      ZOPS=ZOP1
C      END COMPUTATION BLOCK NUMBER 16
C      =====
C      START COMPUTATION BLOCK NUMBER 17
      IF(TJ .GE. 1.) NL=NL+1
      IF(TJ .GE. 1.)C1(NL)=CB(1)
      IF(TJ .GE. 1.)FNL=FNL+1.
      NLM1=NL-1
      NLM2=NL-2
      IF(TJ .GE. 1.)DT=DTS
      IF(TJ .GE. 1.) CALL TRIDNL
      IF(TJ .GE.1. ) SM(1)=0.
C      END COMPUTATION BLOCK NUMBER 17
C      =====
C      START COMPUTATION BLOCK NUMBER 18
      MMP1=MM+1
      TTMMPI=TTMM+DT
      IF( TTMMPI .LE. TLIN ) ZOP1 = ( TTMMPI - TW)* SLOPE +ZW
      IF(TTMMPI .GT. TLIN)ZOP1=SQRT((CNA**2)+CNB*(TTMMPI-TW))-CNA+ZW
      YOP1=ALPHA*ZOP1
C      END COMPUTATION BLOCK NUMBER 18

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C =====
C START COMPUTATION BLOCK NUMBER 19
C CHECK IF NEW CELLS ARE ADDED
SES=(FNR*DY-YOP1)/DY
IF(SES .LT. 0.) NR=NR+1
IF(SES .LT. 0.) FNR=FNR+1.
IF(SES .LT. 0.) SM(2)=1.
NRP1=NR+1
NRP2=NR+2
NRM1=NR-1
C END COMPUTATION BLOCK NUMBER 19
C =====
C START COMPUTATION BLOCK NUMBER 20
MMP2=MMP1+1
TTMMP2=TTMMP1+DT
IF( TTMMP2 .LE. TLIN ) ZOP2=(TTMMP2 -TW )* SLOPE + ZW
IF( TTMMP2 .GT. TLIN ) ZOP2=SQRT((CNA**2)+CNB*(TTMMP2-TW))-CNA+ZW
TJ=(ZOP2-FNL*DZ)/DZ
IF(TJ .LT. 1.) GO TO 219
ZOP1=(FNL+1.)*DZ
IF( ZOP1 .LE. ZCRIT)TTMMP1=(ZOP1-ZW)/SLOPE + TW
IF( ZOP1 .GT. ZCRIT)TTMMP1=((ZOP1-ZW)*( ZOP1-ZW+CNSTA))/CNSTB +TW
DT=TTMMP1-TTMM
CALL TRIDNL
YOP1=ALPHA*ZOP1
219 CONTINUE
C END COMPUTATION BLOCK NUMBER 20
C CONSERVATION OF NUMBER CALCULATION
S1M=C1(NL)*DZ*.5+(C1(NL)+CB(1))*SM(1)*.5*DZ
IF(NL .EQ. 1) S1M=(C1(1)+ CB(1))*SM(1)*.5*DZ
IF(NL .GE. 2)S1M=S1M+.5*DZ*C1(1)
IF(NL .LE. 2) GO TO 222
DO 111 J=2,NLM1
S1M=S1M+DZ*C1(J)
111 CONTINUE
222 S2M=C2(NR) *DY*.5+(C2(NR)+CB(2))* SM(2)*.5*DY
DO 112 J=NRP1,N2M1
S2M=S2M+C2(J)*DY
112 CONTINUE
C =====
C START COMPUTATION BLOCK NUMBER 21
S(1)=(ZOP1-FNL*DZ)/DZ
S(2)=(FNR*DY-YOP1)/DY
C END COMPUTATION BLOCK NUMBER 21
C =====
C START COMPUTATION BLOCK NUMBER 22
IF(MM .EQ. 1) CALL TRIDNL
C END COMPUTATION BLOCK NUMBER 22
C =====
C START COMPUTATION BLOCK NUMBER 23
IF(NL.GT. 1) GO TO 223
IF(NL .EQ. 1)DM1=S(1)*DZ
IF(NL .EQ. 1)DM2=DM1*DM1/(2.*DT)
IF(NL .EQ. 1 .AND.MM .EQ. 1) DM2=0.
IF(NL .EQ. 1)DM3=DM2
IF(NL .EQ. 1)DM=1./( DF1+DM2+DM1*CONPRO)
IF(NL .EQ. 1 )P1(1)=DM*DF1
IF(NL .EQ. 1)Q1(1)=DM*(C1(1)*DM3+DM1*CONPRO*CONOUT)
C END COMPUTATION BLOCK NUMBER 23

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C =====
C START COMPUTATION BLOCK NUMBER 24
223 IF(NL .GT. 1 )DM=1./((DZ*DZ/(2.*DT) +DZ* CONPRO+DF1 )
    IF(NL .GT. 1 )P1(1)=DF1*DM
        IF(NL .GT. 1 )Q1(1)=(+C1(1)*(DZ**2)/(2.*DT)+DZ*CONPRO*CONOUT)*DM
C END COMPUTATION BLOCK NUMBER 24
C =====
C START COMPUTATION BLOCK NUMBER 25
    IF(NL .LE. 2) GO TO 213
    DO 203 J=2,NLM1
    AF(J)=A1M*C1(J)
203 CONTINUE
    DO 205 J=2,NLM1
    JM1=J-1
    Q1(J)=(AF(J)-Q1(JM1)*A2L)/D1(J)
205 CONTINUE
C END COMPUTATION BLOCK NUMBER 25
    IF(MM .EQ. KD) WRITE( 6,15)
    IF(MM .EQ.KD) WRITE(6,5) (P1(J),J=1,NLM1,1)
    IF(MM .EQ.KD)WRITE(6,5) (Q1(J),J=1,NLM1,1)
    IF( MM .EQ. KD ) WRITE(6,20)
    IF(MM .EQ. KD)WRITE(6,5) (AF(J) ,J=2,NLM1,1)
C =====
C START COMPUTATION BLOCK NUMBER 26
213 CONTINUE
    DO 204 J=NRP1,N2M1
    BF(J)=B1M*C2(J)
204 CONTINUE
    NE=N2-NRP1
    DO 207 J=1,NE
    K=N2-J
    KP1=K+1
    Q2(K)=(BF(K)-Q2(KP1))/D2(K)
207 CONTINUE
C END COMPUTATION BLOCK NUMBER 26
C =====
C START COMPUTATION BLOCK NUMBER 27
    CALL CENTER
C END COMPUTATION BLOCK NUMBER 27
C =====
C START COMPUTATION BLOCK NUMBER 28
    DO 209 J=NRP1,N2M1
    JM1=J-1
    C2(J)=P2(J)*C2(JM1)+Q2(J)
209 CONTINUE
C END COMPUTATION BLOCK NUMBER 28
C =====
C START COMPUTATION BLOCK NUMBER 29
    IF(NL .LE. 1) GO TO 215
    DO 210 K=1,NLM1
    J=NL-K
    JP1=J+1
    C1(J)=P1(J)*C1(JP1)+Q1(J)
210 CONTINUE
215 CONTINUE
C END COMPUTATION BLOCK NUMBER 29
C =====
C START COMPUTATION BLOCK NUMBER 30
    IF(KW .EQ. 0 .OR. KW .GT. 1) GO TO 799
    WRITE(6,32)
    IF(KW .EQ. 1) WRITE(6,8) TTMP1
    IF(KW .EQ. 1 )WRITE(6,5) (C1(J) ,J=1,NL,15 )
    WRITE(6,41)
    IF(KW .EQ. 1) WRITE(6,1) MM,NL,NR

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WRITE(6,45)
WRITE(6,5) C1(1),CB(1),CR(2),DTS,DZ,DY
IF(KW.EQ. 1) WRITE(6,9) TTMMMP1
IF(KW.EQ. 1)WRITE(6,5) (C2(J),J=NR ,N2,20)
799 CONTINUE
C END COMPUTATION BLOCK NUMBER 30
C =====
C START COMPUTATION BLOCK NUMBER 31
SM(1)=S(1)
SM(2)=S(2)
TTMM=TTMMMP1
C END COMPUTATION BLOCK NUMBER 31
C SHIFT TO NEW MOVING BOUNDARY AND CALC NEW PAPAMETERS
C =====
C START COMPUTATION BLOCK NUMBER 32
IF ( TIMEND .GT. TTMMMP1 ) GO TO 78
C END COMPUTATION BLOCK NUMBER 32
C =====
C START COMPUTATION BLOCK NUMBER 33
IF(JSTOP .EQ. 1 ) GO TO 800
C END COMPUTATION BLOCK NUMBER 33
MTIME=MTIME+1
TT(MTIME)=TTMMMP1
ZO(MTIME)=ZOP1
C CALCULATE CONERVED QUANTITIES AND GRAPH OF STANDARD S DIMENSION
IF(KW .LT. 1) GO TO 800
AF(1)=YOP1
DM=S(2)
AF(2)=AF(1)+DM *DY
BF(1)=CB(2)
BF(2)=C(2)
DO 803 J=3,ND
AF(J)=AF(2)+(J-2.)*DY*10.
K=NR +(J-2)*10
BF(J)=C2(K)
803 CONTINUE
DO 250 J=1,ND
XRL(J)=AF(J)
YRL(J)=BF(J)
250 CONTINUE
WRITE(6,26)
CALL PLOT (ND,XPL,YRL)
C CONSERVATION OF NUMBER CALCULATION
S1 =C1(NL)*DZ*.5+(C1(NL)+CB(1))* S(1)*.5*DZ
IF(NL.EQ. 1) S1 =(C1(1)+CB(1))*S(1)*.5 *DZ
IF(NL.GE. 2)S1 =S1 +.5*DZ*C1(1)
IF(NL.LE. 2) GO TO 221
DO 113 J=2,NLM1
S1 =S1 +DZ*C1(J)
113 CONTINUE
221 S2 =C2(NR) *DY*.5+(C2(NR)+CB(2))* S(2)*.5*DY
DO 114 J=NRP1,N2M1
S2 =S2 +C2(J)*DY
114 CONTINUE
STM= S1M+S2M
ST=S1+S2
E1=ST-STM
RY=(DF2*DT)/(DY**2)
E2=-DT*(CONPRO)*(C1(1)-CONOUT)
E3=RY*(C2(N2)-C2(N2M1))*DY
ERROR=E1-(E2+E3)

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```

C =====
C START COMPUTATION BLOCK NUMBER 34
800 CONTINUE
WRITE(6,26)
      WRITE(6,8) TTMP1
      WRITE(6,5) (C1(J),J=1,NL,5)
WRITE(6,41)
      WRITE(6,1) MM,NL,NR
WRITE(6,45)
WRITE(6,5) C1(1),CB(1),CB(2),DTS,DZ,DY
      WRITE(6,9) TTMP1
      WRITE(6,5) (C2(J),J=NR,N2,20)

NMOD=8
NMOD1=4
UN1=1./ZOP1
UN2=2.*SQRT(DF2*TTMP1)
UN2=1./UN2
EZ=DZ*UN1
NLP1=NL+1
NLP2=NLP1+1
NLP3=NLP2+1
AF(1)=0.
BF(1)=C1(1)
NC=INT((NL-1)/NMOD)
FNC=FLOAT(NC)
IF(NC.LT.1) GO TO 231
DO 230 J=1,NC
  K=J*NMOD+1
  JP1=J+1
  BF(JP1)=C1(K)
  AF(JP1)=(K-1)*EZ
230 CONTINUE
231 NCP1=NC+2
  NCP2=NC+3
  NCP3=NC+4
  AF(NCP1)=ZOP1*UN1
  BF(NCP1)=CB(1)
  BF(NCP2)=Y1S
  AF(NCP2)=X1S
  AF(NCP3)=0.
  BF(NCP3)=0.
  DO 252 J=1,NCP3
    XRL(J)=AF(J)
    YRL(J)=BF(J)
252 CONTINUE
  WRITE(6,26)
  CALL PLOT (NCP3,XRL,YRL)
  WRITE(6,36)NORUN
  EY=DY*UN2
  AF(NLP2)=0.
  BF(NLP2)=CB(2)
  BF(NLP3)=C2(NR)
  AF(NLP3)=AF(NLP2)+S(2)*EY
  DO 232 J=3,ND
    K=NLP3+J-2
    KS=NR+(J-2)*NMOD1
    BF(K)=C2(KS)
    AF(K)=AF(NLP3)+(J-2)*EY*NMOD1
232 CONTINUE
  DO 234 J=1,ND
    K=J+NLP1
    AF(J)=AF(K)
    BF(J)=BF(K)

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234 CONTINUE
  X2SCT=X2S/2.
  NDE=0
  DO 235 J=1,ND
    IF(AF(J) .LT. X2SCT) NDE=NDE+1
235 CONTINUE
  NDP1=NDE+1
  AF(NDP1)=X2S
  BF(NDP1)=Y2S
  NDP2=NDP1+1
  AF(NDP2)= 0.
  BF(NDP2)=0.
  DO 251 J=1,NDP2
    XRL(J)=AF(J)
    YRL(J)=BF(J)
251 CONTINUE
  WRITE(6,26)
  CALL PLOT (NDP2,XRL,YRL)
C   END      COMPUTATION BLOCK NUMBER 34
C   =====
C   START COMPUTATION BLOCK NUMBER 35
  WRITE (6,35) NORUN
  PARAM(8)=CR(1)
  PARAM(9)=CB(2)
  PARAM(10)=DT*BTM
  PARAM(11)=TTMMP1*BTM
  PARAM(12)=BDRY*BLTH
  ZOCCR=ZOP1*BLTH
  WRITE(6,32)
  WRITE(6,38) NORUN
  WRITE(6,33)
  WRITE(6,5) (PARAM(J),J=1,7 )
  WRITE (6,34)
  WRITE(6,5) SEG,ALPHA,WFCR, TFINAL,ZOCCR ,SCALEP
  WRITE(6,37)
  WRITE(6,5) (PARAM(J) , J=8,12 )
  PARAM(12)=CMAX
  PARAM(13)=CBULK
  PARAM(14)=Y1S
  PARAM(15)=Y2S
  PARAM(16)=X2S
  PARAM(17)=X1S
  PARAM(18)=BTM
  WRITE(6,44)
  WRITE(6,5) (PARAM(J), J=12,18 )
  WRITE(6,42)
  WRITE(6,1) NZO,MME ,ND ,NYO,NH ,KPRINT
C   END      COMPUTATION BLOCK NUMBER 35
C   =====
C   START COMPUTATION BLOCK NUMBER 36
  JSAVE =JSAVE +1
  IF( JSTOP .EQ. JSAVE ) GO TO 79
C   END      COMPUTATION BLOCK NUMBER 36
  J = JSAVE
  DF2= DFB(J)*DFC
  BT (J) =( BLTH**2)/ DF2
  WRITE(6,5)DFB(1),DFC,DF2,BLTH,BT(1)
  TNEW(J)= TTMMP1* BTM/BT (J)
  CONPRO = CONPR (J)* ( BT (J)/ BLTH)
  CNSTA  = CNST1(J)/BLTH
  CNSTB  = CNST2(J)/DF2
  CNTAU  = CNTA (J)/BT (J)
  DF1 = DFA(J)/DF2
  DF2 = 1./DFC

```

```

WRITE(6,5)DFB(1),DFC,DF2,BLTH,BT(1),DF1,DFA(1)
CNA = .5 * CNSTA
CNB = CNSTB
CNSTX = SQRT ( CNA**2 +CNB*CNDAU )-CNA
TLIN = CNDAU + TNEW(J)
C
CALCULATE DT SLOPE ZCRIT
DM=DZ*WFRC
IF( CNDAU .LE. .00000001)DT= (DM*(DM+ CNSTA) )/CNSTB
IF( CNDAU .LE. .00000001)DTS =DT
IF( CNDAU .LE. .00000001) ZCRIT = ZOP1
IF( CNDAU .LE. .00000001) SLOPE =1.
IF( CNDAU .LE. .00000001) GO TO 316
ZCRIT = ZOP1 + CNSTX
SLOPE = CNSTX/CNDAU
DT = DM/SLOPE
DTS=DT
316 CONTINUE
ZONEW(J) = ZOP1
TTMM= TNEW(J)
NORUN=NORUN+1
WRITE(6,27 )
WRITE(6,5)TLIN,CNDAU,TTMM, SLOPE ,ZCRIT, CNSTX
TW =TNEW(J)
TIMEND = TFINN(J) * 1./BT (J)
WRITE(6,39)
WRITE(6,5) TIMEND,TNEW(J),BTM,CNDAU,TLIN,BT(J)
ZW= ZONEW(J)
SCALE2 = 2.* SQRT(DFB(J)*TFINN(J))
BTM=BT(J)
TFINAL=TFINN(J)
CALL TRIDNL
PARAM(1)=DFA(J)
PARAM(2)=DFB(J)
PARAM(3)= CONPR(J)
PARAM(4)=CONOUT
PARAM(5)=CNST1(J)
PARAM(6)=CNST2(J)
PARAM(7)=CNDA(J)
C =====
C START COMPUTATION BLOCK NUMRER 37
78 CONTINUE
IF(TIMEND .GT. TTMP1) WRITE(6,43)
79 CONTINUE
STOP
END

```

11.2. Subroutine CENTER

```

C      START COMPUTATION BLOCK NUMBER  0
      IMPLICIT DOUBLE PRECISION (A-H,O-Z)
      COMMON/BL20/DT,DY,DZ,THETA
      COMMON/BL21/DF1,DF2
      COMMON/BL25/P(2),Q(2),PA(2),QA(2),C(2),CB(2),R(2),S(2),SM(2)
      COMMON/BL26/P1(2000),P2(2000),Q1(2000),Q2(2000),D1(2000),D2(2000)
      COMMON/BL28/N2M1,NLM1,N2 , NRP1,NL,NR
      COMMON/BL29/C1(2000),C2(2000)
      COMMON /BL30 / CO,CK,TZERO,JEE,ALPHA,CAPA,SEG,CMVY
      COMMON/BL32/CONPRO,CONOUT
C      END      COMPUTATION BLOCK NUMBER  0
      5      FORMAT (7F14.5)
      30      FORMAT( 43H S(1) SU SUM FL FR ERR
C      CONSERVE CALCULATION
      SUM=      DZ* (C1(NL)+CB(1))*0.5 *SM(1) +DY*
1SM(2)*(C2(NR) +CB(2))*0.5+C2(NR)*DY*0.5
C      =====
C      START COMPUTATION BLOCK NUMBER  1
      P(2)=P2(NRP1)
      Q(2)=Q2(NRP1)
C      END      COMPUTATION BLOCK NUMBER  1
C      =====
C      START COMPUTATION BLOCK NUMBER  2
      IF(NL .EQ. 1) GO TO 849
      P(1)=P1(NLM1)
      Q(1)=Q1(NLM1)
C      END      COMPUTATION BLOCK NUMBER  2
C      =====
C      START COMPUTATION BLOCK NUMBER  3
      849 R(1)=      2.*DT/(DZ**2)
      R(2)=2.*DF2*DT/(DY**2)
      DO 850 L=1,2
      IF(NL .EQ. 1 .AND. L .EQ. 1 )GO TO 850
C      COMPUTE P AND Q FOR HALF CELL
      DM=1. +S(L)
      IF(L .EQ. 2 ) GO TO 847
      DM1=DF1+S(L)/R(L)
      DM2=DF1/DM
      DM3=DM2*S(L)
      IF(L .EQ. 1)DM4=(S(L)/R(L))*C1(NL)
      IF(L .EQ. 1) GO TO 848
      847 DM1=1.+S(L)/R(L)
      DM2=1./DM
      DM3=S(L)/DM
      IF(L .EQ. 2)DM4=(S(L)/R(L))*C2(NR)
      848 PA(L)=DM2/(DM1-DM3*P(L))
      QA(L)=(DM4+Q(L)*DM3)/(DM1-DM3*P(L))
      850 CONTINUE
      IF(NL .EQ. 1)PA(1)=P1(1)
      IF(NL .EQ. 1)QA(1)=Q1(1)
C      END      COMPUTATION BLOCK NUMBER  3
C      =====
C      START COMPUTATION BLOCK NUMBER  4
C      CALCULATION OF BOUNDARY DENSITIES
      IF(NL .EQ. 1)SAVE= S(1)
      IF(NL .EQ. 1)S(1)=1.

```

```

DM=1.+S(1)
D11=S(1)**2
D12=S(1)*S(2)
RT=(DZ*DF2)/(DY)
DM1=D11/R(1)+(SEG*RT*D12)/R(2)+DF1/DM
IF(NL.EQ.1)DM1=SAVE/R(1)+(SEG*RT*S(2))/R(2)
DM2=-D11/R(1)+(1.-S(1))*DF1
IF(NL.EQ.1)DM2=-(SAVE/R(1)+DZ*CONPRO)
DM3=-RT*D12/R(2)-RT*S(1)*(1.+1./R(2))
DM4=D11*DF1/DM
IF(NL.EQ.1)DM4=0.
DM5=RT*S(1)
DM6=S(1)*SM(1)*(C1(NL)+CB(1))/R(1)+RT*SM(2)*S(1)*CB(2)/R(2)
1 +S(1)*(RT*SM(2)/R(2)+RT/R(2))*C2(NR)
IF(NL.EQ.1)DM6=DM6+DZ*CONPRO*CONOUT
IF(NL.EQ.1)S(1)=SAVE
DM8=DM2+DM4*P(1)
DM9=DM3+DM5*P(2)
DM10=DM6+Q(1)*DM4+DM5*Q(2)
DM11=DM10+QA(1)*DM8+QA(2)*DM9
DM12=DM1-DM8*PA(1)-SEG*DM9*PA(2)
CB(1)=DM11/DM12
CB(2)=SEG*CB(1)
C   END      COMPUTATION BLOCK NUMBER      4
C   =====
C   START COMPUTATION BLOCK NUMBER      5
DO 855 L=1,2
C(L)=PA(L)*CB(L)+QA(L)
855 CONTINUE
C1(NL)=C(1)
C2(NR)=C(2)
C   END      COMPUTATION BLOCK NUMBER      5
C   CONSERVE CALCULATION
SU= DZ*S(1)*(C1(NL)+CB(1))*0.5 + 0.5* DY*
1S(2)*(C2(NR)+CB(2))+C2(NR)*DY*0.5
IF(NL.GT.1) FL=-R(1)*(-(S(1)**2)*C1(NLM1)/(S(1)+1.))+C1(NL)
1*(S(1)-1.)+CB(1)/(S(1)+1.))*DZ*0.5*DF1
IF(NL.EQ.1)FL=-DT*CONPRO*(C1(1)-CONOUT)
IF(NL.EQ.1)FR=R(2)*(C2(NRP1)-C2(NR))*DY*0.5
IF(NL.EQ.1)ERR=SU-SUM-(FL+FR)
IF(NL.EQ.1)GO TO 860
FR=R(2)*S(1)*(C2(NRP1)-C2(NR))*DY*0.5
ERR=S(1)*(SU-SUM)-(FL+FR)
860 CONTINUE
RETURN
END

```

1.3. Subroutine TRIDNL

```

@FOR,IS TRIDNL
SUBROUTINE TRIDNL
IMPLICIT DOUBLE PRECISION (A-H,O-Z)
COMMON/BL20/DT,DY,DZ,THETA
COMMON/BL21/DF1,DF2
COMMON/BL23/ B2M,B2R,B2L,A2L,A2M,A2R,A1L,A1M,A1R,B1L,B1M,B1R
COMMON/BL25/P(2),Q(2),PA(2),QA(2),C(2),CB(2),P(2),S(2),SM(2)
COMMON/BL26/P1(2000),P2(2000),Q1(2000),Q2(2000),D1(2000),D2(2000)
COMMON/BL28/N2M1,NLM1,N2 , NRP1,NL,NR
COMMON/BL29/C1(2000),C2(2000)
COMMON/BL32/CONPRO,CONOUT
5  FORMAT (7F14.5)
C  CALC. P,S AND DUMMIES
C  START COMPUTATION BLOCK NUMBER 1
C  CALL INTER
C  =====
C  END COMPUTATION BLOCK NUMBER 1
  IF(NL .EQ. 1)DM1=S(1)*DZ
  IF(NL .EQ. 1)DM2=DM1*DM1/(2.*DT)
  IF(NL .EQ. 1)DM=1./( DF1+DM2+DM1*CONPRO)
  IF(NL .EQ. 1 )P1(1)=DM*DF1
C  START COMPUTATION BLOCK NUMBER 2
  IF(NL .GT. 1 )DM=1./(DZ*DZ/(2.*DT) +DZ* CONPRO+DF1 )
  IF(NL .GT. 1 )P1(1)=DF1*DM
C  =====
C  END COMPUTATION BLOCK NUMBER 2
C  START COMPUTATION BLOCK NUMBER 3
  IF(NL .LE. 2 )GO TO 106
  DO 105 J= 2,NLM1
    JM1=J-1
    D1(J) =A2M+P1(JM1)*A2L
    P1(J)=-A2R/D1(J)
105  CONTINUE
106  CONTINUE
C  END COMPUTATION BLOCK NUMBER 3
C  =====
C  START COMPUTATION BLOCK NUMBER 4
  DO 101 J= 1,N2M1
    K=N2-J
    KP1=K+1
    D2(K)=B2M+P2(KP1)
    P2(K)=-1./D2(K)
101  CONTINUE
C  END COMPUTATION BLOCK NUMBER 4
  RETURN
END

```

11.4. Subroutine INTER

```
SUBROUTINE INTER
IMPLICIT DOUBLE PRECISION (A-H,O-Z)
IMPLICIT DOUBLE PRECISION (A-H,O-Z)
COMMON/BL20/DT,DY,DZ,THETA
COMMON/BL21/DF1,DF2
COMMON/BL23/ B2M,B2R,B2L,A2L,A2M,A2R,A1L,A1M,A1R,B1L,B1M,B1R
5  FORMAT (7F14.5)
   RA1=DT/(DZ**2)
   RA2=DT/(DY**2)
   A2L= DF1
   A2R=A2L
   A2M=-(2.*DF1+1./RA1)
   A1L=1.
   A1R= A1L
   A1M=-1./RA1
   B2L=1.
   B2R=B2L
   B2M=-(2.+1./(DF2*RA2) )
   B1L=1.
   B1R =B1L
   B1M = -1./(DF2*RA2)
   RETURN
   END
```

12. GLOSSARY

- $\left. \begin{array}{l} A2L \\ A2M \\ A2R \\ A1M \end{array} \right\}$ - See eqs (5.6) and (5.7) and table 5.
- AF - An array that stores the inhomogeneous terms in the tridiagonal equations for the z-region (table 5).
- ALPHA - Swelling ratio α [eq (2.5)].
- $\left. \begin{array}{l} B2L \\ B2M \\ B2R \\ B1M \end{array} \right\}$ - See eqs (5.10) and table 7.
- BDRY - The point representing infinity in the y-region [eq (2.11')].
- BLTH - The unit being used to dimensionalize lengths (sec. 4.3).
- BTM - The unit being used to dimensionalize time (sec. 4.3).
- BF - An array that stores the inhomogeneous terms in tridiagonal equations in the y-region [eq (5.10) and table 7].
- $\left. \begin{array}{l} C_B \\ C_{max} \\ C_{out} \\ C_p \end{array} \right\}$ - Material parameters [eqs (2.11), (2.12), and (2.13)].
- $\left. \begin{array}{l} C1() \\ C2() \end{array} \right\}$ - Arrays representing concentrations at the grid points in the z- and y-regions, respectively. At the beginning of an iteration of loop 78, $C1()$ represents $C_1(, TTMM)$, and at the end of an iteration, $C1()$ represents $C_1(, TTMMPl)$. Likewise, $C2()$.
- $\left. \begin{array}{l} CB(1) \\ CB(2) \end{array} \right\}$ - These represent $C_i(z_O(TTMMPl), TTMMPl)$, $i = 1, 2$, i.e., the concentrations in the oxide and silicon at the moving boundary.
- CBULK - The concentration in the bulk of the silicon and at $y = 0$ [eqs (2.13) and (2.19), $C_B \equiv CBULK$].
- CENTER - A subroutine for calculating $C1(NL)$, $C2(NR)$, $CB(1)$, $CB(2)$ (secs. 7.2 and 8.2).
- CMAX - The value of $C2(y,0)$ for $y \leq NH$ in eq (2.13).
- CNA - By definition, $A/2$.
- CNB - Another name for CNSTB.
- CNSTA - The constants A and B, respectively, in eqs (4.5) to (4.9) (table 2).
- CNSTX - Defined in eq (4.9) and FORTRAN name for ZCRIT.
- CNTAU - The constant τ in eqs (4.8) and (4.9).

CONOUT	- A constant in eq (2.18) representing the boron concentration in the oxygen at the oxygen-oxide interface (sec. 5.7); CONOUT = C_{out} .
CONPRO	- A proportionality constant in eq (2.18) representing the evaporation rate of boron from the oxide into the oxygen ambient (sec. 5.7); CONPRO = C_p .
D1	- An intermediate array used to compute the arrays Q1, P1 [eq (6.9') and sec. 7.3, computational block #3].
D2	- An intermediate array used to compute arrays P2, Q2 [sec. 7.3, block #4, and eq (6.16')].
DF1	- The diffusion coefficient D_1 in the oxide or z-region.
DF2	- The diffusion coefficient D_2 in the silicon or y-region.
DFC	- A normalizing factor set equal to one in VERSION 1.
DM1 through DM4	- For these quantities used in computational block #3 of sub-routine CENTER, see eqs (6.10') and (6.17').
DM1 through DM10	- For these quantities used in computational block #4 of sub-routine CENTER, see eqs (6.20), (6.21), and (6.22).
DT	- The time mesh width Δt (sec. 4.4).
DTS	- A value of DT that is stored before the moving boundary z_0 crosses a grid point (sec. 7.1, computational block #20).
DY	- The mesh width Δy in the y-region (sec. 4.1).
DZ	- The mesh width Δz in the z-region (sec. 4.1).
EY EZ	- Scaled value of DY, DZ used in plot output.
FNL	- The real value of NL - 1.
FNR	- The real value of NR - 1.
FNZO	- The quantity NZO floated, i.e., made real.
JSAVE	- A parameter used to shift control in the program (computational block #36, sec. 7.1). JSAVE = 0 in VERSION 1 to begin with.
JSTOP	- In VERSION 1, JSTOP equals 1.
KPOW	- A signal to increase the value of DT when KPOW = 100 and $ZOACEL \leq 0.2$ (computational block #16, sec. 7.1).
KPRINT	- The concentrations and certain other integer parameters are printed out when MM = 0 modulo (KPRINT).
LOOP 78	- Each iteration of this loop calculates the concentrations at one time, Δt . (Later see computational block #14, sec. 7.1).
m	- Another symbol for segregation coefficient SEG [eq (2.2)].

MM - This is the "DO" index in loop 78.

MME - This integer specifies the number of iterations in loop 78 (computational block #14, sec. 7.1).

N1 - The value of NL at time $t = 0$ in VERSION 1 (computational block #9, sec. 7.1).

N2 - The number of fixed grid points in the y-region, $N2 = NYO + 1$ [computational block #9, sec. 7.1, and eq (4.2)].

ND - Tells how many y-grid points to the right of NR will be plotted in output graph (block #34, sec. 7.1).

NE - A loop limit index in block #26, sec. 7.1.

NH - The point on the y-axis where the initial concentrations in the silicon changes from CMAX to CBULK [eq (2.13) and sec. 7.1, computational block #10].

NL - See end of section 4.1.

NMOD - The z-grid points are plotted modulo NMOD (block #34, sec. 7.1).

NMOD1 - The y-grid points from NR to the right are plotted modulo NMOD1 (block #34, sec. 7.1).

NORUN - In VERSION 1. NORUN = 1.

NR - See end of section 4.1.

NYO - The number of mesh widths of length DY that cover (0, BDRY) (sec. 4.1).

NZO - A parameter used in the definition of DZ [eq (4.3)].

P1 }
P2 } - These are the arrays whose functions are described in eqs (3.5) and (3.7). The quantities with the exception of P1(1) are computed in subroutine TRIDNL. See eqs (6.5'), (6.6'), and (6.7') for P1(1) and (6.9') for P1(J), J > 1. See computational blocks #23 and #24 for computation of P1(1). See eq (6.16') for the derivation of (6.16).

P(1) }
P(2) } - Alternate names for P1(NLM1), P2(NRP1) [see eq (6.18')].

PA - Coefficient linking C1(NL) with CB(1) and C2(NR) with CB(2) calculated in subroutine CENTER, block #3 [eqs (6.19') and (6.12')]. Function of this array is explained in section 3.1, steps #2 and #3.

PARAM - An array containing various material input constants and computer program constants of possible interest that are program output (computational blocks #2 and #35, sec. 7.1).

PLOT - An NBS "in-house" plotting program available from NBS Applied Mathematics Division. Documented in Appendix 2.

Q1 }
Q2 } - Everything to do with these arrays is explained in the same places as P1 and P2.

Q(1)} Q(2)}	- Alternate names for Q1(NLM1), Q2(NRP1) [eq (6.18')].
R	- Another name for RT.
R(1)} R(2)}	- These are quantities that are defined in eqs (5.35) and calculated in computational block #3 of subroutine CENTER. [See also eqs (5.25) and (5.16, 5.16')].
RA1} RA2}	- Combinations of mesh widths used in subroutine INTER (tables 5 and 7).
RT	- This combination of mesh quantities is defined in eq (5.35) and appears also in eqs (5.38) and (5.34) (computational block #4 of subroutine CENTER).
S(1)} S(2)}	- See eqs (5.35), (5.29), (5.22), (5.15) and figures 5 and 6. These quantities are computed in computational block #21, section 7.1.
SAVE	- See computational block #4 of subroutine CENTER; see remarks at the end of section 5.9 before the SUMMARY.
SCALE2	- Essentially the same as UN2, a scale factor used in plotting. (See sec. 4.4).
SEG	- The FORTRAN symbol for m, the segregation coefficient [eq (2.2)].
SES	- A signal which when negative implies the moving boundary y_0 reached a new y-grid point during the previous iteration of loop 78 (computational block #19, sec. 7.1).
SLOPE	- The speed of the moving boundary in dry oxidations [eq (4.8)].
SM(1)} SM(2)}	- See the same equations and figures cited in description of S(1), S(2). These quantities are computed in computational block #12 and #31, section 7.1.
TFINAL	- This is the time in hours that is inputted into the program.
TIMEND	- When TTMMPl is greater than TIMEND (which is TFINAL in BTM units), the program stops and control is shifted to printing output (computational blocks #32 and #4, sec. 7.1).
TJ	- A signal which, when its value is greater than or equal to 1, indicates that the moving boundary z_0 has reached a new z-grid point during the previous iteration of loop 78.
TLIN	- The quantity T in dry oxidations (table 4.1); also called CN τ .
TRIDNL	- The subroutine where arrays P1, D1 are calculated (secs. 7.3 and 8.3).
TTMM	- The time at the beginning of the MMth iteration of loop 78 in units of BTM (computational block #18, sec. 7.1).
TTMMP1	- The time at the end of the MMth iteration of loop 78 (in BTM units).

TW	- This quantity is always zero in VERSION 1.
UN1} UN2}	- Scaling factors used in the plot output (computational block #34, sec. 7.1, and sec. 4.4).
WFRC	- The fraction of DZ that the moving boundary z_0 moves in the first iteration of loop 78 [eq (4.4) and computational block #7, sec. 7.1].
X1S} X2S}	- Quantities used in setting scales for plots of concentrations (computational block #34, sec. 7.1, and sec. 4.4).
X2SCT	- A cutoff for points with large abscissas (sec. 4.4).
XRL	- An array for abscissas used in plotting (sec. 3.4).
$y_0(t)$	- The position at time t in the y-coordinate frame, calculated by using eq (2.8).
Y1S} Y2S}	- Quantities used in setting scales for plots of concentrations (computational block #34, sec. 7.1, and sec. 4.4).
YO1	- Always zero in VERSION 1.
YOP1	- Position in y-region of moving boundary at time, TTMMPl (computational block #18, sec. 7.1).
YRL	- An array for ordinates used in plotting (sec. 3.4).
$z_0(t)$	- The position of the moving boundary in the z-coordinate frame at time t (sec. 4.2).
ZCRIT	- Same as CNSTX.
ZO1	- Always zero in VERSION 1.
ZOACEL	- When the moving boundary is moving slowly, this parameter is small and the value of DT is increased in order to speed up distance the boundary moves in a given iteration of loop 78 (computational block #16, sec. 7.1).
ZOCR	- ZOPl in units of micrometers (computational block #34, sec. 7.1).
ZOP1	- Position in z-region of moving boundary at time, TTMMPl (computational block #18, sec. 7.1).
ZOP2	- See computational block #20, sec. 7.1.
ZOPS	- See computational block #16, sec. 7.1.
ZW	- Always zero in VERSION 1.

13. REFERENCES

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Appendix 1

FORMULAS USED IN DERIVATION OF DISCRETE ALGEBRAIC EQUATIONS

We collect here for convenience some standard finite difference approximations used in the discretizations effected in chapter five. The derivations of these formulas can be found in a text book on numerical analysis.

1. TAYLOR'S SERIES

$$f(x+\Delta x) = f(x) + f'(x)\Delta x + \frac{f''(x)}{2} \Delta x^2 + \dots + \frac{f^n(x)}{n!} \Delta x^n + \dots \quad (A1)$$

2. QUADRATURE APPROXIMATIONS

a. Midpoint rule

$$\int_a^b f(x)dx = f\left(\frac{a+b}{2}\right) (b-a) + O[(b-a)^3] \quad (A2)$$

b. Right end point

$$\int_a^b f(x)dx = f(b)\Delta x + O[(b-a)^2] \quad (A3)$$

c. Left end point

$$\int_a^b f(x)dx = f(a) (b-a) + O[(b-a)^2] \quad (A4)$$

d. Trapezoid rule

$$\int_a^b f(x)dx = \frac{f(a)+f(b)}{2} (b-a) + O[(b-a)^3] \quad (A5)$$

3. DERIVATIVE APPROXIMATIONS

a. Forward differences

$$\frac{df(x)}{dx} = \frac{f(x+\Delta x) - f(x)}{\Delta x} + O[\Delta x] \quad (A6)$$

b. Backward differences

$$\frac{df(x)}{dx} = \frac{f(x) - f(x-\Delta x)}{\Delta x} + O[\Delta x] \quad (A7)$$

c. Central differences

$$\frac{df(x)}{dx} = \frac{f(x+\Delta x) - f(x-\Delta x)}{2\Delta x} + O[\Delta x^2] \quad (A8)$$

4. THREE-POINT APPROXIMATIONS

Let x_2, x, x_1 be three points such that $x_1 > x > x_2$; then a three-point approximation to the derivative of $t(x)$ at point x is

$$\begin{aligned} \frac{df}{dx} = & - \frac{\Delta x_1}{\Delta x_2} \frac{f(x-\Delta x_2)}{(\Delta x_1 + \Delta x_2)} + \frac{(\Delta x_1 - \Delta x_2)f(x)}{\Delta x_1 \Delta x_2} + \\ & \frac{\Delta x_2}{\Delta x_1} \frac{f(x-\Delta x_1)}{(\Delta x_1 + \Delta x_2)} \end{aligned} \quad (A9)$$

where $\Delta x_1 \equiv x_1 - x$ and $\Delta x_2 \equiv x - x_2$.

Plotting Subroutines

B. L. Joiner and S. T. Peavy

Five FORTRAN subroutines for producing plots similar to the one shown in Figure 1 are now available on the NBS UNIVAC 1108 FASTRAND file named PLOTS.

Questions related to the operation of these subroutines may be directed to:

Brian L. Joiner or Sally T. Peavy
A337 Administration Bldg.
National Bureau of Standards
Washington, D. C. 20234
921-2315

Task numbers for the UNIVAC 1108 may be obtained from the

Computer Services Division
A238 Administration Bldg.
National Bureau of Standards
Washington, D. C. 20234
921-3364

General Remarks

Except as specified below, the subroutines automatically figure out limits for the plots based on the smallest and largest data points. A new page is not called by any of these subroutines. This allows the user to label the top of the page before calling for the plot. These subroutines do not change any of the values of the arguments. Plotting is done by repetitively searching the arrays rather than by sorting them.

The resolution of the plots is 51 characters high by 101 characters wide and each plot consumes 54 lines counting borders and scale labeling. The length and width of the actual plotting area are $8\frac{1}{2}$ inches and 10 inches respectively, and the overall dimensions including borders and scale labeling are 9 inches and $11\frac{1}{4}$ inches respectively.

These five subroutines may be called in from FASTRAND by inserting the following pair of cards after the RUN card:

```
@ XQT CUR
  INF PLOTS
```

where @ means a 7 and 8 punched in card column one.

Subroutines

I. PLOT (N, X, Y)

Plots the data in one column versus that in another column.

N : The number of points to be plotted.

X : A vector (one dimensional array) containing the values of the abscissa.

Y : A vector containing the values of the ordinate.

Example of main program.

```
      DIMENSION X(10), Y(10)
      DO 2 I = 1,5
        X(I) = I
2     Y(I) = SIN(X(I))
      N = 5
      CALL PLOT (N, X, Y)
      STOP
```

II. PLOTS (NARGS, X, Y, NRMX, NROW)

Plots the data in up to 5 pairs of columns. The symbols used are . * + , - respectively for the 5 curves.

NARGS : The number of curves to be plotted.

X : A matrix (two dimensional array) having up to 5 columns and containing the values of the abscissa.

Y : A matrix having the same dimensions as X and containing the values of the ordinate. The first column of Y is plotted versus the first column of X, etc.

NRMX : A vector (one dimensional array) containing the number of points to be plotted in each of the (5 or less) column pairs.

NROW : The number of rows specified for X and Y in their dimension statement(s) in the main program.

(An example is given on the following page.)

Example of main program.

```
      DIMENSION X(85,4), Y(85,4), NRMX(4)
      DO 5 I = 1,20
      X(I,1) = I-10
-5    Y(I,1) = ABS(X(I,1))
      DO 10 I = 1,37
      X(I,2) = I-20
10    Y(I,2) = 20. - X(I,2)**2
      NARGS = 2
      NRMX (1) = 20
      NRMX (2) = 37
      NROW = 85
      CALL PLOTS (NARGS, X, Y, NRMX, NROW)
      STOP
```

III. PLOTL (N, X, Y, IT)

Plots the data in one column versus that in another column using the symbols specified in the IT column.

N : The number of points to be plotted.

X : A vector (one dimensional array) containing the values of the abscissa.

Y : A vector containing the values of the ordinate.

IT : A vector containing numbers between 1 and 26 which dictate the letter of the alphabet to be used as a plotting symbol.

number:	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15
letter:	A	B	C	D	E	F	G	H	I	J	K	L	M	N	O
	16	17	18	19	20	21	22	23	24	25	26				
	P	Q	R	S	T	U	V	W	X	Y	Z				

Example of main program.

```
      DIMENSION X(100), Y(100), IT(100)
      DO 20 I = 1,5
      X(I) = I
      Y(I) = SIN(X(I))
20    IT(I) = 19
      DO 30 I = 6,10
      X(I) = I-5
      Y(I) = COS(X(I))
30    IT(I) = 3
      CALL PLOTL (10, X, Y, IT)
      STOP
```

IV. PLOTLA (N, X, Y, IT, YMIN, YMAX)

This subroutine is the same as PLOTL except that the limits for the Y axis (ordinate) are specified in the call statement. If any points fall outside the specified limits, the limits are stretched so as to include all points.

Example of main program is same as for PLOTL except for call.

```
CALL PLOTLA (10, X, Y, IT, -1., 1.)
```

V. PLOTLF (N, X, Y, IT, XMIN, XMAX, YMIN, YMAX)

This subroutine is also similar to PLOTL except that here the limits for both X and Y are specified in the call statement. Any points falling outside the specified limits are omitted but a tally is kept and the number of offending points is printed below the plot.

Example of main program is same as for PLOTL except for call.

```
CALL PLOTLF (10, X, Y, IT, 0., 5., -1., 1.)
```

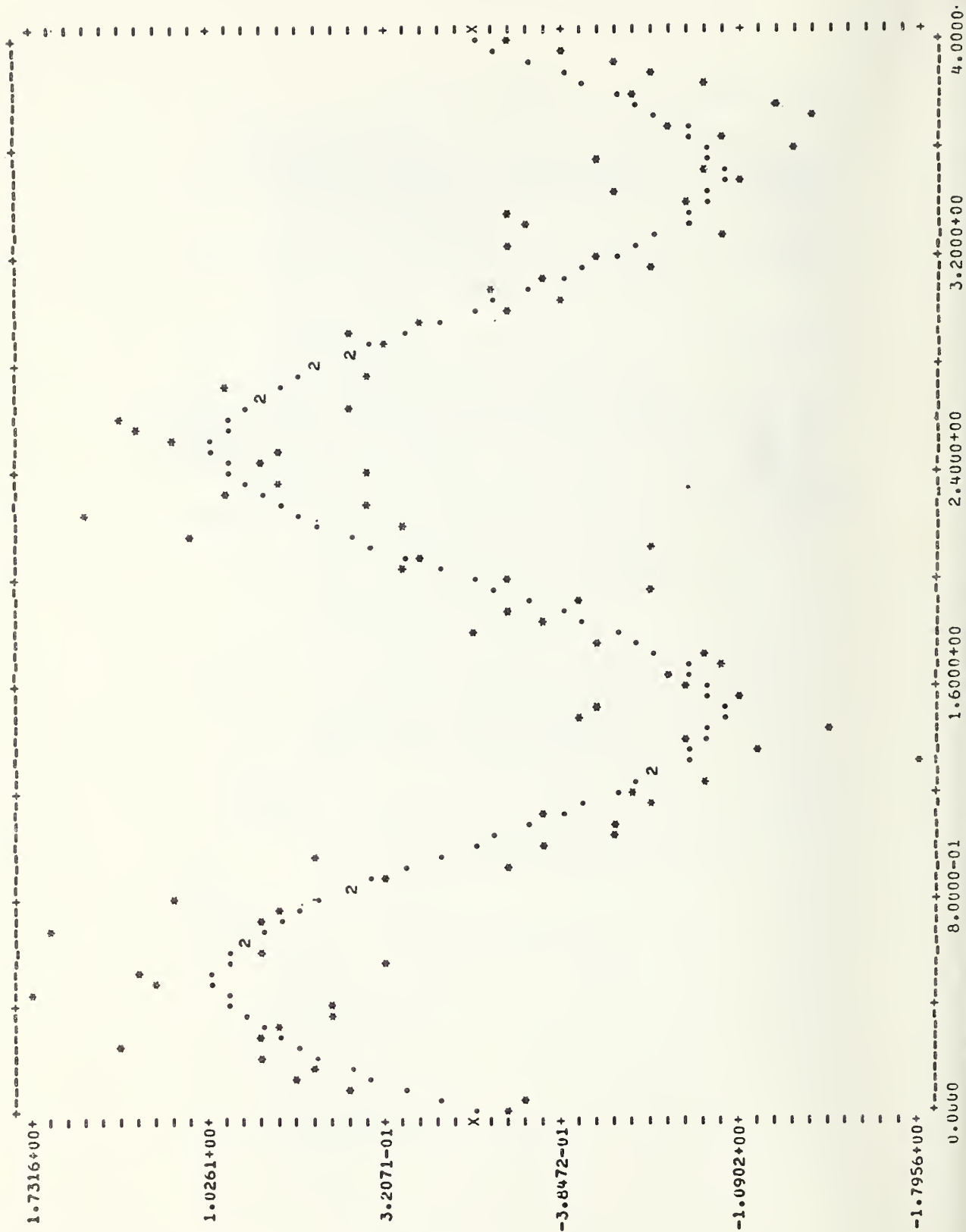
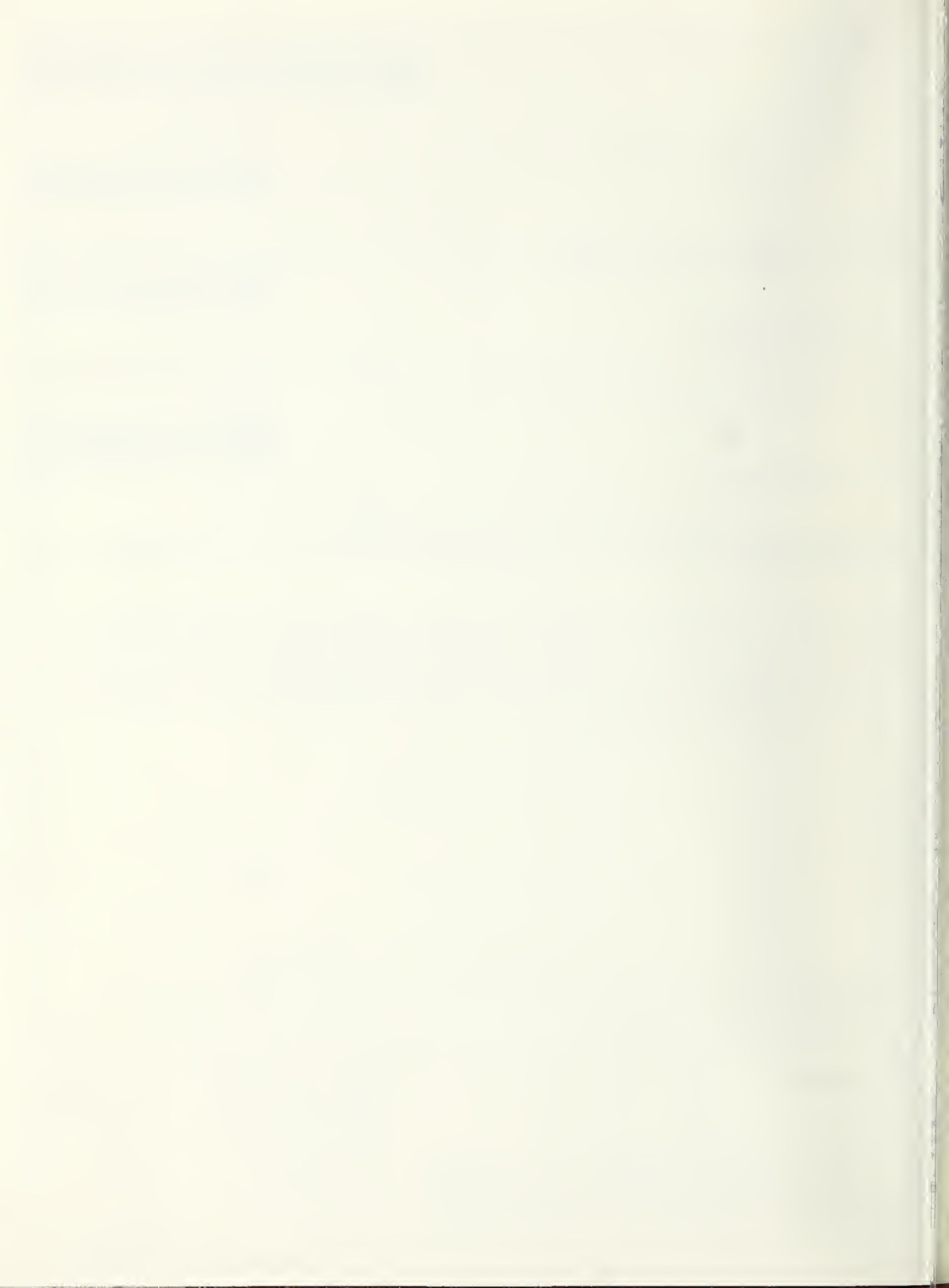


Figure 1.

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